



IDW '14

THE 21ST INTERNATIONAL DISPLAY WORKSHOPS

Special Topics of Interest on

- Oxide-Semiconductor TFT
- Augmented Reality and Virtual Reality
- Lighting Technologies
- Printed Electronics

Workshops on

- LC Science and Technologies (LCT)
- Active Matrix Displays (AMD)
- FPD Manufacturing, Materials and Components (FMC)
- EL Displays and Phosphors (PH)
- Field Emission Displays, CRTs and Plasma Displays (FED)
- OLED Displays and Related Technologies (OLED)
- 3D/Hyper-Realistic Displays and Systems (3D)
- Applied Vision and Human Factors (VHF)
- Projection and Large-Area Displays and Their Components (PRJ)
- Electronic Paper (EP)
- MEMS and Emerging Technologies for Future Displays and Devices (MEET)
- Display Electronic Systems (DES)
- Flexible Electronics (FLX)
- Touch Panels and Input Technologies (INP)

Advance Program

***TOKI MESSE Niigata Convention Center
Niigata, Japan
December 3 – 5, 2014***

CONTENTS

Program Highlights	7
General Information	12
Travel Information	15

Plenary Sessions

Wednesday, December 3

IDW '14 Opening	20
IDW '14 Keynote Addresses	20
IDW '14 Invited Addresses	21

Special Topics of Interest on Oxide-Semiconductor TFT

Wednesday, December 3

AMDp1 Poster: Oxide TFT.....	22
------------------------------	----

Thursday, December 4

AMD1 High Resolution Displays Using LTPS and Oxide TFTs.....	24
FMCp4 Poster: Oxide TFT/Printed Electronics	24
AMD2 Physics of Oxide Semiconductors	25
AMD3 Stability of Oxide TFT	26
AMD4 Higher Performance Oxide TFT	26

Special Topics of Interest on Augmented Reality and Virtual Reality

Thursday, December 4

DES1 Display Technologies in Augmented Reality	28
PRJ4 Wearable Display	28
INP3 AR Interactive Systems.....	29
3D2 Interactive 3D Display Technology	29
3D3 Omnidirectional Hyper-Realistic System	30

Friday, December 5

FMC4 Augmented Reality and Virtual Reality	30
DES3/VHF5 System Design and Evaluation in Augmented Reality	31

Special Topics of Interest on Lighting Technologies

Thursday, December 4

FMCp3 Poster: Lighting Technologies	32
PHp2 Poster: Phosphors for Lighting Application.....	33
OLEDp1 Poster: OLED Poster	33

Friday, December 5

PH3 Phosphors for Lighting Application	33
FMC5 Lighting Technologies	34

Special Topics of Interest on Printed Electronics

Thursday, December 4

OLED3 OLED Process Technologies	35
OLED4 OLED Materials (1)	35
FLX3 Advanced Printing Technologies	36
OLEDp2 <i>Poster</i> : OLED Poster	36
FLX4 Printed TFT Technologies	37
AMD5 Printed Electronics	37

Workshop on LC Science and Technologies

Wednesday, December 3

LCT1 Fast Switching LCD	38
LCT2 Novel Optics for LCD	38

Thursday, December 4

LCT3 Photo Alignment	39
LCT4 LC Materials	40
LCT5 LC Evaluation	40
LCTp1 <i>Poster</i> : Fast Switching LCD	41
LCTp2 <i>Poster</i> : LC Application	41
LCTp3 <i>Poster</i> : Photo Alignment	42
LCTp4 <i>Poster</i> : LC Materials	42
LCTp5 <i>Poster</i> : LC Evaluation	43

Workshop on Active Matrix Displays

Wednesday, December 3

AMDp1 <i>Poster</i> : Oxide TFT	44
AMDp2 <i>Poster</i> : Active-Matrix Devices	46

Thursday, December 4

AMD1 High Resolution Displays Using LTPS and Oxide TFTs	47
AMD2 Physics of Oxide Semiconductors	47
AMD3 Stability of Oxide TFT	48
AMD4 Higher Performance Oxide TFT	49
AMD5 Printed Electronics	49

Workshop on FPD Manufacturing, Materials and Components

Wednesday, December 3

FMC1 Manufacturing Technologies	51
FMC2 Materials and Components	51

Thursday, December 4

FMCp1 <i>Poster</i> : Manufacturing Technologies	52
FMCp2 <i>Poster</i> : Materials and Components	53

FMCp3 <i>Poster: Lighting Technologies</i>	54
FMCp4 <i>Poster: Oxide TFT/Printed Electronics</i>	55
FMC3 <i>Optical Films</i>	56

Friday, December 5

FMC4 <i>Augmented Reality and Virtual Reality</i>	56
FMC5 <i>Lighting Technologies</i>	57
FLX6/FMC6 <i>Flexible Materials and Devices</i>	57

Workshop on EL Displays and Phosphors

Thursday, December 4

PHp1 <i>Poster: Phosphors</i>	59
PHp2 <i>Poster: Phosphors for Lighting Application</i>	59
PH1 <i>Phosphor for General</i>	60
PH2 <i>Phosphor Applications</i>	61

Friday, December 5

PH3 <i>Phosphors for Lighting Application</i>	61
---	----

Workshop on Field Emission Displays, CRTs and Plasma Displays

Friday, December 5

Opening	63
FED1 <i>Novel Devices and Applications</i>	63
FED2 <i>Fabrication Processes and New Materials</i>	64
FED3 <i>FE Mechanisms and PDP Protective Layers</i>	64
FED4 <i>Summing Up of PDP History</i>	65

Workshop on OLED Displays and Related Technologies

Wednesday, December 3

OLED1 <i>Advanced OLED Technologies (1)</i>	67
OLED2 <i>Advanced OLED Technologies (2)</i>	67

Thursday, December 4

OLED3 <i>OLED Process Technologies</i>	68
OLED4 <i>OLED Materials (1)</i>	69
OLEDp1 <i>Poster: OLED Poster</i>	69
OLEDp2 <i>Poster: OLED Poster</i>	70
OLEDp3 <i>Poster: OLED Poster</i>	70

Friday, December 5

OLED5 <i>OLED Materials (2)</i>	73
---------------------------------------	----

Workshop on 3D/Hyper-Realistic Displays and Systems

Thursday, December 4

3Dp1	Poster: 3D/Hyper-Realistic Displays	74
3D1	Holography.....	75
3D2	Interactive 3D Display Technology	76
3D3	Omnidirectional Hyper-Realistic System	76

Friday, December 5

3D4	3D/Hyper-Realistic Displays (1)	77
3D5	3D/Hyper-Realistic Displays (2).....	78
3D6	Optical Devices for 3D System	78
3D7/VHF7	Visual Perception for 3D System	79

Workshop on Applied Vision and Human Factors

Thursday, December 4

VHF1	Optical Measurements.....	80
VHF2	Color and OLEDs.....	80
VHFp1	Poster: Applied Vision & Human Factors.....	81
VHF3	Moving Image Quality	82

Friday, December 5

VHF4	Display Legibility	83
DES3/VHF5	System Design and Evaluation in Augmented Reality	83
VHF6	Mobile Human Factors and 'Kansei' Evaluation.....	84
3D7/VHF7	Visual Perception for 3D System	85

Workshop on Projection and Large-Area Displays and Their Components

Wednesday, December 3

Opening	86
PRJ1	Solid-State Light Source Technologies for Projector.....	86
PRJ2	Vehicle Display.....	87

Thursday, December 4

PRJ3	Projection Technologies	87
PRJ4	Wearable Display	88
PRJ5	Projection Applications	88
PRJp	Short Presentation: Projection	89

Friday, December 5

PRJp1	Poster: Projection	89
-------	--------------------------	----

Workshop on Electronic Paper

Wednesday, December 3

EP1	Electrophoretic Displays	90
EP2	Various Technologies for e-Paper	90

Thursday, December 4

EP3	Chromic Displays	91
EPp	Short Presentation: Electronic Paper	91
EPp1	Poster: Electronic Paper	91

Workshop on MEMS and Emerging Technologies for Future Displays and Devices

Thursday, December 4

Opening	92	
MEET1	Emerging Quantum Dots and Nanotechnologies	92
MEET2	Fundamental Components and Process Technologies.....	93
MEET3	EL Quantum Dots Technologies	94
MEET4	Novel Materials and Components.....	94
MEET5	Nanotechnology Display and Imaging	95

Workshop on Display Electronic Systems

Thursday, December 4

DES1	Display Technologies in Augmented Reality	97
DES2	Image Processing	97
DESp1	Poster: Display Electronic Systems	98

Friday, December 5

DES3/VHF5	System Design and Evaluation in Augmented Reality	99
DES4	Display Driving Technologies	100
DES5	Display Interface and Driving Technologies	101

Workshop on Flexible Electronics

Wednesday, December 3

Opening	102	
FLX1	Flexible Backplane	102
FLX2	Flexible Displays and Devices	103

Thursday, December 4

FLXp1	Poster: Flexible Electronics.....	103
FLX3	Advanced Printing Technologies	105
FLX4	Printed TFT Technologies	105

Friday, December 5

FLX5	Flexible Substrates	106
FLX6/FMC6	Flexible Materials and Devices.....	107

Workshop on Touch Panels and Input Technologies

Wednesday, December 3

Opening	108	
INP1	Touch Panel (1).....	108
INP2	Touch Panel (2) and Haptics.....	109

Thursday, December 4

INPp1	Poster: Touch Panel.....	109
INP3	AR Interactive Systems.....	110
INP4	Sensor and Applications.....	110
IDW '14	Workshop Timetable	Pullout
IDW '14	Special Topics of Interest Navigator.....	Pullout
IDW '14	Scope Navigator	Pullout
IDW '14	Registration and Accommodations	Pullout
IDW '14	Committees.....	112
Floor Map		120

PROGRAM HIGHLIGHTS

The 21st International Display Workshops will be held as IDW '14 for encouraging aggressive research and development of display technologies throughout the world and especially in the Asian region. IDW '14 focuses on the following four special topics, which are extremely timely, as well as fourteen active workshops.

Special Topics of Interest on

- Oxide-Semiconductor TFT
- Augmented Reality and Virtual Reality
- Lighting Technologies
- Printed Electronics

Workshops on

- LC Science and Technologies
- Active Matrix Displays
- FPD Manufacturing, Materials and Components
- EL Displays and Phosphors
- Field Emission Displays, CRTs and Plasma Displays
- OLED Displays and Related Technologies
- 3D/Hyper-Realistic Displays and Systems
- Applied Vision and Human Factors
- Projection and Large-Area Displays and Their Components
- Electronic Paper
- MEMS and Emerging Technologies for Future Displays and Devices
- Display Electronic Systems
- Flexible Electronics
- Touch Panels and Input Technologies

The three-day conference will feature 386 papers, including 2 keynote addresses, 2 invited addresses, 97 invited papers and 131 oral presentations, and 154 poster presentations. Following plenary session of Keynote and Invited addresses in the Wednesday morning, presentations will begin and continue in 7 parallel oral sessions through Friday. Poster sessions and author interviews and demonstrations will enable participants to discuss topics in detail. IDW '14 will also present "IDW Best Paper Award" and "IDW Outstanding Poster Paper Award" based on paper originality and technical significance to information displays. Exhibits by universities and display industry-related businesses will also be featured from Wednesday to Friday in parallel with workshops. IDW '14 should be of interest to not only researchers and engineers, but also managers of companies and institutions in the display community.

Special Topics of Interest on Oxide-Semiconductor TFT (OXT)

Oxide TFTs have a long history going back for almost a half century, but they have been intensively investigated only since the first demonstration of amorphous oxide semiconductor TFTs in 2004, and have now become one of the hottest topics in backplane technologies for active-matrix FPDs. Although we were glad to see and touch the first commercial LCD products using the oxide TFTs in 2012 and the subsequent OLED televisions last year, there still remain many technical issues for further evolution toward better performance, high resolution, robust reliability, low fabrication temperature, and broader applications. In IDW '14, the latest achievements involved in the brand-new challenges of these issues will be found. Neither should you miss the brilliant invited talks given by world-leading researchers in oxide TFTs nor the contributed presentations with outstanding results.

Special Topics of Interest on Augmented Reality and Virtual Reality (AR&VR)

In recent years, augmented reality (AR) and virtual reality (VR) applications have been making substantial progress with high-performance display devices and sensors including cameras with tracking capabilities and computer graphics technologies. In the 3D-WS sessions, interactive display technologies using high-speed image processing and applications using wide-field imaging will be presented. Presentations in the DES-WS sessions will include AR with a variety of display techniques such as wide-field head mounted display, fog display, head-up display, projection AR, and Diminished Reality (DR). In the DES/VHF-WS, effects of AR/VR will be presented with AR vehicles, 3D display, and monocular AR. In the INP-WS sessions, system design considerations for personal light field displays and MR visual stimulation on tactile sensation will be presented. In the PRJ-WS sessions, see-through glasses and light field display for AR/VR will be presented. In the FMC-WS sessions, floating image displays to represent 3D images of objects, and wide field of view optical combiner for AR head-up displays will be presented.

Special Topics of Interest on Lighting Technologies (LIT)

The Lighting Technologies of STI will cover all aspects of science and technologies of lighting including LED lighting, OLED lighting, flexible lighting, manufacturing of lighting, lighting materials, device structures for lighting and internal or external efficiency enhancement technologies. A highlight for IDW '14 will be the presentations on novel speckle reduction technology using phase-randomizing deformable mirror applied to direct view LED-BLU with blue laser stimulation of the quantum dots (FMC-WS), high efficient backlight with a nanorod-based optical film and EL sheet driven by wireless power (PH-WS), and flexible white lighting device and tunable lighting device (OLED-WS).

Special Topics of Interest on Printed Electronics (PE)

Printing technologies are opening a new era of electronic devices for their high productivity, low cost, large scale and low environmental-burden fabrication advantages. Printed Electronics, a new Special Topics of Interest, will cover all aspects concerning printed electronics from science and technology viewpoints. This year, five oral sessions will be held including devices and displays fabricated with printing technologies, materials suitable for printing and fabricating process.

Workshop on LC Science and Technologies (LCT)

This workshop covers topics from fundamental studies to recent developments in LCD technologies and LC materials. Of special note this year is the six invited presentations related to fast switching technologies, photo alignment technologies, and LC materials technologies. Moreover, new LCD technologies, such as polymer-stabilized LCDs, 3D-LCDs, IPS-LCDs and ferroelectric LCs are discussed.

Workshop on Active Matrix Displays (AMD)

The AMD workshop covers Si-TFT, oxide TFT, organic TFT, OLED, and integrated sensors. Recent paper presentations tend to focus on oxide TFT, which may be expected to play a role in applications for higher-definition LC and OLED displays. We highlight the oxide TFT as a special topic of interest (STI) with four devoted sessions covering a wide area from materials, physics, devices, and processes to applications. We also have prepared one session on printed electronics STI.

Workshop on FPD Manufacturing, Materials and Components (FMC)

The FMC workshop covers recent developments and achievements in the field of flat panel display technologies that include panel manufacturing, materials, measurements and components. The oral

presentations contain more than 15 papers of which 5 papers are invited papers. In addition, more than 25 posters will be presented. This also includes joint sessions with the FLX-WS. This year our workshops include the hot topics of laser processing, bonding and de-bonding technologies, light control by submicron structure and quantum dot lighting. The AR/VR session devoted to special topics of interests will present the recent trends in augmented and virtual reality. In the newly planned demonstration session, three papers from the oral session will be presented on December 5.

Workshop on EL Displays and Phosphors (PH)

This workshop presents the latest achievements on devices and phosphors for emissive displays, general lighting and LCD backlighting. Invited talks will cover emerging technologies such as highly efficient backlight with a nanorod-based optical film, electron-beam excited UV light source and wavelength conversion nano phosphors synthesized by the microreaction method. Display and medical applications with novel phosphors using Cu-complex and EL sheet driven by wireless power will also be presented.

Workshop on Field Emission Displays, CRTs and Plasma Displays (FED)

This workshop wholly covers the fields of FED, CRT and PDP technologies. Recent progress in image sensors and displays with field emitter arrays will be discussed. The invited talk will present an optical nano-imaging system with electron beam excitation for living cells. Additionally, fabrication processes, field emission characteristics and mechanism, and field emitter materials such as CNT and PrO, will be discussed. Since the invention of plasma displays in 1964, there has been much progress. The 50th anniversary talk discusses successes and declines in the PDP business. Also covered in the session are the latest PDP technologies and discharge applications for medical use and plant factories.

Workshop on OLED Displays and Related Technologies (OLED)

The OLED workshop covers all aspects of the science and technologies of OLED and other organic devices, ranging from material research, basic device physics to display including backplane technologies and other applications. OLED technologies from micro display to large size TV applications and OLED lighting will be reported. Material and device structure for higher quantum efficiencies supporting these device technologies will also be presented. Soluble OLED materials, printed devices and process technologies focused on Printed Electronics (PE) as STI are special discussions this year.

Workshop on 3D/Hyper-Realistic Displays and Systems (3D)

This workshop focuses on recent progress in 3D, hyper-realistic display systems and related visual sciences. It covers acquisition, processing, 2D/3D conversion, dual-view display, multi-view display, holography, new optical components, crosstalk, measurement, perception, standardization and more for 3D/hyper-reality display technologies. This year, some novel technologies will be presented as invited papers, such as super high frame-rate videos, floating display and electronic holography. Some technologies for omnidirectional video are also introduced, which provided the audience a good opportunity to understand the trends in these fields.

Workshop on Applied Vision and Human Factors (VHF)

The VHF workshop covers all topics on vision, human factors and image quality relating to information display. The oral and poster sessions include lively discussions on the latest topics ranging from fundamental theories to applications. This year, we have five VHF oral sessions on Optical Measurement, Color and OLEDs, Moving Image Quality, Display

Legibility, and Mobile Human Factors and 'Kansei' Evaluation. We also have a joint session with the DES (Display Electronic Systems) workshop on the theme of AR (Augmented Reality) and a joint session with the 3D workshop. Both of these promises groundbreaking interdisciplinary discussions, in addition to our VHF poster session which enables participants to quiz presenters in detail. Two distinguished invited talks will be given in the oral sessions, concerning the latest topics in the FPD Mura Index under the IEC standard and visual effects of curved AMOLEDs.

Workshop on Projection and Large-Area Displays and Their Components (PRJ)

The PRJ workshop covers wearable technologies, vehicle information displays, adaptive headlights, solid-state light sources, projection mapping, augmented reality, 3D measurement, advanced sensing and all the projection technologies. This time, our sessions will focus on miniature optical system technologies, laser and LED materials, projection devices, short throw optics, speckle mitigation, and a laser driving system. Recent studies of advanced technologies such as virtual imaging for wearable and vehicle displays, and an innovative theory of solid-state lighting devices will be presented. There will be 17 oral and four poster presentations, for a total 21 presentations, of which 5 papers are invited presentations.

Workshop on Electronic Paper (EP)

This workshop focuses on current topics in electronic paper including rewritable paper and flexible displays. Newly developed e-Paper technologies are now eagerly sought for emerging applications such as e-Books, e-Notebooks, electronic shelf labels, and signage. Various novel technologies such as electrophoretic, electro/thermo chromic, and twisting ball displays will be presented. There will also be reports on front lighting technology and challenging new approaches in e-Paper technologies. Systems, devices, materials, and applications in this field are expected to be enthusiastically discussed.

Workshop on MEMS and Emerging Technologies for Future Displays and Devices (MEET)

The MEET workshop is unique in covering all aspects of MEMS, nanotechnologies and emerging technologies concerning future displays, imaging devices, and emerging electron devices. It seeks to broaden the horizon of display and imaging technologies into cutting-edge technologies. Research areas such as materials, basic physics and fabrication processes are included. Among all the MEMS and display conferences in the world, this is the only opportunity for MEMS and cutting-edge technology researchers to gather and discuss such devices. This year will mark the 10th anniversary of the founding of the MEET workshop. Authorities from top research institutions around the world in this field have been invited. Invited speakers are from Univ. of Cambridge, MIT (QD Vision), École Polytechnique, CEA-LETI, Brunel Univ., Kyung Hee Univ., Seoul Nat. Univ., Sungkyunkwan Univ., Lumiode, NanoPhotonica, Ostendo, Pacific Light Technologies, Ritsumeikan Univ. and Tohoku Univ. Together with contributed papers with high-quality content, this workshop invites participants who wish to open up new fields in displays, imaging devices and emerging devices.

Workshop on Display Electronic Systems (DES)

This workshop covers all aspects of display electronics and systems in relation to video data processing, interface technologies, cooperative operations between display components such as cells and backlights and sensors. This year, we will have 27 papers including seven invited talks and 10 poster presentations (excluding late-news). Sessions related to the driving/low-power technologies for LCD/OLED and vehicle display technologies are planned. We will also highlight AR/VR

technology as a STI including a joint session with VHF-WS.

Workshop on Flexible Electronics (FLX)

Recently, there has been much attention on flexible display technologies which are spread over a wide range of fields from materials science to practical applications. The sessions cover all aspects of the hottest flexible device / wearable / material technologies including OLED, TFT fabrication, substrate, printing / roll-to-roll processes and evaluation.

Workshop on Touch Panels and Input Technologies (INP)

Conventional interface technologies such as touch panels and interactive technologies are the stars of the session. AR/Interactive systems such as haptics and AR are special topics of INP. Computer vision and natural interface technologies are still important research topics of INP. This year, new topics will be presented: Illusion and its analysis which comes from difference of the movement states between real and virtual objects and a near eye display system using light-field technology. INP papers will open a new window in displays and interactive technologies.

IDW Best Paper Award and IDW Outstanding Poster Paper Award

IDW will present “IDW Best Paper Award” and “IDW Outstanding Poster Paper Award”. The award committee of IDW will select the most outstanding papers from those presented at IDW '14. The award winners will be announced on the IDW website and given a plaque after the conference.

Innovative Demonstration Session

This year, IDW introduces new live demonstration for all oral and poster presenters, which provides a larger space and more time for preparation and demonstration than that of the “Author Interviews and Demonstrations”. Best Demonstration Award will be awarded to the demonstration that has the biggest impact on the audience.

Exhibition

The IDW '14 Exhibition, which will be held from December 3 through December 5, covers materials, components, manufacturing and measuring equipment, software systems and other related products for display devices. Please join in and enjoy discussions at exhibitors' booths (Exhibition Hall B).

December 3: 12:40 – 18:00

December 4: 10:00 – 18:00

December 5: 10:00 – 14:00

GENERAL INFORMATION

SPONSORSHIP

IDW '14 is sponsored by the Institute of Image Information and Television Engineers (ITE) and the Society for Information Display (SID).

CONFERENCE SITE

TOKI MESSE Niigata Convention Center
6-1, Bandaijima, Chuo-ku, Niigata City,
Niigata 950-0078

Phone: +81-25-246-8400 Fax: +81-25-246-8411 mail@tokimesse.com

ON-SITE SECRETARIAT

Telephone and fax machines for IDW '14 use will be temporarily set up in the secretariat room (Room 203) at TOKI MESSE (December 2-5).
Phone/Fax: +81-25-246-8511

RECEPTION

A buffet style reception will be held on December 3 from 19:00 to 21:00 at the Room "Continental" (4F) in the Hotel Okura Niigata. As the number of tickets is limited, you are urged to make an advance reservation through the registration website.

EVENING GET-TOGETHER WITH WINE

A get-together will be held on December 2 from 18:00 to 20:00 at Observation Deck (31F) in Hotel Nikko Niigata. Wine (Sponsored by Merck Ltd., Japan) will be served to participants in a relaxed atmosphere for networking.

REGISTRATION

Registration is available in advance and also on-site. However, advance registration is strongly recommended to speed up your registration at the conference site.

Registration Fees

The registration fee for IDW '14 includes admission to the conference and a CD-ROM of the proceedings. Detailed information will be announced on the website.

	Until Oct. 31	On and After Nov. 1
Individual Member (ITE/SID/ASO*)	¥ 35,000	¥ 45,000
Non-Member**	¥ 45,000	¥ 55,000
Student***	¥ 8,000	¥ 10,000
Life Member of ITE/SID	¥ 8,000	¥ 10,000
Reception	¥ 8,000	¥ 10,000

*ASO: Academic Supporting Organizations

(See p.14 as well as "Supporting Organizations and Sponsors" at the end of each workshop section.)

**Non-Member: If you intend to join either ITE or SID, the one year membership fee will be subsidized by IDW '14 committee.

***Photocopy of student ID is required.

Please note that the payment of reduced registration fee is accepted until October 31. The full fee will be charged for payments made on and after November 1. Also note that the number of reception tickets to register on site is limited.

Proceedings Data at the Conference Site

We will provide the data on USB flash drives for copying near Snow Hall. This data can also be accessed from the web-server via the wireless network only in the Free Wi-Fi Area at the conference site.

For **additional proceedings** (CD-ROM)

At the conference site	¥ 8,000
Airmail after the conference	¥ 12,000
Domestic mail after the conference	¥ 10,000

Payment

Three ways are provided for registration.

(1) e-Registration

Access the following URL.

<http://www.idw.or.jp/regist.html>

e-Registration will be accepted until November 21, 2014.

(2) Mail or Fax Registration

Complete the registration form (download from the website) and send it to the secretariat together with the proof of payment no later than November 21, 2014.

IDW '14 Secretariat

c/o Bilingual Group Ltd.

3-3-6 Kudan Minami, Chiyoda-ku, Tokyo 102-0074, Japan

Phone: +81-3-3263-1345 Fax: +81-3-3263-1264

E-mail: idw@idw.or.jp

The registration fee should be paid by one of the following methods.

1. Credit Card (VISA, MasterCard, JCB, AMEX or Diners)
2. Bank Transfer to:

Bank: Bank of Tokyo-Mitsubishi UFJ
(Swift Code: BOTKJPJT)

Branch: Ichigaya Branch (Branch No. 14)

Account No.: 0167640 (Ordinary Account)

Account: IDW

Please attach a copy of the bank receipt to the registration form to avoid any confusion. Please note that **the remittance charges, including that of Bank of Tokyo Mitsubishi UFJ, should be paid by the payer.**

All above payments should be made in **JAPANESE YEN**.

Also, please note that personal and traveler's checks are not accepted.

(3) On-site Registration

Conference registration desk will open:

December 2 (Tue.) 17:00 – 20:00

December 3 (Wed.) 8:00 – 18:00

December 4 (Thu.) 8:00 – 18:00

December 5 (Fri.) 8:00 – 13:00

On-site registration fee will be payable by:

1. Cash (JAPANESE YEN only)
2. Credit Card (VISA, MasterCard, JCB, AMEX, China Union Pay)

Bank transfer, bank checks, or personal/traveler's checks are not accepted.

Cancellation Policy

Until **October 31**, cancellation is accepted by writing to IDW '14 Secretariat to get refunds for registration and reception. For cancellations received on and **after November 1 or no-shows, refunds will not be made.** However, after IDW '14 closes, a CD-ROM of the proceedings will be sent to the registrants who have paid the registration fees. If it becomes difficult to hold IDW '14 due to the outbreak of infectious diseases and other unavoidable factors, we will substitute the IDW with the mail delivery of the IDW '14 proceedings at a later date to all those who have registered and completed payment.

INQUIRIES

IDW '14 Secretariat

c/o Bilingual Group Ltd.

3-3-6 Kudan Minami, Chiyoda-ku, Tokyo 102-0074, Japan

Phone: +81-3-3263-1345 Fax: +81-3-3263-1264

E-mail: idw@idw.or.jp

ACADEMIC SUPPORTING ORGANIZATIONS (ASO)

- The Chemical Society of Japan
- The Electrochemical Society of Japan
- The Illuminating Engineering Institute of Japan
- The Imaging Society of Japan
- The Institute of Electrical Engineers of Japan
- The Institute of Electronics, Information and Communication Engineers
- The Institute of Image Electronics Engineers of Japan
- International Electrotechnical Commission
- Japan Ergonomics Society
- The Japanese Liquid Crystal Society
- The Japan Society of Applied Physics
- The Society of Polymer Science, Japan
- The Virtual Reality Society of Japan

FUNDS

- Niigata Prefectural Government
- Niigata Visitors & Convention Bureau (Niigata City)
- The Murata Science Foundation
- Support Center for Advanced Telecommunications Technology Research, Foundation

**For final updated information, please visit our website,
<http://www.idw.or.jp/>**

TRAVEL INFORMATION

ACCOMMODATIONS

JTB Kanto Corp. will handle arrangements for your hotel reservations.

Hotel reservations can be made at the IDW website.

<http://www.idw.or.jp/accommodation.html>

Hotel list and the rates are available on the Pullout of this Advance Program.

JTB Kanto Corp.

Corporate Sales Division, Niigata, IDW '14 Desk

Phone: +81-25-255-5101 Fax: +81-25-248-7687

Office Hours: 9:30-17:30 (Weekdays only)

E-mail: jtb_niigata_ec@kanto.jtb.jp

There will be an on-site travel information desk during the conference period to handle arrangements for transportations.

VISAS

Visitors from countries whose citizens must have visas should apply to Japanese consular office or diplomatic mission in their respective countries. For further details, please contact your travel agency or the local consular office in your country.

Attention: For some countries' citizens, official documents prepared by the secretariat will be needed. Please access the IDW website for applications.

<http://www.idw.or.jp/visa.html>

JAPAN RAIL PASS AND JR EAST PASS

Japan Railway (JR) provides the following economical passes. They should be purchased before you leave your country. Please contact your travel agency. Visit following sites for the details.

(1) The JAPAN RAIL PASS is the most economical way to travel throughout Japan by rail and JR buses.

(2) The JR EAST PASS is an economical and flexible rail pass to travel around Eastern Japan.

Japan Rail Pass: <http://www.japanrailpass.net/eng/en001.html>

JR East Pass: <http://www.jreast.co.jp/e/eastpass/>

CLIMATE

The average temperature in Niigata during the conference should be around 9°C (48°F) in the daytime and 3°C (37°F) at night.

NIIGATA CITY

Niigata City is located in the center of the Japanese Islands, 250 km north of Tokyo. The city has a long history as a port, and is distinguished for being the site of one of only five international ports opened in 1868 when Japan resumed contact with other countries after nearly 250 years of isolation. Since that time, Niigata has developed into one of the most important modern international ports in Japan. Geographically, the city is distinctive in that it is surrounded by water. The Shinano and Agano, two of the largest rivers in Japan, run through the heart of Niigata before emptying into the sea. Until relatively recently, the city was also crisscrossed by a series of canals used to transport goods. Although the canals have been filled in to make the construction of modern roadways possible, the willows that lined these canals still remain today and now serve to lend a gentle air to the bustling downtown area.

When Niigata is mentioned, many people often think of the area's delicious rice and sake or the city's beautiful sunsets. But the residents of Niigata themselves take pride, rather, in the spirit of hospitality and community that so distinguishes the city.

PLACES OF INTEREST

Sado Island

Sado Island lies isolated from the mainland by 35 km, and is accessible by Sado Kisen, a ferry service from Niigata City which takes two and a half hours by car ferry or only one hour by jet foil. Sado Island has a perimeter of 261 km, and a total area of 855.26 km². It is one of the largest islands in Japan. Many tourists come from all over the country every year to visit Sado, an island rich in natural beauty and historic monuments.

Niigata Furusatomura

This facility displays and provides information relating to Niigata's history, culture and sightseeing spots. There are shops selling various traditional crafts and local products, such as sake, rice and fish, for which Niigata is famous throughout the country. In addition, there is a food court serving delicious local dishes.

<http://furusatomura.pref.niigata.jp/modules/guide09/index.php?id=2>

Bandai Bridge

The present Bandai Bridge is the third to have spanned the Shinano River (the first was built in 1887, the second in 1909 and the third in 1929). The bridge is 307 m long, 21.9 m wide and consists of 6 arches. Not only was it strong enough to survive the Niigata Earthquake during the 1960s, it has also become one of the symbols of Niigata City.

Prefectural Government Memorial Hall

Built in 1884, this building was formerly home to the Niigata Prefectural Assembly. This Western-style building fuses elements of Western and traditional Japanese architecture. It is the only prefectural assembly building dating from the early Meiji era (1868~1912) still in existence in Japan and is designated as a nationally important cultural property.

The hall is located in Hakusan Park; 10-minute bus ride from Niigata station.

NIIGATA INFORMATION DESK

Information concerning hotels and tours will be available during the conference period.

More information is available from these websites:

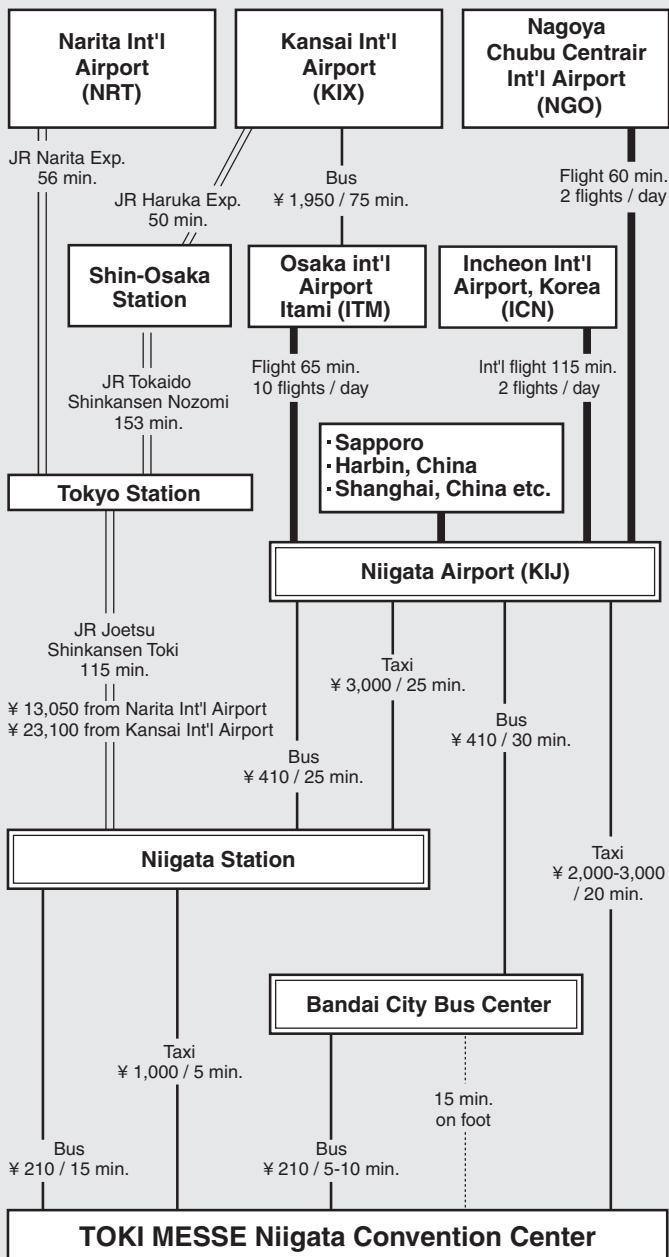
(Niigata City Online)

http://www.city.niigata.lg.jp/multilingual/e_index/index.html

Niigata Prefecture Tourism Guide

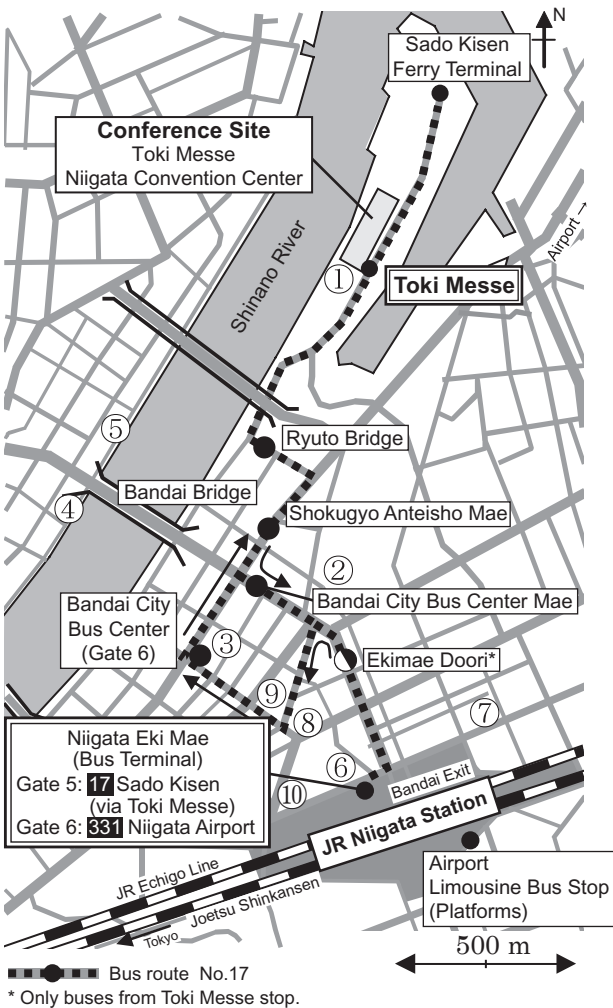
enjoyniigata.com

Access to Conference Site



(as of July, 2014)

Niigata Downtown and Hotel Locations



- ① Hotel Nikko Niigata
- ② ANA Crowne Plaza Hotel
- ③ Bandai Silver Hotel
- ④ Hotel Okura Niigata
- ⑤ Niigata Grand Hotel
- ⑥ Niigata Tokyu Inn
- ⑦ Hotel Sanroute Niigata
- ⑧ Niigata Toei Hotel
- ⑨ Court Hotel Niigata
- ⑩ Comfort Hotel Niigata

- Phone: +81-25-240-1888
- Phone: +81-25-245-3333
- Phone: +81-25-243-3711
- Phone: +81-25-224-6111
- Phone: +81-25-228-6111
- Phone: +81-25-243-0109
- Phone: +81-25-246-6161
- Phone: +81-25-244-7101
- Phone: +81-25-247-0505
- Phone: +81-25-242-0611

Late-News Papers

Due September 25, 2014

Submit a two-page camera-ready manuscript
via IDW website:

<http://www.idw.or.jp/latenews.html>

“Innovative Demonstration Session” by Oral and Poster Presenters

Live demonstrations of emerging information
display technologies

Thursday, December 4, 2014

Friday, December 5, 2014

In the afternoon

Exhibition Hall B

Evening Get-Together with Wine

Tuesday, December 2, 2014

18:00 – 20:00

Observation Deck (31F),

Hotel Nikko Niigata

(Sponsored by Merck Ltd., Japan)

See page 12 for details

Final Program

The final program of IDW '14 will be available on
the website (<http://www.idw.or.jp/>)
from the middle of November.

Plenary Sessions

Wednesday, December 3

9:30 - 9:50

Snow Hall

Opening

Master of Ceremony: S. Komura, Executive Chair, Japan Display, Japan

Opening Remarks

9:30

K. Azuma, General Chair, IDW

A. Ghosh, President of SID

K. Kubota, President of ITE

A. Mikami, Program Chair, IDW

9:50 - 11:10

Snow Hall

Keynote Addresses

Chair: A. Mikami, Program Chair, IDW

Co-Chair: K. Azuma, General Chair, IDW

Keynote Address - 1 Recent Progress on 8K Super Hi-Vision

9:50

M. Sugawara

NHK, Japan

Keynote Address - 2 Display Technologies in Mobile Applications

10:30

J. Hong

Qualcomm, USA

----- Break -----

IDW Best Paper Award

IDW Outstanding Poster Paper Award

These awards will go to the most outstanding papers selected from those presented at IDW '14.

The 2014 award winners will be announced on the IDW website: <http://www.idw.or.jp/award.html>

11:20 - 12:30

Snow Hall

Invited Addresses

Chair: M. Kimura, Vice-Program Chair, IDW

Co-Chair: Y. Gotoh, Vice-Program Chair, IDW

Invited Address - 1 Research and Development of Oxide TFTs
11:20*S.-H. K. Park**KAIST, Korea***Invited Address - 2 Ultraflexible Electronics Using Organic**
11:55 Devices*T. Someya**Univ. of Tokyo, Japan***“Innovative Demonstration Session”**
by Oral and Poster PresentersLive demonstrations of emerging information
display technologies

Thursday, December 4, 2014

Friday, December 5, 2014

In the afternoon

Exhibition Hall B

IDW '14 Tutorial in Japanese

Organized by SID Japan Chapter

Tuesday, December 2, 2014

Room 301, 3F

TOKI MESSE Niigata Convention Center

Detailed information is available on

<http://www.sid-japan.org>

Special Topics of Interest on Oxide-Semiconductor TFT

Wednesday, December 3

14:00 - 17:00

Exhibition Hall B

Poster AMDp1: Oxide TFT

- AMDp1 - 1** **Influence of Subthreshold Leakage Current on Temperature Dependence of Oxide TFTs with Light-Induced Bias-Stress**
B.-L. Yeh, C.-N. Lin
AU Optronics, Taiwan
- AMDp1 - 2** **A 31-in. FHD AMOLED TV Driven by Amorphous IGZO TFTs**
H.-J. Zhang, C.-Y. Su, W.-H. Li, L.-Q. Shi, X.-W. Lv, Y.-T. Hu, C.-Y. Tseng, Y.-F. Wang, C.-C. Lo
Shenzhen China Star Optoelect. Tech., China
- AMDp1 - 3** **5.8-in. Indium Gallium Zinc Oxide TFT LCD with Slim Border**
E.-C. Liu, Y.-H. Chen, S.-C. Chiang, Y.-J. Lu, Y.-Y. Huang
Chunghwa Picture Tubes, Taiwan
- AMDp1 - 4** **Investigation of Hysteresis in Dual-Gate a-IGZO TFTs**
Y.-H. Kim, J. G. Um, S. Lee, M. Mativenga, J. Jang
Kyung Hee Univ., Korea
- AMDp1 - 5** **CVD-Free and Low Temperature a-InGaZnO TFTs for Flexible Display Applications**
W.-T. Lin, C.-C. Cheng, C.-Y. Liu, M.-F. Chiang
AU Optronics, Taiwan
- AMDp1 - 6** **Investigation for the Time-Dependent Characteristics of Sol-Gel Processed Zinc-Tin-Oxide (ZTO) Transistors**
Y. W. Wang, T. M. Jian, H. H. Wang, W. L. Liu
Nat. Chang Hua Univ. of Education, Taiwan
- AMDp1 - 7** **Electrical Characteristics and Stability of Bottom Gate a-InGaZnO TFTs with Different Geometric Structures**
H.-W. Li, C.-P. Chang, H.-H. Lu
AU Optronics, Taiwan

- AMDp1 - 8 Hysteresis Improvements by Introducing a Double-Active-Layered Structure in a-InGaZnO TFTs**
 Y.-C. Tsai, F.-J. Chan, P.-T. Liu, H.-P. D.-D. Shieh
Nat. Chiao Tung Univ., Taiwan
- AMDp1 - 9 Self Heating Induced Hole Trapping at Back-Channel Edge of Flexible a-InGaZnO TFTs under Gate and Drain Bias Stress**
 G. Li*, B.-R. Yang^{**,*}, Y.-C. Tsai^{***}, R. Zhan*, C.-Y. Su^{****},
 C.-Y. Lee^{****}, C.-Y. Tseng^{****}, C.-C. Lo^{****}, A. Lien^{*****},
 S. Deng*, N. Xu*, H.-P. D.-D. Shieh^{***}
^{*}Nat. Sun Yat-Sen Univ., China
^{**}SYSU-CMU Shunde Int. Joint Res. Inst., China
^{***}Nat. Chiao Tung Univ., Taiwan
^{****}Shenzhen China Star Optoelect. Tech., China
^{*****}TCL Corporate Res., China
- AMDp1 - 10 Enhancement of Performance and Storage Stability of Thin-Film Transistor with InZnSnO/InGaZnO Bilayer Stack Channel Layers**
 P.-T. Liu, C.-S. Fuh, C.-H. Chang, C.-C. Chang, X.-Y. Yeh
Nat. Chiao Tung Univ., Taiwan
- AMDp1 - 11 Effects of Negative-Gate-Bias with Illumination Stress on the Hysteresis in the Transfer Curve of a-IGZO TFT Measured by the New Sampling Method**
 Y.-J. Chen, Z.-H. Cai, Y.-H. Tai, C.-Y. Chang, C.-J. Li*,
 Y.-H. Yeh*
Nat. Chiao Tung Univ., Taiwan
^{*}ITRI, Taiwan
- AMDp1 - 12 Back-Channel-Etching (BCE) TFT Fabrication with High Etchant-Resistive Solute Metal Oxide Semiconductor**
 K.-H. Su, M. Marinkovic, D.-V. Pham, A. Merkulov,
 A. Hoppe, R. Anselmann
Evonik Inds., Germany
- AMDp1 - 13 Reduction of Hysteresis in Transfer Characteristics of Solution Processed IZTO TFT by Plasma Treatment**
 T.-H. Kim, C. Avis, H.-R. Hwang, J. Jang
Kyung Hee Univ., Korea
- AMDp1 - 14 Effect of Solution Processed AlO_x Passivation on Back Channel Etch a-IGZO TFTs**
 S. An, M. Mativenga, X. Lee, J. Jang
Kyung Hee Univ., Korea

AMDp1 - 15 Impact of Negative Bias and Illumination Stress on Channel and Series Resistance of Back Channel Etched a-IGZO TFTs

*M. Chun, J. Um, M. Mativenga, J. Jang
Kyung Hee Univ., Korea*

Thursday, December 4

9:00 - 10:15

Snow Hall A

AMD1: High Resolution Displays Using LTPS and Oxide TFTs

Chair: T. Kamiya, Tokyo Inst. of Tech., Japan
Co-Chair: K. Takatori, NLT Techs., Japan

AMD1 - 1: *Invited* High PPI Technologies for Mobile Displays
9:00

*A. Takimoto
Japan Display, Japan*

AMD1 - 2: *Invited* Advantages of IGZO Platform in Ultra-High-Resolution LCD Applications
9:25

*N. Ueda, Y. Ogawa, K. Okada, A. Oda, S. Katoh,
S. Uchida, K. Yamamoto, T. Matsuo, H. Kawamori
Sharp, Japan*

AMD1 - 3: *Invited* Ultra High-Definition OLED Display Using C-Axis Aligned Crystalline Oxide Semiconductor FETs
9:50

*H. Miyake, S. Kawashima, S. Inoue, M. Shiokawa,
A. Suzuki, S. Eguchi, Y. Hirakata, J. Koyama,
S. Yamazaki, T. Sato*, T. Shigenobu*, Y. Ohta**,
S. Mitsui**, N. Ueda**, T. Matsuo**
Semiconductor Energy Lab., Japan
*Advanced Film Device, Japan
**Sharp, Japan*

9:00 - 12:00

Exhibition Hall B

Poster FMCp4: Oxide TFT/Printed Electronics

FMCp4 - 1 Effect of Cu Dopant on Structural and Optical Properties of Zinc Oxide Nanorods

*Z. Jin, T. Umakoshi, Y. Abe, M. Kawamura, K. H. Kim
Kitami Inst. of Tech., Japan*

FMCp4 - 2 Post-Annealing Effect of Zinc Oxide Nanorods Grown on Al-Doped Zinc Oxide Seed Layers

*T. Umakoshi, Y. Abe, M. Kawamura, K. H. Kim
Kitami Inst. of Tech., Japan*

FMCP4 - 3 Application of Microwave-Detected Photoconductivity Decay Technique to Process Monitoring in Back Channel Etching-Type TFT Fabrication

*H. Goto, M. Ochi, H. Tao, S. Morita, Y. Takanashi,
A. Hino, K. Hayashi, T. Kugimiya
Kobe Steel, Japan*

FMCP4 - 4 Copper Nano Particle Ink for Reverse Offset Printing and the Application to Thin Film Transistors

M. Koutake^{,**}
*JAPER, Japan
**DIC, Japan*

10:45 - 12:20

Snow Hall A

AMD2: Physics of Oxide Semiconductors

Chair: J. Jang, Kyung Hee Univ., Korea
Co-Chair: N. Morosawa, Sony, Japan

AMD2 - 1: Invited Multiple Origins of Near-VBM Defects and Its Passivation Effects in Amorphous In-Ga-Zn-O

10:45

*T. Kamiya, H. Kumomi, H. Hosono
Tokyo Inst. of Tech., Japan*

AMD2 - 2: Invited Thermalization Energy Analysis of the Stability of Amorphous Oxide Thin Film Transistors

11:10

*A. J. Flewitt
Univ. of Cambridge, UK*

AMD2 - 3: Invited Origin of High Photoconductivity Gain and Persistent Photoconductivity in Nanocrystalline Oxide Photo-Sensors

11:35

*S. Jeon
Korea Univ., Korea*

AMD2 - 4 Differences in Crystalline Morphology among Crystalline Oxide Semiconductors

12:00

*K. Dairiki, Y. Nonaka, M. Koyama, Y. Yamada,
A. Shimomura, N. Sorida, E. Takahashi, M. Takahashi,
S. Yamazaki
Semiconductor Energy Lab., Japan*

----- Lunch -----

13:30 - 14:55

Snow Hall A

AMD3: Stability of Oxide TFT

Chair: S. Jeon, Korea Univ., Korea
 Co-Chair: M. Kimura, Ryukoku Univ., Japan

AMD3 - 1: Invited Improved Electrical Characteristics and Stability Using Various Post Treatments on Sputtered In-Ga-Zn-O Thin-Film Transistors

13:30

Y. J. Tak, S. P. Park, H. Lee, H. J. Kim
Yonsei Univ., Korea

AMD3 - 2 Reliability of Amorphous InGaZnO Thin Film Transistors with Low Water-Absorption Passivation Layer

13:55

S. Ishikawa, K. Hamada, C. Kulchaisit, M. Fujii*, Y. Ishikawa*, Y. Uraoka**
JSR, Japan
**Nara Inst. of S&T, Japan*

AMD3 - 3 Channel Length Dependent Bias and Light Stability of Bulk Accumulation a-IGZO TFTs with Top Gate Offsets

14:15

S. Lee, M. Mativenga, J. Jang
Kyung Hee Univ., Korea

AMD3 - 4 Effect of Parasitic Capacitance on Pixel Compensation Circuit Developed by Oxide TFT

14:35

C.-Y. Lee, W.-C. Hsu, M.-W. Shih, Y. L. Chen, C. C. Huang, L. W. Liu, C. K. Lo, H. G. Chang, L.-F. Lin, C.-H. Liu, L.-H. Chang, Y.-H. Lin
AU Optronics, Taiwan

----- Break -----

15:15 - 16:20

Snow Hall A

AMD4: Higher Performance Oxide TFT

Chair: H. J. Kim, Yonsei Univ., Korea
 Co-Chair: H. Kumomi, Tokyo Inst. of Tech., Japan

AMD4 - 1: Invited Bulk Accumulation Oxide TFTs for High Resolution Displays

15:15

J. Jang, M. Mativenga, D. Geng
Kyung Hee Univ., Korea

AMD4 - 2 High Mobility Zn-Free Oxide Thin Film Transistors

15:40

*T. Kugimiya, M. Ochi, A. Hino, H. Goto, M. Kanamaru**
Kobe Steel, Japan
**Kobelco Res. Inst., Japan*

AMD4 - 3
16:00

**Amorphous In₂O₃-Based Thin Film Transistors
Fabricated by Low-Thermal Budget Process with
High Mobility and Transparency**

*C.-H. Chang, C.-S. Fuh, C.-J. Chang, C.-C. Chang,
X.-Y. Yeh, P.-T. Liu, H.-H. Lin*, K.-L. Fang*, Y.-C. Kao*,
C.-L. Lee*, P.-L. Shih*, W.-C. Chang*, I.-M. Lu**

Nat. Chiao Tung Univ., Taiwan

**Yeh Hsin Tech., Taiwan*

Author Interviews and Demonstrations

18:30 – 19:30

**The 50th Anniversary Speech of PDPs
“Summing Up of the PDP History
and a Peek at Plasma
Technologies Beyond Displays”
(FED4 – 1)**

Friday, December 5, 2014

15:15 - 15:55

Room 302B

See page 65 for detail

SID Display Week 2015

June 2 – 5, 2015

San Jose Convention Center

San Jose, California, U.S.A.

IMID 2014

August 26 – 29, 2014

EXCO

Daegu, Korea

Special Topics of Interest on Augmented Reality and Virtual Reality

Thursday, December 4

9:00 - 10:35

Room 302 B

DES1: Display Technologies in Augmented Reality

Chair: K. Kiyokawa, Osaka Univ., Japan

Co-Chair: K. Makita, AIST, Japan

DES1 - 1: *Invited* Diminished Reality Based on Image Inpainting for Visually Removing Real Objects in Real Time

9:00

N. Kawai

Nara Inst. of S&T, Japan

DES1 - 2: *Invited* HMD Technologies for AR

9:25

K. Kiyokawa

Osaka Univ., Japan

DES1 - 3: *Invited* Fog Display as a Co-creative Expression Media

9:50

Y. Miwa, S. Itai, Y. Terada

Waseda Univ., Japan

DES1 - 4 Security Doors

10:15

H.-F. Wang, C.-C. Lan, J.-Y. Huang, T.-H. Lin, H.-S. Chen

Nat. Taiwan Univ. of S&T, Taiwan

----- Break -----

10:45 - 11:50

Room 301

PRJ4: Wearable Display

Chair: S. Shikama, Setsunan Univ., Japan

Co-Chair: S. Ouchi, Hitachi, Japan

PRJ4 - 1: *Invited* Laser Light Field Display Based on a Retinal Scanning Array

10:45

M. Ide, K. Yoda, S. Kato

Citizen Holdings, Japan

PRJ4 - 2 Compact Optical Engine for Smart Glass

11:10

H. Baba, T. Totani, T. Hashizume

Seiko Epson, Japan

PRJ4 - 3 **Light-Guide Optical Element Utilizing Notch Filters
for See-Through Glasses**

11:30

X. Xiao, X. Lin, X. Tan

Beijing Inst. of Tech., China

----- Lunch -----

13:30 - 14:20

Room 301

INP3: AR Interactive Systems

Chair: N. Hashimoto, Citizen Holdings, Japan

Co-Chair: N. Balram, Ricoh Innovations, USA

INP3 - 1: ***Invited* System Design Considerations for Personal
Light Field Displays for the Mobile Information
Gateway**

13:30

N. Balram, W. Wu, I. Tasic, K. Berkner

Ricoh Innovations, USA

INP3 - 2: ***Invited* Further Analysis of the R-V Dynamics
Illusion on Sense of Weight**

13:55

S. Hashiguchi, Y. Kataoka, F. Shibata, A. Kimura

Ritsumeikan Univ., Japan

----- Break -----

15:15 - 16:30

Room 301

3D2: Interactive 3D Display Technology

Chair: M. Tsuchida, NTT, Japan

Co-Chair: K. Yamamoto, NICT, Japan

3D2 - 1: ***Invited* Interactive Display Technologies using
High-Speed Image Processing**

15:15

M. Ishikawa

Univ. of Tokyo, Japan

3D2 - 2: ***Invited* Floating Digital Signage Based on Aerial
Imaging Techniques**

16:00

H. Yamamoto^{, **, ***}, S. Suyama^{***}*

^{}Utsunomiya Univ., Japan*

*^{**}JST-CREST, Japan*

*^{***}Univ. of Tokushima, Japan*

----- Break -----

17:00 - 18:40

Room 301

3D3: Omnidirectional Hyper-Realistic System

Chair: K. Yamamoto, NICT, Japan

Co-Chair: M. Tsuchida, NTT, Japan

3D3 - 1: Invited Characteristic of the Ultra-Realistic Dome Images Estimated from Viewing Behavior

17:00

*M. Okyudo, C. Yoshizumi**Wakayama Univ., Japan***3D3 - 2: Invited Development of Spherical Image Camera RICOH THETA**

17:25

*M. Shohara**Ricoh, Japan***3D3 - 3: Invited Omnidirectional Video Streaming System with HMD**

17:50

*D. Ochi**NTT, Japan***3D3 - 4: Invited Holographic HMD with Wide Visual Field**

18:15

*Y. Sakamoto**Hokkaido Univ., Japan***Author Interviews and Demonstrations**

18:30 – 19:30

Friday, December 5

9:00 - 10:00

Snow Hall B

FMC4: Augmented Reality and Virtual Reality

Chair: H. Okumura, Toshiba, Japan

Co-Chair: M. Shinohara, Omron, Japan

FMC4 - 1: Invited Wide Field of View Optical Combiner for Augmented Reality Head-Up Displays

9:00

*H. Okumura, A. Hotta, T. Sasaki, K. Horiuchi, N. Okada**Toshiba, Japan***FMC4 - 2: Panoramic 3D Floating Image Display Using Dual Concave Reflectors**

9:20

*K. Li**Wavien, USA*

FMC4 - 3 **Fabrication of Special Glass-Beads Retroreflector
9:40** **for Aerial Imaging by Retro-Reflection**

Y. Tomiyama^{}, S. Suyama^{*}, H. Yamamoto^{*,**,*}*

^{}Univ. of Tokushima, Japan*

*^{**}JST-CREST, Japan*

*^{***}Utsunomiya Univ., Japan*

----- Break -----

10:45 - 12:15

Room 201

DES3/VHF5: System Design and Evaluation in Augmented Reality

Chair: K. Morita, Nat. Traffic Safety & Environment Lab., Japan
Co-Chair: K. Sakamoto, Panasonic, Japan

**DES3/
VHF5 - 1:** ***Invited* Simulation of Traffic Accident Scenarios with
10:45** **an Augmented Reality Vehicle**

N. Uchida, T. Tagawa, K. Sato

Japan Automobile Res. Inst., Japan

**DES3/
VHF5 - 2:** ***Invited* The Realistic 3D Image Display Using Direct
11:10** **Light Scanning Method**

H. Horimai, K. Hattori^{}, T. Umezaki*

³Dragons, Japan

^{}Chubu Univ., Japan*

**DES3/
VHF5 - 3** **Fast Calculation Algorithm Based on Point-Based
11:35** **Method for CGHs Using Polygon Model**

Y. Ogihara, Y. Sakamoto

Hokkaido Univ., Japan

**DES3/
VHF5 - 4** **The Superiority of Widespread Monocular
11:55** **Augmented Reality Presentation in a Manual Tracing
Task**

A. Kitamura, H. Naito, T. Kimura^{}, K. Shinohara,*

*T. Sasaki^{**}, H. Okumura^{**}*

Osaka Univ., Japan

^{}Kansai Univ. of Welfare Scis., Japan*

*^{**}Toshiba, Japan*

Author Interviews and Demonstrations

16:45 – 17:45

Special Topics of Interest on Lighting Technologies

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster FMCp3: Lighting Technologies

- FMCp3 - 1** **Construction of a Backlight Module by Connecting Unit Cells with an Optical Fiber**
T. Kojima, Y. Asakura, T. Ogawa, I. Fujieda
Ritsumeikan Univ., Japan
- FMCp3 - 2** **Effect of LGP Outline on Edge-Lit LED TV Design**
H. He, Y.-Y. Qiu
Shenzhen China Star Optoelect. Tech., China
- FMCp3 - 3** **Solution for Achieving an Optimized LED Spectrum for LCM**
C.-T. Kang, R. Chang, Y.-Y. Qiu, Z.-J. Su
Shenzhen China Star Optoelect. Tech., China
- FMCp3 - 4** **Portable LED Illuminating Device for Personal Photodynamic Treatment and Cell Culturing**
C.-J. Ou, Z.-W. Lin, Y.-S. Lin, P.-Y. Lin, J.-Y. Chen, Y.-K. Tsai
Hsiuping Univ. of S&T, Taiwan
- FMCp3 - 5** **A Glare Detection for the High-Brightness LED Display Boards Using a Digital Camera**
Y.-H. Siao, P.-J. Wu^{}, B.-J. Pong^{**}, S.-W. Hsu^{**}, C.-H. Wen^{***}, C.-Y. Chen*
Nat. Yunlin Univ. of S&T, Taiwan
^{*}*Nat. Chiao Tung Univ., Taiwan*
^{**}*ITRI, Taiwan*
^{***}*Nat. Taiwan Univ. of S&T, Taiwan*
- FMCp3 - 6** **The Design of Personal Privacy and Wide Viewing Functions LCM Model Design**
Y. W. Chang
AU Optronics, Taiwan

9:00 - 12:00

Exhibition Hall B

Poster PHp2: Phosphors for Lighting Application

- PHp2 - 1 Study on Luminescence Property of $\text{Ba}_3(\text{Sc}_{1-x}\text{Ho}_x)_4\text{O}_9$ Phosphors**
K. Sugimoto, S. W. Kim, T. Ishigaki, K. Uematsu, K. Toda, M. Sato
Niigata Univ., Japan
- PHp2 - 2 The Effect of Si_3N_4 Sources on the Synthesis and the Luminescence Characteristic of $\text{Sr}_{2-x}\text{Si}_3\text{O}_2\text{N}_4: x\text{Eu}^{2+}$**
C.-H. Chiang, T.-S. Zhan, S.-Y. Chu
Nat. Cheng Kung Univ., Taiwan
- PHp2 - 3 A Novel Reddish Orange-Emitting $\text{BaLa}_2\text{Si}_2\text{S}_8:\text{Eu}^{2+}$ Thiosilicate Phosphor for White Light-Emitting Diodes**
S.-P. Lee, T.-M. Chen
Nat. Chiao Tung Univ., Taiwan

----- Lunch -----

13:30 - 16:30

Exhibition Hall B

Poster OLEDp1: OLED Poster

- OLEDp1 - 1 Flexible Hybrid White Light Emitting Diodes Based on Small Molecules and Quantum Dots**
W. Wu, F. Li, H. Hu, J. Lin, T. Guo
Fuzhou Univ., China
- OLEDp1 - 2 Novel Phosphorescent Host Material for Tunable Hybrid White OLED Devices**
H.-L. Huang, B. Balaganesan, H.-M. Kuo, B.-W. Xie, T.-C. Chao, M.-R. Tseng
eRay Optoelect. Tech., Taiwan

Friday, December 5

9:00 - 10:25

Room 302A

PH3: Phosphors for Lighting Application

Chair: W. Chen, Univ. of Texas at Arlington, USA
 Co-Chair: K. Ohmi, Tottori Univ., Japan

- PH3 - 1: 9:00 *Invited* Quantum Rods Optical Film for Backlight**
E. Shaviv, D. Glozman, Y. Bonfil, U. Banin, S. Amir
Qlight Nanotech, Israel

- PH3 - 2**
9:25 **Thermal Degradation of Green-Emitting SrSi₂O₂N₂:Eu²⁺**
C. Wang, R.-J. Xie, T. Takeda*, T. Suehiro*, N. Hirotsuki**
Univ. of S&T of China, China
**NIMS, Japan*
- PH3 - 3**
9:45 **Wireless Power Transmission Method of a Powder EL Sheet Device**
K. Wani, T. Kanda, E. Hashimoto
TAZMO, Japan
- PH3 - 4**
10:05 **Studies of Electroluminescence from Individual Phosphor Particles**
J. Silver, P. G. Harris
Brunel Univ., UK

----- Break -----

10:45 - 12:05

Snow Hall B

FMC5: Lighting Technologies

- Chair: F. P. Shevlin, Dyoptyca, Ireland
Co-Chair: K. Kälántär, Global Optical Solutions, Japan
- FMC5 - 1**
10:45 **Light Guide Plate Illumination with Blue Laser and Quantum Dot Emission**
F. Shevlin
DYOPTYKA, Ireland
- FMC5 - 2**
11:05 **Design and Perception of an Edge Lit HDR Display**
P. Cirkel, L. Penninck
TPVision, Belgium
- FMC5 - 3**
11:25 **Predicting Color Appearance under Non-Uniform Lighting Environments**
H.-C. Li, P.-L. Sun*, S.-Y. Chang*, R. Luo*^{**}*
**Nat. Taiwan Univ. of S&T, Taiwan*
***Univ. of Leeds, UK*
- FMC5 - 4**
11:45 **The Design of Anti-Glare Lens Applied to Direct LED Panel Lighting**
J. W. Pan, Y. K. Hus, C. W. Chiang
Nat. Chiao Tung Univ., Taiwan

----- Lunch -----

Author Interviews and Demonstrations

16:45 – 17:45

Special Topics of Interest on Printed Electronics

Thursday, December 4

9:00 - 10:10

Snow Hall B

OLED3: OLED Process Technologies

Chair: T. Shimizu, NHK, Japan

Co-Chair: T. Komatsu, Panasonic, Japan

OLED3 - 1: *Invited* OLED Device Fabrication by Ink-Jet Printing Technology

9:00

*T. Sonoyama, M. Uchida, T. Sago, S. Watanabe,
K. Ishida, M. Ito, M. Ishida, M. Yamada, Y. Okawa,
S. Tanabe, H. Kiguchi
Seiko Epson, Japan*

OLED3 - 2: *Invited* Important Technologies of Ink Jet System for OLED Display Fabrication

9:25

T. Hayashi, K. Oshima, S. Takei, A. Shimamura,
Y. Konta, S. Tanabe*
Tokyo Electron, Japan
Seiko Epson, Japan

OLED3 - 3 UV-Activated Transparent Desiccant for Practical OLED Encapsulation Process

9:50

*H. Katsui, T. Miyasako, T. Arai, M. Takahashi,
N. Onimaru, N. Takamatsu, T. Yamamura, K. Konno,
K. Kuriyama
JSR, Japan*

----- Break -----

10:45 - 11:55

Snow Hall B

OLED4: OLED Materials (1)

Chair: K. Nakayama, Yamagata Univ., Japan

Co-Chair: K. Monzen, Nissan Chem. Inds., Japan

OLED4 - 1: *Invited* Blue Fluorescent OLEDs for Printed Display Applications

10:45

*E. Boehm, C. Pflumm, H. Heil, S. Meyer, L.-I. Rodriguez,
B. Burkhart, F. Eckes, K. Stegmaier, H. Buchholz
Merck KGaA, Germany*

OLED4 - 2: Invited Development and Manufacture of Solution-Processed White OLED Lighting Panel

11:10

T. Ogata

Mitsubishi Chem. Group S&T Res. Ctr., Japan

OLED4 - 3 The Soluble Hole Injection Materials and the Inks Applicable to OLED Devices

11:35

N. Otani, H. Koga, S. Moriyama, T. Endo, N. Nakaie, K. Monzen

Nissan Chem. Inds., Japan

----- Lunch -----

13:30 - 14:45

Snow Hall B

FLX3: Advanced Printing Technologies

Chair: M. Ito, Toppan Printing, Japan

Co-Chair: H. Hirata, Toray Eng., Japan

FLX3 - 1: Invited Novel Roll-to-Roll Screen Printing Machine for Flexible Devices

13:30

D. Kobayashi, N. Naoi, T. Suzuki*, T. Sasaki*, T. Furukawa***

Tokai Shoji, Japan

**Tokai Seiki, Japan*

***Yamagata Univ., Japan*

FLX3 - 2: Invited Technologies for Fully Integrated Printed Displays

13:55

N. Fruehauf, M. Strecker, D. Benzel, S. Hoehla, J. Remmele

Univ. of Stuttgart, Germany

FLX3 - 3: Invited Flexible Transparent Conductive Films Based on Metal Mesh Technology

14:20

Z. Cui

Chinese Ac. of Sci., China

13:30 - 16:30

Exhibition Hall B

Poster OLEDp2: OLED Poster

OLEDp2 - 1 High-Mobility Solution-Processed Organic Field-Effect Transistors with Channel Length of 5 μm

13:30

R. Nakamichi, T. Nagase, T. Kobayashi, Y. Sadamitsu, H. Naito*

Osaka Pref. Univ., Japan

**Nippon Kayaku, Japan*

15:15 - 16:25

Snow Hall B

FLX4: Printed TFT Technologies

Chair: Y. Uraoka, NAIST, Japan
 Co-Chair: T. Furukawa, Yamagata Univ., Japan

FLX4 - 1: Invited Fully Printed Flexible TFT Array for Electronic Paper

15:15

*M. Ito, H. Chujo, K. Murata, M. Nishizawa, N. Ikeda,
 K. Hatta, M. Yokoo, R. Matsubara, O. Kina, S. Akao,
 T. Yamamoto, M. Takei, M. Kumagai, M. Ishizaki,
 K. Morosawa, M. Matsumura*
Toppan Printing, Japan

FLX4 - 2: Invited Fully-Printed Organic TFTs and Circuits on Ultra-Flexible Substrates

15:40

K. Fukuda, Y. Takeda, S. Tokito
Yamagata Univ., Japan

FLX4 - 3 Flexible Electronics on Backmolded Plastic Foils

16:05

P. Gaucci, N. Fruehauf, A. Ilchmann, B. Polzinger*,
 W. Eberhardt*, H. Kueck**
Univ. of Stuttgart, Germany
**HSG-IMAT, Germany*

----- Break -----

17:00 - 18:10

Snow Hall A

AMD5: Printed Electronics

Chair: Y. Fujisaki, NHK, Japan
 Co-Chair: H. Minemawari, AIST, Japan

AMD5 - 1: Invited High Performance Polymer Semiconductors

17:00

A. Ohno
Mitsubishi Chem., Japan

AMD5 - 2: Invited Flexible Printed Organic TFT Array and Integrated Circuits

17:25

S. Tokito
Yamagata Univ., Japan

AMD5 - 3 Alignment Control of Patterned Organic Semiconductor Crystals in Short Channel Organic Thin-Film Transistors

17:50

Y. Fujisaki, D. Takahashi, Y. Nakajima, H. Tsuji,
 M. Nakata, T. Yamamoto*
NHK, Japan
**Tokyo Univ. of Sci., Japan*

Author Interviews and Demonstrations

18:30 – 19:30

Workshop on LC Science and Technologies

Wednesday, December 3

14:00 - 15:05

Room 301

LCT1: Fast Switching LCD

Chair: M. Ozaki, Osaka Univ., Japan

Co-Chair: H. Okada, Univ. of Toyama, Japan

LCT1 - 1: *Invited* Fast Response LCDs by Doping Nanoparticles and Optical Compensation

14:00

*S. Kobayashi, Y. Shiraishi, H. Takatsu**

Tokyo Univ. of Sci., Yamaguchi, Japan

**DIC, Japan*

LCT1 - 2: Polymer-Wall Stabilization of Ultra-Short-Pitch TN-LCDs

14:25

M. Akimoto, S. Ando, T. Yamashita, K. Takatoh

Tokyo Univ. of Sci., Yamaguchi, Japan

LCT1 - 3: Fast Switching PSV-FLC Using Low Birefringence LCs

14:45

*T. Fijisawa, Y. Aoki, A. Koiso, I. Nishiyama, H. Takatsu, S. Kobayashi**

DIC, Japan

**Tokyo Univ. of Sci., Yamaguchi, Japan*

----- Break -----

15:45 - 17:10

Room 301

LCT2: Novel Optics for LCD

Chair: S. Kobayashi, Tokyo Univ. of Sci., Yamaguchi, Japan

Co-Chair: M. Suzuki, Merck, Japan

LCT2 - 1: *Invited* Scattering-Free, Microsecond Electro-Optic Response Based on Polymer/LC Nanocomposite

15:45

M. Ozaki, Y. Inoue, J. Kobashi, K. Kim, H. Yoshida*

Osaka Univ., Japan

**Kyoto Univ., Japan*

LCT2 - 2: Stacked LC Micro Lens Array Designed for 2D/3D Switching on Compound-Eye Camera

16:10

M. Ito, Y. Kizu, H. Kwon, Y. Kizaki, K. Suzuki, R. Ueno, M. Kobayashi, H. Funaki, Y. Nakai

Toshiba, Japan

LCT2 - 3 **Polarizer-Free Imaging of LC Lens Using Reference Image**
16:30

C. Cui, R. Bao, S. Yu, X. Gong, M. Ye
SuperD, China

LCT2 - 4 **Anisotropic Photoluminescence from an LC-Dye System**
16:50

T. Masuda, T. Kamimura, S. Itaya, I. Fujieda
Ritsumeikan Univ., Japan

Author Interviews and Demonstrations

17:15 – 18:15

Thursday, December 4

10:45 - 11:55

Marine Hall

LCT3: Photo Alignment

Chair: R. Yamaguchi, Akita Univ., Japan

Co-Chair: K. Miyachi, Sharp, Japan

LCT3 - 1: *Invited* Ideal Photoalignment Technology for IPS-LCDs
10:45

N. Kunimatsu, H. Sonoda, Y. Hyodo, Y. Tomioka
Japan Display, Japan

LCT3 - 2: *Invited* New Photo-Aligning Materials Having Cinnamoyl Moieties
11:10

H. Hasebe, K. Maruyama, M. Takashima, S. Amano, F. Kodaera, S. Yamamoto, I. Nishiyama, Y. Saito, Y. Kadomoto, H. Ito, K. Obi, T. Kusumoto, H. Takatsu, Y. Tani, K. Yamauchi, K. Fujisawa, H.-S. Kwok, V. G. Chigrinov*, M. Schadt***

DIC, Japan

**Hong Kong Univ. of S&T, Hong Kong*

***MS High-Tech Consulting, Switzerland*

LCT3 - 3 **Optimization of In-Plane LC Photo Alignment Technology for Large Size Panel**
11:35

*Y.-J. Song, C.-C. Hsieh, Y.-C. Zhao, R.-T. Zhao, X. Li, C.-Y. Chiu, C.-Y. Lee, C.-C. Lo, A. Lien**

Shenzhen China Star Optoelect. Tech., China

**TCL Corporate Res., China*

----- Lunch -----

13:30 - 14:35

Marine Hall

LCT4: LC Materials

Chair: S. Ishihara, Osaka Inst. of Tech., Japan

Co-Chair: H. Hasebe, DIC, Japan

LCT4 - 1: Invited High-HTP Macrocyclized Phenyl Cinnamate Dimer Utilizable as Photo-Responsive Chiral Dopant for Nematic LCs

13:30

*J. Watanabe**Tokyo Inst. of Tech., Japan***LCT4 - 2: Photo Switchable Bent and U-Shaped LCs**

13:55

L. M. Rahman, M. M. Yusoff, S. M. Sarkar, S. Kumar, C. Tschierske****Univ. Malaysia Pahang, Malaysia***Raman Res. Inst., India****Martin-Luther-Univ., Germany***LCT4 - 3: LC Semiconductors Bearing Cyclotetrasiloxane Rings and Their Ring-Opening Polymerization**

14:15

*M. Funahashi, Y. Funatsu, K. Takenami, K. Seike, A. Sonoda***Kagawa Univ., Japan***JAIST, Japan*

----- Break -----

15:15 - 16:20

Marine Hall

LCT5: LC Evaluation

Chair: H. Wakemoto, Japan Display, Japan

Co-Chair: M. Inoue, Apple, Japan

LCT5 - 1: Invited Azimuth Easy Axis and Anchoring Control of Rubbed Polymers by LC Mixture

15:15

*R. Yamaguchi, M. Nishimura, A. Kodate**Akita Univ., Japan***LCT5 - 2: A Method to Determine the Degree of Jet Mura for Curved Display**

15:40

*K. H. Chen, W. F. Sung, W. S. Kao, Y. Cheng**AU Optronics, Taiwan***LCT5 - 3: Premeditate Display Quality of FFS-LCD Using Negative LC by DC Stress**

16:00

*Y. Tang, H. Cui, X. Jiang, J. Liu, P. Liao, C. Yu**Infovision Optoelect., China***Author Interviews and Demonstrations**

18:30 - 19:30

Friday, December 5

9:00 - 12:00

Exhibition Hall B

Poster LCTp1: Fast Switching LCD

- LCTp1 - 1** **Electro-Optic Response of a Chiral Nematic LC with Low Dielectric Anisotropy**
I. Onodera, M. Kimura
Nagaoka Univ. of Tech., Japan
- LCTp1 - 2** **Enhanced Optical Response in Homogeneously Aligned LC Cells via He-Ne Laser Holographic Exposure**
C.-Y. Chien, C.-R. Sheu
Nat. Cheng Kung Univ., Taiwan
- LCTp1 - 3** **Effect of Polymer Wall Formation on Stability and Electro-Optical Properties of Reverse TN-LCDs**
M. Akimoto, K. Nagao, K. Takatoh
Tokyo Univ. of Sci., Yamaguchi, Japan

9:00 - 12:00

Exhibition Hall B

Poster LCTp2: LC Application

- LCTp2 - 1** **The See-Through Screen Based on a Polarization-Dependent LC Device**
W.-K. Lin, W.-C. Su
Nat. Changhua Univ. of Education, Taiwan
- LCTp2 - 2** **Evaluation of Resolving Capabilities at Different Incident Angles of an Imaging System with LC Lens**
R. Bao, C. Cui, S. Yu, X. Gong, M. Ye
SuperD, China
- LCTp2 - 3** **LC Tuning Slow Light Photonic Crystal Waveguide**
G.-H. Li, F.-L. Hsiao
Nat. Changhua Univ. of Education, Taiwan
- LCTp2 - 4** **Surface Morphology Investigation of UV-Glue Composition in PDLC Films**
C.-T. Su, C.-S. Hsieh, J.-T. Lien
Chunghwa Picture Tubes, Taiwan
- LCTp2 - 5** **Features of the Optical Response and Relaxation of the Nematic LC Doped with CdSe/ZnS Quantum Dots**
I. Galin, E. Konshina, D. Shcherbinin, E. Gavrish
ITMO Univ., Russia

- LCTp2 - 6 A New Low-Power and High Aperture Ratio for High-Resolution Mobile TN Panels**
W. Q. Song, D. L. Fu, J. F. Wu, Y. C. Chang
InfoVision Optoelect., China
- LCTp2 - 7 Study on Improving the Image Quality Using Single Compensation Film**
B. Hai, C.-T. Kang
Shenzhen China Star Optoelect. Tech., China

9:00 - 12:00

Exhibition Hall B

Poster LCTp3: Photo Alignment

- LCTp3 - 1 Multi-Domain IPS LC Cell Using the Photo Alignment Method**
B.-J. Mun, K.-W. Park, G.-D. Lee
Dong-A Univ., Korea
- LCTp3 - 2 Localized Cell Parameter Comparison of Photo Alignment and Rubbing Type in FFS-LCD**
K.-T. Huang, Y.-W. Hung, R.-X. Fang, Y.-T. Chao, T. Lee, C. Lee
HannStar Display, Taiwan
- LCTp3 - 3 Fast Switchable Ferroelectric LC Grating and Analysis for the Parameters**
Y. Ma, L. Shi, A. K. Srivastava, V. G. Chigrinov, H. S. Kwok
Hong Kong Univ. of S&T, Hong Kong

9:00 - 12:00

Exhibition Hall B

Poster LCTp4: LC Materials

- LCTp4 - 1 Modeling of LC/Dendrimer Mixtures by Using Hard Repulsive Molecules**
T. Koda, M. Uchida, A. Nishioka, O. Haba, K. Yonetake, M. Kwak, Y. Momoi*, N. Kim*, S. Hong*, D. Kang*, Y. Choi**
Yamagata Univ., Japan
**LG Display, Korea*
- LCTp4 - 2 Single Hydrogen-Bonded Discotic Complexes: A Simple and Robust Route to Room Temperature Columnar Mesophases**
I.-T. Sohn, B.-S. Lee, Y. J. Byun, J. H. Lee
Myongji Univ., Korea

LCTp4 - 3 Pretilt Angle Control of LC on Doping Silica Nanoparticles and Reactive Monomers

*C.-J. Hsu, C.-C. Kuo, C.-D. Hsieh, C.-Y. Huang
Nat. Changhua Univ. of Education, Taiwan*

9:00 - 12:00

Exhibition Hall B

Poster LCTp5: LC Evaluation**LCTp5 - 1 Analysis on Flexoelectric Effect in AH-IPS LC Mode under Low Frame Rate Driving Using a High Speed Camera**

D.-J. Lee^{,**}, G.-Y. Shim^{**}, S.-H. Yoo^{**}, J.-H. Lee^{*},
J.-H. Baek^{*}, H. Choi^{*}, H.-R. Kim^{**}*

^{}LG Display, Korea*

*^{**}Kyungpook Nat. Univ., Korea*

LCTp5 - 2 Proposal of Measuring the Difference in Flexoelectric Coefficient of a TN-LC Cell by Transmission Ellipsometry

*F. B. Z. Arif, H. Matsumoto, M. Kimura, T. Akahane
Nagaoka Univ. of Tech., Japan*

LCTp5 - 3 Analysis of the Vertical Crosstalk of Advanced Super Dimension Switch Mode TFT-LCD

*S. Wang, J. Li, S. Q. Huang, W. Xue, Y. J. Wang, Y. Shi,
Q. Y. Guo, K. H. Park, Y. B. Lee, S. K. Lee*

Hefei BOE Optoelect. Tech., China

LCTp5 - 4 Measurement for Sum of Flexoelectric Coefficients for Nematic LCs by Using Capacitance Characteristics under Applying the DC Voltage

S. Nakamura, Y. Kudoh, T. Takahashi

Kogakuin Univ., Japan

EXHIBITION

12:40 – 18:00 Wednesday, Dec. 3, 2014

10:00 – 18:00 Thursday, Dec. 4, 2014

10:00 – 14:00 Friday, Dec. 5, 2014

Exhibition Hall B

TOKI MESSE Niigata Convention Center

Free admission with your registration name tag

Workshop on Active Matrix Displays

Wednesday, December 3

14:00 - 17:00

Exhibition Hall B

Poster AMDp1: Oxide TFT

Special Topics of Interest on Oxide-Semiconductor TFT

- AMDp1 - 1** **Influence of Subthreshold Leakage Current on Temperature Dependence of Oxide TFTs with Light-Induced Bias-Stress**
B.-L. Yeh, C.-N. Lin
AU Optronics, Taiwan
- AMDp1 - 2** **A 31-in. FHD AMOLED TV Driven by Amorphous IGZO TFTs**
H.-J. Zhang, C.-Y. Su, W.-H. Li, L.-Q. Shi, X.-W. Lv, Y.-T. Hu, C.-Y. Tseng, Y.-F. Wang, C.-C. Lo
Shenzhen China Star Optoelect. Tech., China
- AMDp1 - 3** **5.8-in. Indium Gallium Zinc Oxide TFT LCD with Slim Border**
E.-C. Liu, Y.-H. Chen, S.-C. Chiang, Y.-J. Lu, Y.-Y. Huang
Chunghwa Picture Tubes, Taiwan
- AMDp1 - 4** **Investigation of Hysteresis in Dual-Gate a-IGZO TFTs**
Y.-H. Kim, J. G. Um, S. Lee, M. Mativenga, J. Jang
Kyung Hee Univ., Korea
- AMDp1 - 5** **CVD-Free and Low Temperature a-InGaZnO TFTs for Flexible Display Applications**
W.-T. Lin, C.-C. Cheng, C.-Y. Liu, M.-F. Chiang
AU Optronics, Taiwan
- AMDp1 - 6** **Investigation for the Time-Dependent Characteristics of Sol-Gel Processed Zinc-Tin-Oxide (ZTO) Transistors**
Y. W. Wang, T. M. Jian, H. H. Wang, W. L. Liu
Nat. Chang Hua Univ. of Education, Taiwan
- AMDp1 - 7** **Electrical Characteristics and Stability of Bottom Gate a-InGaZnO TFTs with Different Geometric Structures**
H.-W. Li, C.-P. Chang, H.-H. Lu
AU Optronics, Taiwan

- AMDp1 - 8 Hysteresis Improvements by Introducing a Double-Active-Layered Structure in a-InGaZnO TFTs**
 Y.-C. Tsai, F.-J. Chan, P.-T. Liu, H.-P. D.-D. Shieh
Nat. Chiao Tung Univ., Taiwan
- AMDp1 - 9 Self Heating Induced Hole Trapping at Back-Channel Edge of Flexible a-InGaZnO TFTs under Gate and Drain Bias Stress**
 G. Li*, B.-R. Yang^{**,*}, Y.-C. Tsai^{***}, R. Zhan*, C.-Y. Su^{****},
 C.-Y. Lee^{****}, C.-Y. Tseng^{****}, C.-C. Lo^{****}, A. Lien^{*****},
 S. Deng*, N. Xu*, H.-P. D.-D. Shieh^{***}
^{*}Nat. Sun Yat-Sen Univ., China
^{**}SYSU-CMU Shunde Int. Joint Res. Inst., China
^{***}Nat. Chiao Tung Univ., Taiwan
^{****}Shenzhen China Star Optoelect. Tech., China
^{*****}TCL Corporate Res., China
- AMDp1 - 10 Enhancement of Performance and Storage Stability of Thin-Film Transistor with InZnSnO/InGaZnO Bilayer Stack Channel Layers**
 P.-T. Liu, C.-S. Fuh, C.-H. Chang, C.-C. Chang, X.-Y. Yeh
Nat. Chiao Tung Univ., Taiwan
- AMDp1 - 11 Effects of Negative-Gate-Bias with Illumination Stress on the Hysteresis in the Transfer Curve of a-IGZO TFT Measured by the New Sampling Method**
 Y.-J. Chen, Z.-H. Cai, Y.-H. Tai, C.-Y. Chang, C.-J. Li*,
 Y.-H. Yeh*
Nat. Chiao Tung Univ., Taiwan
^{*}ITRI, Taiwan
- AMDp1 - 12 Back-Channel-Etching (BCE) TFT Fabrication with High Etchant-Resistive Solute Metal Oxide Semiconductor**
 K.-H. Su, M. Marinkovic, D.-V. Pham, A. Merkulov,
 A. Hoppe, R. Anselmann
Evonik Inds., Germany
- AMDp1 - 13 Reduction of Hysteresis in Transfer Characteristics of Solution Processed IZTO TFT by Plasma Treatment**
 T.-H. Kim, C. Avis, H.-R. Hwang, J. Jang
Kyung Hee Univ., Korea
- AMDp1 - 14 Effect of Solution Processed AlO_x Passivation on Back Channel Etch a-IGZO TFTs**
 S. An, M. Mativenga, X. Lee, J. Jang
Kyung Hee Univ., Korea

AMDp1 - 15 Impact of Negative Bias and Illumination Stress on Channel and Series Resistance of Back Channel Etched a-IGZO TFTs

*M. Chun, J. Um, M. Mativenga, J. Jang
Kyung Hee Univ., Korea*

14:00 - 17:00

Exhibition Hall B

Poster AMDp2: Active-Matrix Devices

AMDp2 - 1 Study of TFT-LCD Greenish Phenomenon

*W. Qin, H. Kim, J.-Y. Zhao, Y. Wei, C.-F. Zhang, L. Wang,
S. Kim, J.-J. Mok
BOE Tech. Group, China*

AMDp2 - 2 Driving Circuit of Fast Current Programming and Leakage Current Compensation for External Compensation on AMOLED Panel

*C.-C. Chen, K.-Y. Lee, H.-S. Lin, L.-H. Chang, Y.-H. Lin
AU Optronics, Taiwan*

AMDp2 - 3 Active Matrix Organic Light Emitting Diode Compensative Circuit with Amorphous Silicon TFTs

G.-T. Zheng, P.-T. Liu, R.-J. Chen*, C.-Y. Tsai*,
H.-H. Hsieh**
Nat. Tsing Hua Univ., Taiwan
*Nat. Chiao Tung Univ., Taiwan
**Giantplus Tech., Taiwan*

AMDp2 - 4 Simple Pixel Circuit Using LTPS TFTs with Mirror Compensation for AMOLED Displays

*P.-S. Chen, Y.-T. Liu, F.-H. Chen, C.-L. Lin
Nat. Cheng Kung Univ., Taiwan*

AMDp2 - 5 New AMOLED Pixel Circuit to Compensate for V_{TH} Variation with an Eliminated V_{DD} Line

*Y.-T. Liu, P.-S. Chen, P.-S. Shieh, C.-L. Lin
Nat. Cheng Kung Univ., Taiwan*

AMDp2 - 6 Circuit of Gate Driver on Array with Direct Threshold Voltage Compensation for the Pull-Down Transistors

Z.-H. Cai, Y.-J. Chen, Y.-H. Tai, C.-Y. Chang, C.-L. Wu,
Y.-H. Yeh*
Nat. Chiao Tung Univ., Taiwan
ITRI, Taiwan

AMDp2 - 7 Design of High Reliable and Self-Healing Integrated Gate Driving Circuit Applied for Amorphous Silicon TFT-LCDs

*C. Dai, T. Lee, T.-C. Lai, C.-C. Lo, A. Lien**

Shenzhen China Star Optoelect. Tech., China

**TCL Corporate Res., China*

Thursday, December 4

9:00 - 10:15

Snow Hall A

AMD1: High Resolution Displays Using LTPS and Oxide TFTs
Special Topics of Interest on Oxide-Semiconductor TFT

Chair: T. Kamiya, Tokyo Inst. of Tech., Japan

Co-Chair: K. Takatori, NLT Techs., Japan

AMD1 - 1: *Invited* High PPI Technologies for Mobile Displays
9:00

A. Takimoto

Japan Display, Japan

AMD1 - 2: *Invited* Advantages of IGZO Platform in Ultra-High-Resolution LCD Applications
9:25

N. Ueda, Y. Ogawa, K. Okada, A. Oda, S. Katoh,

S. Uchida, K. Yamamoto, T. Matsuo, H. Kawamori

Sharp, Japan

AMD1 - 3: *Invited* Ultra High-Definition OLED Display Using C-Axis Aligned Crystalline Oxide Semiconductor FETs
9:50

H. Miyake, S. Kawashima, S. Inoue, M. Shiokawa,

A. Suzuki, S. Eguchi, Y. Hirakata, J. Koyama,

S. Yamazaki, T. Sato, T. Shigenobu*, Y. Ohta**,*

*S. Mitsui**, N. Ueda**, T. Matsuo***

Semiconductor Energy Lab., Japan

**Advanced Film Device, Japan*

***Sharp, Japan*

----- Break -----

10:45 - 12:20

Snow Hall A

AMD2: Physics of Oxide Semiconductors
Special Topics of Interest on Oxide-Semiconductor TFT

Chair: J. Jang, Kyung Hee Univ., Korea

Co-Chair: N. Morosawa, Sony, Japan

AMD2 - 1: *Invited* Multiple Origins of Near-VBM Defects and Its Passivation Effects in Amorphous In-Ga-Zn-O
10:45

T. Kamiya, H. Kumomi, H. Hosono

Tokyo Inst. of Tech., Japan

AMD2 - 2: 11:10 *Invited* **Thermalization Energy Analysis of the Stability of Amorphous Oxide Thin Film Transistors**

A. J. Flewitt

Univ. of Cambridge, UK

AMD2 - 3: 11:35 *Invited* **Origin of High Photoconductivity Gain and Persistent Photoconductivity in Nanocrystalline Oxide Photo-Sensors**

S. Jeon

Korea Univ., Korea

AMD2 - 4: 12:00 **Differences in Crystalline Morphology among Crystalline Oxide Semiconductors**

K. Dairiki, Y. Nonaka, M. Koyama, Y. Yamada, A. Shimomura, N. Sorida, E. Takahashi, M. Takahashi, S. Yamazaki

Semiconductor Energy Lab., Japan

----- Lunch -----

13:30 - 14:55

Snow Hall A

AMD3: Stability of Oxide TFT

Special Topics of Interest on Oxide-Semiconductor TFT

Chair: *S. Jeon, Korea Univ., Korea*

Co-Chair: *M. Kimura, Ryukoku Univ., Japan*

AMD3 - 1: 13:30 *Invited* **Improved Electrical Characteristics and Stability Using Various Post Treatments on Sputtered In-Ga-Zn-O Thin-Film Transistors**

Y. J. Tak, S. P. Park, H. Lee, H. J. Kim

Yonsei Univ., Korea

AMD3 - 2: 13:55 **Reliability of Amorphous InGaZnO Thin Film Transistors with Low Water-Absorption Passivation Layer**

S. Ishikawa, K. Hamada, C. Kulchaisit, M. Fujii*, Y. Ishikawa*, Y. Uraoka**

JSR, Japan

**Nara Inst. of S&T, Japan*

AMD3 - 3: 14:15 **Channel Length Dependent Bias and Light Stability of Bulk Accumulation a-IGZO TFTs with Top Gate Offsets**

S. Lee, M. Mativenga, J. Jang

Kyung Hee Univ., Korea

AMD3 - 4 **Effect of Parasitic Capacitance on Pixel Compensation Circuit Developed by Oxide TFT**
14:35

*C.-Y. Lee, W.-C. Hsu, M.-W. Shih, Y.-L. Chen,
 C.-C. Huang, L.-W. Liu, C.-K. Lo, H.-G. Chang, L.-F. Lin,
 C.-H. Liu, L.-H. Chang, Y.-H. Lin*
AU Optronics, Taiwan

----- Break -----

15:15 - 16:20

Snow Hall A

AMD4: Higher Performance Oxide TFT
Special Topics of Interest on Oxide-Semiconductor TFT

Chair: H. J. Kim, Yonsei Univ., Korea
 Co-Chair: H. Kumomi, Tokyo Inst. of Tech., Japan

AMD4 - 1: *Invited* Bulk Accumulation Oxide TFTs for High Resolution Displays
15:15

J. Jang, M. Mativenga, D. Geng
Kyung Hee Univ., Korea

AMD4 - 2 **High Mobility Zn-Free Oxide Thin Film Transistors**
15:40

*T. Kugimiya, M. Ochi, A. Hino, H. Goto, M. Kanamaru**
Kobe Steel, Japan
**Kobelco Res. Inst., Japan*

AMD4 - 3 **Amorphous In₂O₃-Based Thin Film Transistors Fabricated by Low-Thermal Budget Process with High Mobility and Transparency**
16:00

*C.-H. Chang, C.-S. Fuh, C.-J. Chang, C.-C. Chang,
 X.-Y. Yeh, P.-T. Liu, H.-H. Lin*, K.-L. Fang*, Y.-C. Kao*,
 C.-L. Lee*, P.-L. Shih*, W.-C. Chang*, I.-M. Lu**
Nat. Chiao Tung Univ., Taiwan
**Yeh Hsin Tech., Taiwan*

----- Break -----

17:00 - 18:10

Snow Hall A

AMD5: Printed Electronics
Special Topics of Interest on Printed Electronics

Chair: Y. Fujisaki, NHK, Japan
 Co-Chair: H. Minemawari, AIST, Japan

AMD5 - 1: *Invited* High Performance Polymer Semiconductors
17:00

A. Ohno
Mitsubishi Chem., Japan

AMD5 - 2: Invited Flexible Printed Organic TFT Array and Integrated Circuits

17:25

S. Tokito

Yamagata Univ., Japan

AMD5 - 3 Alignment Control of Patterned Organic Semiconductor Crystals in Short Channel Organic Thin-Film Transistors

17:50

Y. Fujisaki, D. Takahashi, Y. Nakajima, H. Tsuji, M. Nakata, T. Yamamoto*

NHK, Japan

**Tokyo Univ. of Sci., Japan*

Author Interviews and Demonstrations

18:30 – 19:30

Supporting Organizations:

Technical Committee on Electronic Information Displays, Electronics Society, IEICE

Thin Film Materials & Devices Meeting

IDW '15

The 22nd International Display Workshops

December 8 – 11, 2015

Otsu Prince Hotel

Otsu, Japan

<http://www.idw.or.jp>

IDW Best Paper Award

IDW Outstanding Poster Paper Award

These awards will go to the most outstanding papers selected from those presented at IDW '14.

The 2014 award winners will be announced on the IDW website: <http://www.idw.or.jp/award.html>

Workshop on FPD Manufacturing, Materials and Components

Wednesday, December 3

14:00 - 15:20

Marine Hall

FMC1: Manufacturing Technologies

Chair: M. Kimura, Nagaoka Univ. of Tech., Japan

Co-Chair: P. E. Malinowski, imec, Belgium

FMC1 - 1: *Invited* Visualization Analyses of Replication Molding Phenomena in Injection Molding

14:00

H. Yokoi

Univ. of Tokyo, Japan

FMC1 - 2 Development of Roll to Sheet Gravure Offset- Printed Touch Sensor Fabrication

14:20

J. W.-C. Yu, S.-A. Kuo, C.-H. Chen

AU Optronics, Taiwan

FMC1 - 3 Patterning of Multicolor OLEDs with Ultra-High Resolution by Photolithography

14:40

P. E. Malinowski^{}, T. Ke^{*}, A. Nakamura^{**}, S. Steudel^{*},
D. Janssen^{**}, Y. Kamochi^{***}, I. Koyama^{***}, Y. Iwai^{***},
P. Heremans^{****}*

^{}imec, Belgium*

*^{**}FUJIFILM Elect. Materials (Europe), Belgium*

*^{***}FUJIFILM, Japan*

*^{****}Holst Ctr., the Netherlands*

FMC1 - 4 Ultrafast, All-Laser Precision Manufacturing of Display Cover Glass for Consumer Devices

15:00

*M. Mielke, D. Gaudiosi, M. Shirk, E. Juban,
M. Greenberg, N. Matthew, T. Booth, S. Srinivas*

Raydiance, USA

----- Break -----

15:45 - 16:45

Marine Hall

FMC2: Materials and Components

Chair: R. Yamaguchi, Akita Univ., Japan

Co-Chair: W. I. Milne, Univ. of Cambridge, UK

FMC2 - 1: *Invited* Graphene for Plastic Electronics

15:45

*W. I. Milne^{**}, F. Torissi^{*}, T. Hasan^{*}, M. T. Cole^{*},
M. H. Kang^{*}, A. C. Ferrari^{*}*

^{}Univ. of Cambridge, UK*

*^{**}Tokyo Inst. of Tech., Japan*

- FMC2 - 2** **A New Type of Alignment Material for Double-Layered Retarders Composed of Polymerizable LC**
16:05
- R. Takasago, A. Tamura, T. Miyahara, S.-I. Morishima, N. Yanagihara, Y. Takahashi, Y. Furuki, S. Yoshida, Y. Ito*
FUJIFILM, Japan
- FMC2 - 3** **Inorganic Wave Plates with High Performance in Visible Region Fabricated by Serial Bideposition**
16:25
- N. Koike, K. Sasaki, E. Takahashi, N. Hanashima, A. Takada, M. Suzuki**
Dexerials, Japan
**Kyoto Univ., Japan*

Author Interviews and Demonstrations

17:15 – 18:15

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster FMCp1: Manufacturing Technologies

- FMCp1 - 1** **High Resolution Technology for FPD Manufacturing**
N. Yabu, K. Nagano, N. Izumi
CANON, Japan
- FMCp1 - 2** **Realization on Short-Pitch with Wing/Body Patterning Technology**
Z. Cao, J. Xue, B. Zhang, X. He, S. J. Choi
BOE Tech. Group, China
- FMCp1 - 3** **Liquid Optical Clear Adhesive Lamination Guideline for Large Size Panels**
B. Fu, L. Yan
Henkel, China
- FMCp1 - 4** **First Ultra Thin Glass Temporary Bonding Technology Apply in LTPS-LCD**
C.-H. Liao, C.-H. Chan, S.-P. Chiao, T.-C. Fan, Y.-H. Lai, J.-K. Lu, N. Sugiura
AU Optronics, Taiwan
- FMCp1 - 5** **Electrostatic Control for Flexible Substrate De-Bonding Process**
C.-C. Tsai, H.-P. Shih, C.-C. Wu, C.-W. Kung, K.-W. Lan
ITRI, Taiwan

- FMCP1 - 6** **Current Status of Excimer Laser Annealing for High-Volume LTPS Manufacturing**
B. A. Turk, R. Paetzel
Coherent, USA
- FMCP1 - 7** **Direct Morphology Observation of LC-Polymer Boundary Imaged by Atomic Force Microscope**
K. Ueda, T. Yamamoto, M. Kimura
Nagaoka Univ. of Tech., Japan

9:00 - 12:00

Exhibition Hall B

Poster FMCP2: Materials and Components

- FMCP2 - 1** **Analysis of Black Matrix Electric Properties by Thermal Stress**
Y. Na, S. Min, M. Kwak, D. Kang, Y. Choi, S. Jeon
LG Display, Korea
- FMCP2 - 2** **High Thermal Stability Glass Substrate for High Resolution Display**
M. Hayashi, T. Murata, Y. Kato, T. Murata, M. Ohji
Nippon Elec. Glass, Japan
- FMCP2 - 3** **A Study of Spring Impact Hammer to Define the Specification of Impact Test**
B.-C. Huang, K.-C. Chang, C.-Y. Chiu, Y.-C. Liu
G-tech Optoelect., Taiwan
- FMCP2 - 4** **Effect of N₂O Doping on the Properties of ZnO Thin Films on α -Al₂O₃ Using High-Energy H₂O Generated by a Catalytic Reaction**
Y. Ohashi, S. Kanouchi, N. Yamaguchi, Y. Tamayama, T. Kato, K. Yasui
Nagaoka Univ. of Tech., Japan
- FMCP2 - 5** **Crystalline Structure and Dislocation Distribution of ZnO Thin Film Grown on A-Plane Sapphire Substrate Using High-Temperature H₂O Produced by a Pt-Catalyzed H₂ and O₂ Reaction**
T. Nakamura, Y. Ishiduka, N. Yamaguchi, Y. Tamayama, K. Yasui
Nagaoka Univ. of Tech., Japan
- FMCP2 - 6** **Development of Novel Primer Material Suitable for Connecting Cyclolefin Polymer Film and ITO Thin Layer**
T. Yamate, K. Ono, S. Yamada, H. Suzuki, K. Kumazawa
Nippon Soda, Japan

- FMCP2 - 7** **Development of the Li-Doped Potassium Sodium Niobate Piezoelectric Ceramics with High Electromechanical Coupling Coefficient and Applied to Single-Element Ultrasound Transducers**
C.-M. Weng, Y.-H. Zou, C.-C. Tsai^{}, C.-S. Hong^{**}, S.-Y. Chu*
Nat. Cheng Kung Univ., Taiwan
^{}Tung Fang Design Inst., Taiwan*
*^{**}Nat. Kaohsiung Normal Univ., Taiwan*
- FMCP2 - 8** **High Dielectric Constant Material of $(1-x)\text{Na}_{0.5}\text{K}_{0.5}\text{NbO}_3 - x\text{SrTiO}_3$**
H.-H. Su, C.-S. Lin^{}, C.-S. Hong^{**}, C.-C. Tsai^{***}, S.-Y. Chu*
Nat. Cheng Kung Univ., Taiwan
^{}Kun Shan Univ., Taiwan*
*^{**}Nat. Kaohsiung Normal Univ., Taiwan*
*^{***}Tung Fang Design Inst., Taiwan*
- FMCP2 - 9** **The Development of Multi-Layer Step-Down Lead-Free Piezoelectric Transformers with High Isolation and Its Applications on the AC-DC Inverters**
Z.-Y. Chen, C.-C. Tsai^{}, C.-S. Hong^{**}, S.-Y. Chu, S.-K. Hung, C.-C. Chang-Chien*
Nat. Cheng Kung Univ., Taiwan
^{}Tung Fang Design Inst., Taiwan*
*^{**}Nat. Kaohsiung Normal Univ., Taiwan*

9:00 - 12:00

Exhibition Hall B

Poster FMCP3: Lighting Technologies
Special Topics of Interest on Lighting Technologies

- FMCP3 - 1** **Construction of a Backlight Module by Connecting Unit Cells with an Optical Fiber**
T. Kojima, Y. Asakura, T. Ogawa, I. Fujieda
Ritsumeikan Univ., Japan
- FMCP3 - 2** **Effect of LGP Outline on Edge-Lit LED TV Design**
H. He, Y.-Y. Qiu
Shenzhen China Star Optoelect. Tech., China
- FMCP3 - 3** **Solution for Achieving an Optimized LED Spectrum for LCM**
C.-T. Kang, R. Chang, Y.-Y. Qiu, Z.-J. Su
Shenzhen China Star Optoelect. Tech., China

- FMCP3 - 4** **Portable LED Illuminating Device for Personal Photodynamic Treatment and Cell Culturing**
C.-J. Ou, Z.-W. Lin, Y.-S. Lin, P.-Y. Lin, J.-Y. Chen, Y.-K. Tsai
Hsiuping Univ. of S&T, Taiwan
- FMCP3 - 5** **A Glare Detection for the High-Brightness LED Display Boards Using a Digital Camera**
Y.-H. Siao, P.-J. Wu^{}, B.-J. Pong^{**}, S.-W. Hsu^{**}, C.-H. Wen^{***}, C.-Y. Chen*
Nat. Yunlin Univ. of S&T, Taiwan
^{*}*Nat. Chiao Tung Univ., Taiwan*
^{**}*ITRI, Taiwan*
^{***}*Nat. Taiwan Univ. of S&T, Taiwan*
- FMCP3 - 6** **The Design of Personal Privacy and Wide Viewing Functions LCM Model Design**
Y. W. Chang
AU Optronics, Taiwan

9:00 - 12:00

Exhibition Hall B

Poster FMCP4: Oxide TFT/Printed Electronics
Special Topics of Interest on Oxide-Semiconductor TFT

- FMCP4 - 1** **Effect of Cu Dopant on Structural and Optical Properties of Zinc Oxide Nanorods**
Z. Jin, T. Umakoshi, Y. Abe, M. Kawamura, K. H. Kim
Kitami Inst. of Tech., Japan
- FMCP4 - 2** **Post-Annealing Effect of Zinc Oxide Nanorods Grown on Al-Doped Zinc Oxide Seed Layers**
T. Umakoshi, Y. Abe, M. Kawamura, K. H. Kim
Kitami Inst. of Tech., Japan
- FMCP4 - 3** **Application of Microwave-Detected Photoconductivity Decay Technique to Process Monitoring in Back Channel Etching-Type TFT Fabrication**
H. Goto, M. Ochi, H. Tao, S. Morita, Y. Takanashi, A. Hino, K. Hayashi, T. Kugimiya
Kobe Steel, Japan
- FMCP4 - 4** **Copper Nano Particle Ink for Reverse Offset Printing and the Application to Thin Film Transistors**
M. Koutake^{,**}*
^{*}*JAPER, Japan*
^{**}*DIC, Japan*

----- Lunch -----

17:00 - 18:00

Snow Hall B

FMC3: Optical Films

Chair: H.-M. P. Chen, Nat. Chiao Tung Univ., Taiwan
 Co-Chair: T. Nonaka, AZ Elect. Materials Manufacturing Japan, Japan

FMC3 - 1: Invited Microstructure Film for Wide Viewing TN-LCD
17:00
S. Katsuta, E. Yamamoto, Y. Asaoka, T. Kanno, H. Yui, T. Kamada, T. Maeda, Y. Tsuda, K. Kondo
Sharp, Japan

FMC3 - 2: Invited Meta-Surface Film for Heat-Cutting from the Sun Light
17:20
M. Naya, T. Tani, S. Hakuta, H. Yasuda, N. Kiyoto
FUJIFILM, Japan

FMC3 - 3 Square Light-Diffusing Film by Collimated UV Light and a Cross Shaped Light Diffuser
17:40
B. Katagiri, K. Kusama, T. Orui, S. Shoshi
LINTEC, Japan

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

9:00 - 10:00

Snow Hall B

FMC4: Augmented Reality and Virtual Reality
Special Topics of Interest on Augmented Reality and Virtual Reality

Chair: H. Okumura, Toshiba, Japan
 Co-Chair: M. Shinohara, Omron, Japan

FMC4 - 1: Invited Wide Field of View Optical Combiner for Augmented Reality Head-Up Displays
9:00
H. Okumura, A. Hotta, T. Sasaki, K. Horiuchi, N. Okada
Toshiba, Japan

FMC4 - 2 Panoramic 3D Floating Image Display Using Dual Concave Reflectors
9:20
K. Li
Wavien, USA

FMC4 - 3 **Fabrication of Special Glass-Beads Retroreflector
9:40** **for Aerial Imaging by Retro-Reflection**

Y. Tomiyama^{}, S. Suyama^{*}, H. Yamamoto^{*,**,*}*

^{}Univ. of Tokushima, Japan*

*^{**}JST-CREST, Japan*

*^{***}Utsunomiya Univ., Japan*

----- Break -----

10:45 - 12:05

Snow Hall B

FMC5: Lighting Technologies
Special Topics of Interest on Lighting Technologies

Chair: F. P. Shevlin, Dyoptyca, Ireland

Co-Chair: K. Käläntär, Global Optical Solutions, Japan

FMC5 - 1 **Light Guide Plate Illumination with Blue Laser and
10:45** **Quantum Dot Emission**

F. Shevlin

DYOPTYKA, Ireland

FMC5 - 2 **Design and Perception of an Edge Lit HDR Display
11:05**

P. Cirkel, L. Penninck

TPVision, Belgium

FMC5 - 3 **Predicting Color Appearance under Non-Uniform
11:25** **Lighting Environments**

H.-C. Li^{}, P.-L. Sun^{*}, S.-Y. Chang^{*}, R. Luo^{*,**}*

^{}Nat. Taiwan Univ. of S&T, Taiwan*

*^{**}Univ. of Leeds, UK*

FMC5 - 4 **The Design of Anti-Glare Lens Applied to Direct
11:45** **LED Panel Lighting**

J. W. Pan, Y. K. Hus, C. W. Chiang

Nat. Chiao Tung Univ., Taiwan

----- Lunch -----

13:30 - 14:35

Snow Hall A

FLX6/FMC6: Flexible Materials and Devices

Chair: Y. Mishima, FUJIFILM, Japan

Co-Chair: T. Tomono, Toppan Printing, Japan

FLX6/ ***Invited* Flexible Substrates and Alternative
FMC6 - 1:** **Electrodes of ITO for OLED Lighting
13:30**

M. Koden, H. Kobayashi, T. Moriya, N. Kawamura,

T. Furukawa, H. Nakada

Yamagata Univ., Japan

**FLX6/
FMC6 - 2
13:55** **An Analysis Method of Shock Test for Flexible Displays by Using an Image Luminance Measurement Device**

*J.-M. Hsu, S.-W. Hsu, B.-J. Wen, T.-Y. Chung
ITRI, Taiwan*

**FLX6/
FMC6 - 3
14:15** **Plastic Substrate Technology for Flexible LCD**

*Z.-H. Chen, T.-H. Huang, J.-K. Lu, N. Sugiura
AU Optronics, Taiwan*

Author Interviews and Demonstrations

16:45 – 17:45

Supporting Organizations:

Japan Electronics Packaging and Circuits Association
Japan Society of Colour Material
RadTech Japan
The Japanese Research Association for Organic Electronics Materials
The Japanese Society of Printing Science and Technology
The Society of Photography and Imaging of Japan
The Technical Association of Photopolymers, Japan

RECEPTION

Wednesday, December 3, 2014

19:00 – 21:00

Room “Continental” (4F)

Hotel Okura Niigata

See page 12 for details

EXHIBITION

12:40 – 18:00 Wednesday, Dec. 3, 2014

10:00 – 18:00 Thursday, Dec. 4, 2014

10:00 – 14:00 Friday, Dec. 5, 2014

Exhibition Hall B

TOKI MESSE Niigata Convention Center

Free admission with your registration name tag

Workshop on EL Displays and Phosphors

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster PHp1: Phosphors

- PHp1 - 1** **Printing Artefacts in the Manufacture of AC Electroluminescence**
J. Silver, P. G. Harris
Brunel Univ., UK
- PHp1 - 2** **PL and EL Characteristics in UV to Blue-Green Emitting Bi-Activated Y_2O_3 -Based Oxide Phosphor Thin Films Prepared by Magnetron Sputtering**
T. Miyata, S. Abe
Kanazawa Inst. of Tech., Japan
- PHp1 - 3** **Local Structural Effect on Emission Characteristics of Organic-Inorganic Hybrid Phosphor Made from Malic Acid and APTES**
A. Kato, K. Hasegawa, K. Komatsu, T. Kawase
Nagaoka Univ. of Tech., Japan
- PHp1 - 4** **Synthesis of $Y_2WO_6:Eu$ Nano-Rod Phosphor for Local Field Enhanced Inorganic Electroluminescent Devices**
A. Kato, S. Matsumoto, D. Imai
Nagaoka Univ. of Tech., Japan
- PHp1 - 5** **Suppressed Sublimation of Organic Dye Nano-Particles Embedded in Sol-Gel Derived Silica Glass**
T. Yamaki, T. Kurabayashi, T. Fukuda, N. Kamata, Z. Honda
Saitama Univ., Japan

9:00 - 12:00

Exhibition Hall B

Poster PHp2: Phosphors for Lighting Application Special Topics of Interest on Lighting Technologies

- PHp2 - 1** **Study on Luminescence Property of $Ba_3(SC_{1-x}Ho_x)_4O_9$ Phosphors**
K. Sugimoto, S. W. Kim, T. Ishigaki, K. Uematsu, K. Toda, M. Sato
Niigata Univ., Japan

- PHp2 - 2** **The Effect of Si_3N_4 Sources on the Synthesis and the Luminescence Characteristic of $\text{Sr}_{2-x}\text{Si}_3\text{O}_2\text{N}_4: x\text{Eu}^{2+}$**
C.-H. Chiang, T.-S. Zhan, S.-Y. Chu
Nat. Cheng Kung Univ., Taiwan

- PHp2 - 3** **A Novel Reddish Orange-Emitting $\text{BaLa}_2\text{Si}_2\text{S}_8:\text{Eu}^{2+}$ Thiosilicate Phosphor for White Light-Emitting Diodes**
S.-P. Lee, T.-M. Chen
Nat. Chiao Tung Univ., Taiwan

----- Lunch -----

15:15 - 16:25

Room 302 B

PH1: Phosphors for General

- Chair: J. Silver, Brunel Univ., UK
 Co-Chair: T. Miyata, Kanazawa Inst. of Tech., Japan

- PH1 - 1:** ***Invited* A New and Potential Luminescence Material for Displays**
15:15
W. Chen, L. Ma
Univ. of Texas at Arlington, USA

- PH1 - 2:** ***Invited* Advanced Nanophosphors Synthesized by Microreaction Method and Their Application to Wavelength Conversion Layer**
15:40
*H. Okura, K. Ohmi**
Merck, Japan
**Tottori Univ., Japan*

- PH1 - 3** **Synthesis of $\text{LaPO}_4:\text{Tb}^{3+}, \text{Ce}^{3+}$ Phosphors by Solid Hydrate Thermal Processing**
16:05
S. W. Kim, T. Kaneko, K. Toda, K. Uematsu, M. Sato, J. Koide, M. Toda*, Y. Kudo**
Niigata Univ., Japan
**N-Luminescence, Japan*

----- Break -----

17:00 - 18:05

Room 302 B

PH2: Phosphor Applications

Chair: R.-J. Xie, NIMS, Japan

Co-Chair: K. Wani, TAZMO, Japan

PH2 - 1: 17:00 *Invited* Development of a UV Light Source Using Pr:LuAG Thin Film Target Pumped by Electron Beam*N. Ichikawa, K. Ikeda, Y. Honda, H. Taketomi, K. Kawai, T. Suzuki**Hamamatsu Photonics, Japan***PH2 - 2 17:25 Fabrication of Luminescent Thin Film for Nanometric Light Spot of High Spatial Resolution Optical Microscopy***T. Furukawa*, S. Kanamori*, M. Fukuta*, Y. Nawa*, H. Kominami*, Y. Nakanishi*, A. Sugita*, W. Inami**, Y. Kawata****Shizuoka Univ., Japan****JST, Japan***PH2 - 3 17:45 Growth, Structure, and Cathodoluminescence Property of ZnO Nanorods Prepared with Low Temperature Reducing Annealing***C. Li, X. Li, S. Hou**Kochi Univ. of Tech., Japan***Author Interviews and Demonstrations**

18:30 – 19:30

Friday, December 5

9:00 - 10:25

Room 302A

**PH3: Phosphors for Lighting Application
*Special Topics of Interest on Lighting Technologies***

Chair: W. Chen, Univ. of Texas at Arlington, USA

Co-Chair: K. Ohmi, Tottori Univ., Japan

PH3 - 1: 9:00 *Invited* Quantum Rods Optical Film for Backlight*E. Shaviv, D. Glozman, Y. Bonfil, U. Banin, S. Amir
Qlight Nanotech, Israel***PH3 - 2 9:25 Thermal Degradation of Green-Emitting SrSi₂O₂N₂:Eu²⁺***C. Wang, R.-J. Xie*, T. Takeda*, T. Suehiro*, N. Hirosaki*
Univ. of S&T of China, China
NIMS, Japan

**PH3 - 3
9:45** **Wireless Power Transmission Method of a Powder
EL Sheet Device**

*K. Wani, T. Kanda, E. Hashimoto
TAZMO, Japan*

**PH3 - 4
10:05** **Studies of Electroluminescence from Individual
Phosphor Particles**

*J. Silver, P. G. Harris
Brunel Univ., UK*

Author Interviews and Demonstrations

16:45 – 17:45

Supporting Organizations:

Phosphor Research Society, The Electrochemical Society of Japan
The 125th Research Committee on Mutual Conversion between
Light and Electricity, Japan Society for Promotion of Science

**Evening Get-Together
with Wine**

Tuesday, December 2, 2014
18:00 – 20:00

Observation Deck (31F),
Hotel Nikko Niigata
(Sponsored by Merck Ltd., Japan)
See page 12 for details

IMID 2014

August 26 – 29, 2014

EXCO

Daegu, Korea

Workshop on Field Emission Displays, CRTs and Plasma Displays

Friday, December 5

9:00 - 9:05

Room 302 B

Opening

Opening Remarks

9:00

H. Mimura, Shizuoka Univ., Japan

9:05 - 10:35

Room 302 B

FED1: Novel Devices and Applications

Chair: Y. Gotoh, Kyoto Univ., Japan

Co-Chair: F. Wakaya, Osaka Univ., Japan

FED1 - 1: *Invited* High Resolution Optical Imaging for Living Cells with Electron Beam Excitation

9:05

Y. Kawata^{,**}, Y. Nawa^{*}, W. Inami^{*,**}*

^{}Shizuoka Univ., Japan*

*^{**}JST-CREST, Japan*

FED1 - 2: Electrostatic-Focusing Spindt-Type FEA with Improved Electron-Beam Extraction Efficiency for FEA-HARP Image Sensor

9:35

Y. Honda^{,**}, M. Nanba^{*}, K. Miyakawa^{*}, M. Kubota^{*},
M. Nagao^{***}, N. Egami^{****}*

^{}NHK, Japan*

*^{**}Shizuoka Univ., Japan*

*^{***}AIST, Japan*

*^{****}Kinki Univ., Japan*

FED1 - 3: A High-Sensitivity Photodetector Made of Amorphous Selenium and Nitrogen-Doped Diamond Cold Cathode

9:55

T. Masuzawa, T. Yamada^{}, Y. Neo, H. Mimura,
D. H. C. Chua^{**}, K. Okano^{***}*

Shizuoka Univ., Japan

^{}AIST, Japan*

*^{**}Nat. Univ. of Singapore, Singapore*

*^{***}Int. Christian Univ., Japan*

FED1 - 4 **Photoassisted Field Emission from P-Type Silicon FEAs**
10:15

H. Shimawaki, M. Nagao^{}, T. Yoshida^{*}, Y. Neo^{**},
H. Mimura^{**}, F. Wakaya^{***}, M. Takai^{***}*

Hachinohe Inst. of Tech., Japan

^{}AIST, Japan*

*^{**}Shizuoka Univ., Japan*

*^{***}Osaka Univ., Japan*

----- Break -----

10:45 - 12:05

Room 302 B

FED2: Fabrication Processes and New Materials

Chair: H. Mimura, Shizuoka Univ., Japan

Co-Chair: H. Shimawaki, Hachinohe Inst. of Tech., Japan

FED2 - 1 **Fabrication and Emission Characteristics of Ni and Mo Spindt-Type FEAs with Volcano-Structured Focusing Electrode**
10:45

M. Nagao

AIST, Japan

FED2 - 2 **Computer Simulation of Electron Beam Trajectories in Double-Gated Spindt-Type FEAs**
11:05

Y. Gotoh, H. Tsuji, M. Nagao^{}*

Kyoto Univ., Japan

^{}AIST, Japan*

FED2 - 3 **Enhanced Field Emission of CuO Nanowire Arrays by Coating of CNT Network Film**
11:25

H. Hu, D. Zhang, J. Lin, F. Li, T. Guo

Fuzhou Univ., China

FED2 - 4 **Electron Emission from MIM Cathodes with an Ag Nanowire Top Electrode**
11:45

J. Lin, H. Hu, L. Hu, F. Li, T. Guo

Fuzhou Univ., China

----- Lunch -----

13:30 - 14:50

Room 302 B

FED3: FE Mechanisms and PDP Protective Layers

Chair: M. Nagao, AIST, Japan

Co-Chair: H. Kajiyama, Tokushima Bunri Univ., Japan

**FED3 - 1
13:30 Observation of Fringelike Emission Pattern in
Magnetic Field***Y. Yamada, S. Abo, K. Murakami*, F. Wakaya, M. Abe,
M. Takai**Osaka Univ., Japan***Univ. of Tsukuba, Japan***FED3 - 2
13:50 Work Function Measurements of Tungsten Surface
Modified by Praseodymium Oxide by Using Field
Emission Microscopy and Retarding Method***T. Kawakubo, K. Kanbara, T. Kitani, H. Nakane***Nat. Inst. of Tech. Kagawa, Japan***Muroran Inst. of Tech., Japan***FED3 - 3
14:10 High-Intensity Deep-UV Radiation and Exo-Electron
Emission of MgO Powders for AC PDPs***M. Sakai***, H. Asano***, Y. Fukui*, T. Tsujita**,
M. Nishitani***, H. Kimiya*, R. Murai*, M. Kitagawa*****Panasonic, Japan****Osaka Univ., Japan***FED3 - 4
14:30 Electron Storage by Photochromic Transition of
Oxide Nanoparticle***H. Kajiyama, T. Matsuura, M. Maekawa*, K. Uchino*,
K. Takata**, S. Inoue*****Tokushima Bunri Univ., Japan***Kyushu Univ., Japan****Kansai Univ., Japan*****Hiroshima Univ., Japan*

----- Break -----

15:15 - 16:35

Room 302 B

FED4: Summing Up of PDP History

Chair: L. Weber, Consult., USA

Co-Chair: T. Shiga, Univ. of Electro-Commun., Japan

**FED4 - 1: Invited Summing Up of the PDP History and a Peek
15:15 at Plasma Technologies Beyond Displays***S. Mikoshiba**Univ. of Electro-Commun., Japan*

FED4 - 2 **A Flexible Luminous Array Film as a Radiation Area
15:55** **Selectable Hg-Free Ultra-Narrow Band UVB Light
Source**

*B. Guo, K. Awamoto, H. Hirakawa, T. Nishimoto**

Plexie, Japan

**Yumex, Japan*

FED4 - 3 **Photosynthesis Promotion by Pulsed Light from an
16:15** **AC-PDP Based Fluorescent Film**

*H. Kajiyama, T. Ohata, I. Kanmai, S. Nagahara, T. Kono,
S. Funai, T. Matsuura*

Tokushima Bunri Univ., Japan

Author Interviews and Demonstrations

16:45 – 17:45

Supporting Organizations:

JSPS 158th Committee on Vacuum Nanoelectronics
Plasma Display Technical Meeting

RECEPTION

Wednesday, December 3, 2014

19:00 – 21:00

Room “Continental” (4F)

Hotel Okura Niigata

See page 12 for details

Late-News Papers

Due September 25, 2014

Submit a two-page camera-ready manuscript
via IDW website:

<http://www.idw.or.jp/latenews.html>

Workshop on OLED Displays and Related Technologies

Wednesday, December 3

14:00 - 15:20

Snow Hall B

OLED1: Advanced OLED Technologies (1)

Chair: T. Wakimoto, Merck, Japan

Co-Chair: T. Uchida, Tokyo Polytechnic Univ., Japan

OLED1 - 1 Flexibility and Reliability Improvement for Foldable OLED

14:00

S.-T. Yeh, G. Chen, C.-H. Tsai, Y.-H. Peng, J.-C. Ho, C.-C. Lee

ITRI, Taiwan

OLED1 - 2 An Ultrathin AMOLED Integrated with On-Cell Touch Sensor for Flexible Displays

14:20

K.-T. Chen, S.-W. Chen, S.-A. Chen, P.-H. Wang, C.-C. Chang, S.-H. Lee, C.-W. Jung, M.-H. Yeh, K.-J. Chen, J.-Y. Yan, J.-C. Ho, C.-C. Lee

ITRI, Taiwan

OLED1 - 3 Black Screen for High Contrast Smart Window AMOLED Display

14:40

D. C. Choe, G. W. Kim, R. Lampande, J. H. Kwon

Kyung Hee Univ., Korea

OLED1 - 4 High-Transparent 4.65-in. QHD AMOLED Display with 21% Transmittance

15:00

C.-T. Lee, Y.-Y. Huang, C.-C. Tsai, C.-C. Kuo, C.-H. Chiu, J.-H. Huang, C.-C. Tsai, Y.-H. Cheng, C.-L. Chen, C.-T. Liang, W.-C. Yen, J.-S. Huang, Y.-W. Chiu, Y.-W. Liu

Chunghwa Picture Tubes, Taiwan

----- Break -----

15:45 - 16:45

Snow Hall B

OLED2: Advanced OLED Technologies (2)

Chair: Y. Kijima, Sony, Japan

Co-Chair: S. Naka, Univ. of Toyama, Japan

OLED2 - 1 OLED on Silicon for Sensor Applications

15:45

*M. Thomschke, M. Jahnel, B. Beyer, K. Fehse, U. Vogel
Fraunhofer COMEDD, Germany*

**OLED2 - 2 Viewing Angle Spectral Analysis of OLED Display
16:05 Light Emission Properties**

*P. M. Boher, T. Leroux, T. Bignon, V. Collomb-Patton
ELDIM, France*

**OLED2 - 3 Natural Stereoscopic Effect Achieved by High-
16:25 Resolution OLED Display**

*Y. Yanagisawa, H. Ikeda, M. Jikumaru, D. Kubota,
Y. Hirakata, S. Yamazaki, M. Hirose*, M. Kasuga**,***
Semiconductor Energy Lab., Japan
*Univ. of Tokyo, Japan
**Sakushin Gakuin Univ., Japan
***Utsunomiya Univ., Japan*

Author Interviews and Demonstrations

17:15 – 18:15

Thursday, December 4

9:00 - 10:10

Snow Hall B

**OLED3: OLED Process Technologies
Special Topics of Interest on Printed Electronics**

Chair: T. Shimizu, NHK, Japan

Co-Chair: T. Komatsu, Panasonic, Japan

**OLED3 - 1: Invited OLED Device Fabrication by Ink-Jet Printing
9:00 Technology**

*T. Sonoyama, M. Uchida, T. Sago, S. Watanabe,
K. Ishida, M. Ito, M. Ishida, M. Yamada, Y. Okawa,
S. Tanabe, H. Kiguchi
Seiko Epson, Japan*

**OLED3 - 2: Invited Important Technologies of Ink Jet System for
9:25 OLED Display Fabrication**

T. Hayashi, K. Oshima, S. Takei, A. Shimamura,
Y. Konta, S. Tanabe*
Tokyo Electron, Japan
Seiko Epson, Japan

**OLED3 - 3 UV-Activated Transparent Desiccant for Practical
9:50 OLED Encapsulation Process**

*H. Katsui, T. Miyasako, T. Arai, M. Takahashi,
N. Onimaru, N. Takamatsu, T. Yamamura, K. Konno,
K. Kuriyama
JSR, Japan*

----- Break -----

10:45 - 11:55

Snow Hall B

OLED4: OLED Materials (1)
Special Topics of Interest on Printed Electronics

Chair: K. Nakayama, Yamagata Univ., Japan

Co-Chair: K. Monzen, Nissan Chem. Inds., Japan

OLED4 - 1: *Invited* Blue Fluorescent OLEDs for Printed Display Applications

10:45

E. Boehm, C. Pflumm, H. Heil, S. Meyer, L.-I. Rodriguez, B. Burkhart, F. Eckes, K. Stegmaier, H. Buchholz
Merck KGaA, Germany

OLED4 - 2: *Invited* Development and Manufacture of Solution-Processed White OLED Lighting Panel

11:10

T. Ogata
Mitsubishi Chem. Group S&T Res. Ctr., Japan

OLED4 - 3 The Soluble Hole Injection Materials and the Inks Applicable to OLED Devices

11:35

N. Otani, H. Koga, S. Moriyama, T. Endo, N. Nakaie, K. Monzen
Nissan Chem. Inds., Japan

Author Interviews and Demonstrations

18:30 – 19:30

13:30 - 16:30

Exhibition Hall B

Poster OLEDp1: OLED Poster
Special Topics of Interest on Lighting Technologies

OLEDp1 - 1 Flexible Hybrid White Light Emitting Diodes Based on Small Molecules and Quantum Dots

W. Wu, F. Li, H. Hu, J. Lin, T. Guo
Fuzhou Univ., China

OLEDp1 - 2 Novel Phosphorescent Host Material for Tunable Hybrid White OLED Devices

H.-L. Huang, B. Balaganesan, H.-M. Kuo, B.-W. Xie, T.-C. Chao, M.-R. Tseng
eRay Optoelect. Tech., Taiwan

13:30 - 16:30

Exhibition Hall B

Poster OLEDp2: OLED Poster
Special Topics of Interest on Printed Electronics

OLEDp2 - 1 High-Mobility Solution-Processed Organic Field-Effect Transistors with Channel Length of 5 μm

R. Nakamichi, T. Nagase, T. Kobayashi, Y. Sadamitsu, H. Naito*

Osaka Pref. Univ., Japan

**Nippon Kayaku, Japan*

13:30 - 16:30

Exhibition Hall B

Poster OLEDp3: OLED Poster

OLEDp3 - 1 Polyfluorenes Containing Partially Hydrolyzed Phosphonate Pendant Groups as Electron-Injection Layer for PLEDs

Y. Chen, C.-Y. Chou, H.-A. Lu, C.-P. Chen, Y.-J. Lin, C.-S. Wu

Nat. Cheng Kung Univ., Taiwan

OLEDp3 - 2 Inverted Transparent Organic Light-Emitting Diodes (i-TOLEDs) Comprising Metal Oxide Compounds as Electron-Injection Layer without Alkali Metal

R. Tejima, M. Ichikawa, Y. Hoshi, T. Uchida

Tokyo Polytechnic Univ., Japan

OLEDp3 - 3 The Study of High Resolution Micro-Contact Printing Technology on 4-in. 441 ppi FHD OLED Display

J.-A. Cheng, P.-C. Lin, Q. Li, Z. Zhu*, D. An*, L.-N. Chien, C.-T. Lin, I.-W. Wu**, I.-M. Lu, S. Fan**

Yeh Hsin Tech. Consulting, Taiwan

**Tsinghua Univ., China*

***Century Tech., China*

OLEDp3 - 4 Enhancement of Hole-Injection and Power Efficiency of Organic Light Emitting Devices Using an Ultra-Thin MnO-Doped ZnO Buffer Layer

H.-W. Lu, P.-C. Kao, S.-Y. Chu*

Nat. Cheng Kung Univ., Taiwan

**Nat. Chiayi Univ., Taiwan*

OLEDp3 - 5 Characterization of Metals/Pentacene Interfaces by Hard X-Ray Photoelectron Spectroscopy

I. Hirose, T. Watanabe, H. Oji, K. Tada, N. Yoshimoto**

JASRI, Japan

**Iwate Univ., Japan*

- OLEDp3 - 6 Surface-Light-Emitting Transistors Using a P-Type Metal-Base Organic Transistors**
N. Kogasaka, H. Muto, K. Nakayama
Yamagata Univ., Japan
- OLEDp3 - 7 A Characterization and Evaluation Method for a Gas Barrier Film and Polarizer to Predict Minimum Bending Diameter Allowed in a Flexible OLED Device**
A. T. Huang, S.-T. Ho, S.-H. Hung, M.-T. Lee
AU Optronics, Taiwan
- OLEDp3 - 8 Analysis of Exciton Quenching Dynamics of Ir(ppy)₃ with Hole Measured by Time-Resolved Luminescence Spectroscopy**
S. Oyama, H. Sakai, H. Murata
JAIST, Japan
- OLEDp3 - 9 Detection of Charged Species in Operating Organic Devices Using Multiple Reflection Absorption Spectra**
Y. Akagi, H. Sakai, H. Murata
JAIST, Japan
- OLEDp3 - 10 In Situ Characterization of the Charge Transport and Crystal Structural Properties in Organic Thin Film Transistor**
T. Watanabe, T. Koganezawa, M. Kikuchi, K. Nishida*, N. Yoshimoto*, I. Hirozawa*
JASRI, Japan
**Iwate Univ., Japan*
- OLEDp3 - 11 Mechanistic Analysis for Preferable Performances at High Temperature of the OLED Device with New Electron Transport Material**
K. Nomura, T. Tanaka
TOSOH, Japan
- OLEDp3 - 12 High Efficiency Blue Phosphorescent Organic Light-Emitting Diodes with Various Host Materials**
S. H. Kim, Y. J. Kim, Y.H.Son, J.M.Lee, B.Y.Kang, C.H.Noh, S.H.Kim, J.H.Kwon*
Kyung Hee Univ., Korea
**Samsung Elect., Korea*
- OLEDp3 - 13 Improvement on Equivalent Circuit Model for OLED with Its Luminance Decay Characteristics**
J. Wu, Z. Zou, Y. Tang, Y. Zheng
Southeast Univ., China

- OLEDp3 - 14 Efficient Ionization Method of Atomized Droplet for Fabricating Multilayer Organic Light-Emitting Diode**
A. Sato, T. Fukuda, N. Kamata, Z. Honda
Saitama Univ., Japan
- OLEDp3 - 15 A Fast Evaluation of Barrier Tapes for In-Plane Water Vapor Permeation in Conventional Ca Film Tests**
S.-T. Ho, S.-H. Hung, W.-L. Hung, C.-L. Wang, M.-T. Lee
AU Optronics, Taiwan
- OLEDp3 - 16 Blue Phosphorescence Light-Emitting Diode with a New CbzOXD Host**
H.-J. Chen, T.-L. Chiu, Y.-H. Hsieh, M.-K. Leung*, J.-H. Lee**
Yuan Ze Univ., Taiwan
**Nat. Taiwan Univ., Taiwan*
- OLEDp3 - 17 High Efficiency Blue Phosphorescence Light-Emitting Diode with Novel CbzTAZ Host**
H.-J. Chen, T.-L. Chiu, P.-S. Wang, J.-H. Lee*, Y.-H. Hsieh*, M.-K. Leung**
Yuan Ze Univ., Taiwan
**Nat. Taiwan Univ., Taiwan*
- OLEDp3 - 18 Enhancement of Polarization Ratio on Polarized Organic Light Emitting Diodes Using Anisotropic Micro Lens Arrays**
D. M. Lee, Y. D. Kim, S. I. Jo, C.-J. Yu, J.-H. Kim
Hanyang Univ., Korea
- OLEDp3 - 19 Optical Modeling of V-Shaped Organic Solar Cells in Oblique Incidence of Sunlight**
J. Yoon, K. Kang, J. Kim
Kyung Hee Univ., Korea
- OLEDp3 - 20 Solution Processed N-P Junction for High Performance Organic Light Emitting Diode**
J. Kim, H.-M. Kim, J. Jang
Kyung Hee Univ., Korea

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

9:00 - 10:25

Snow Hall A

OLED5: OLED Materials (2)

Chair: S. Aratani, Hitachi, Japan

Co-Chair: T. Ikuta, JNC Petrochem., Japan

**OLED5 - 1: *Invited* Latest Status of Soluble-OLED Material
9:00 Development***T. Yamada, Y. Tsubata, D. Fukushima, K. Ohuchi,
N. Akino**Sumitomo Chem., Japan***OLED5 - 2 Electrical Properties of Solution-Processed Hole
9:25 Injection Layer Analyzed by Impedance
Spectroscopy***T. Endo, Y. Horiuchi, N. Otani, K. Monzen**Nissan Chem. Inds., Japan***OLED5 - 3 Design to Electron Injection Complex Using
9:45 Molecular Energy Calculation for High Performance
OLED***J. H. Kong, G. H. Kim, M. J. Park, H. W. Bae, J. H. Kwon**Kyung Hee Univ., Korea***OLED5 - 4 Iridium-Free OLED Solutions for the Whole Color
10:05 Spectrum***M. Mydlak, D. Volz, D. Zink, T. Baumann, H. Flügge,
C. Fléchon, J. Navarro**CYNORA, Germany***Author Interviews and Demonstrations**

16:45 – 17:45

Supporting Organizations:

The Japanese Society of Printing Science and Technology

The Society of Photography and Imaging of Japan

IDW '15

The 22nd International Display Workshops

December 8 – 11, 2015

Otsu Prince Hotel

Otsu, Japan

<http://www.idw.or.jp>

Workshop on 3D/Hyper-Realistic Displays and Systems

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster 3Dp1: 3D/Hyper-Realistic Displays

- 3Dp1 - 1** **Design of Pixel Structure for Color Electronic Holography using One-Dimensional Spatial Light Modulator**
A. Ueno, K. Nitta, O. Matoba
Kobe Univ., Japan
- 3Dp1 - 2** **Computer-Generated Hologram using Range Sensors and Digital Cameras at Arbitrary Locations**
K. Tai, Y. Sakamoto
Hokkaido Univ., Japan
- 3Dp1 - 3** **Automatic Geometric Calibration in Full-Parallax 3D Display using Holographic Screen**
R. Higashida, M. Yamaguchi
Tokyo Inst. of Tech., Japan
- 3Dp1 - 4** **Volumetric 3D Display using Rotating Screens**
S. Suzuki, C. Fujikawa, M. Omodani
Tokai Univ., Japan
- 3Dp1 - 5** **Floating Depth-Fused 3D Image using Multi-Focal Lens 3D System for Image Data Reduction**
R. Tanimoto^{}, T. Kurokawa^{*}, H. Yamamoto^{***}, S. Suyama^{*}*
^{*}*Univ. of Tokushima, Japan*
^{**}*Utsunomiya Univ., Japan*
- 3Dp1 - 6** **Wide Viewing Zone by Dynamic Head Movement in Edge-Based DFD Display**
T. Soumiya, H. Kuribayashi^{}, H. Yamamoto^{**}, S. Suyama*
^{*}*Univ. of Tokushima, Japan*
^{*}*Nikon, Japan*
^{**}*Utsunomiya Univ., Japan*
- 3Dp1 - 7** **Crossed-Mirror Array Converges Sound Wave in 3D Space**
R. Kujime, K. Miyamoto, S. Suyama, H. Yamamoto^{}*
^{*}*Univ. of Tokushima, Japan*
^{*}*Utsunomiya Univ., Japan*

- 3Dp1 - 8** **Perceived Depth Degradation by Delay Time and Discontinuous Image Flipping in Monocular Motion Parallax Display**
S. Yamada^{}, I. Ishii^{**}, H. Yamamoto^{***}, S. Suyama^{*}*
^{*}*Univ. of Tokushima, Japan*
^{**}*Hiroshima Univ., Japan*
^{***}*Utsunomiya Univ., Japan*
- 3Dp1 - 9** **Elimination and Mechanism Study of Binocular Luminance Difference in a 240 Hz Shutter-Type 3D LCDs**
Y. Tian, X. Zhang, J. Hsu, C. Chen, C. Dong, X. Lian
Shenzhen China Star Optoelect. Tech., China
- 3Dp1 - 10** **Analysis and Improvement of Color Shift on Angles for 6-in. Stereoscopic Displays with Barriers**
H. Wu, H.-J. Yu, D. Xue, Z.-W. Cui, X.-Q. Zhao, Z. Hong, Y.-Y. Yin, L. Xin
Beijing BOE Optoelect. Tech., China
- 3Dp1 - 11** **Crosstalk Suppression Based on Gray Couples Measurement**
J. Wang, X. Li, Y. Zhang, Z. Xia
Southeast Univ., China
- 3Dp1 - 12** **Study of Imaging Performance Affected by Color Pixel Arrangements and Lenticular Lenses Configuration for Autostereoscopy**
Y.-W. Chen, Z.-H. Jhong, C.-R. Sheu
Nat. Cheng Kung Univ., Taiwan
- 3Dp1 - 13** **KANSEI Multimedia Display System That Can Control Smell Discharge Direction and the Psychological Effects**
M. Tanaka, R. Shu, R. Shinohara, K. Tomono, A. Tomono
Tokai Univ., Japan

----- Lunch -----

13:30 - 15:00

Room 302 A

3D1: Holography

Chair: H. Yamamoto, Utsunomiya Univ., Japan
 Co-Chair: M. Tsuchida, NTT, Japan

3D1 - 1: 13:30 ***Invited* Real-Time Pupil Tracking for Holographic Display**

H.-G. Choo, K. A. Moon, J. Kim
ETRI, Korea

- 3D1 - 2:** *Invited* **Color Holographic Display Based on Shifted and Scaled Fractional Fourier Transform**
13:55
J. Xia, C. Chang, Y. Jiang, W. Lei
Southeast Univ., China
- 3D1 - 3** **3D Hologram Reconstruction in the Front of a Transmission Diffuser Screen**
14:20
J.-F. Chang, W.-C. Su
Nat. Changhua Univ. of Education, Taiwan
- 3D1 - 4** **DMD as a Display Device for Holographic Displays**
14:40
J.-Y. Son, B.-R. Lee^{}, M.-C. Park^{**}, O. Chernyshov*
Konyang Univ., Korea
^{*}*ETRI, Korea*
^{**}*KIST, Korea*

----- Break -----

15:15 - 16:30

Room 301

3D2: Interactive 3D Display Technology

Special Topics of Interest on Augmented Reality and Virtual Reality

- Chair: M. Tsuchida, NTT, Japan
 Co-Chair: K. Yamamoto, NICT, Japan

- 3D2 - 1:** *Invited* **Interactive Display Technologies using High-Speed Image Processing**
15:15
M. Ishikawa
Univ. of Tokyo, Japan

- 3D2 - 2:** *Invited* **Floating Digital Signage Based on Aerial Imaging Techniques**
16:00
H. Yamamoto^{,**,**}, S. Suyama^{***}*
^{*}*Utsunomiya Univ., Japan*
^{**}*JST-CREST, Japan*
^{***}*Univ. of Tokushima, Japan*

----- Break -----

17:00 - 18:40

Room 301

3D3: Omnidirectional Hyper-Realistic System

Special Topics of Interest on Augmented Reality and Virtual Reality

- Chair: K. Yamamoto, NICT, Japan
 Co-Chair: M. Tsuchida, NTT, Japan

- 3D3 - 1:** *Invited* **Characteristic of the Ultra-Realistic Dome Images Estimated from Viewing Behavior**
17:00
M. Okyudo, C. Yoshizumi
Wakayama Univ., Japan

3D3 - 2: 17:25 *Invited* **Development of Spherical Image Camera RICOH THETA**

*M. Shohara
Ricoh, Japan*

3D3 - 3: 17:50 *Invited* **Omnidirectional Video Streaming System with HMD**

*D. Ochi
NTT, Japan*

3D3 - 4: 18:15 *Invited* **Holographic HMD with Wide Visual Field**

*Y. Sakamoto
Hokkaido Univ., Japan*

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

9:00 - 10:20

Room 301

3D4: 3D/Hyper-Realistic Displays (1)

Chair: H.-G. Choo, ETRI, Korea

Co-Chair: K. Yamamoto, NICT, Japan

3D4 - 1 9:00 **Realization of Homogeneous Brightness for Autostereoscopic Displays with Directional Backlights Composed of Convex Lens Arrays**

*S. Ishizuka, T. Mukai, H. Kakeya
Univ. of Tsukuba, Japan*

3D4 - 2 9:20 **Floating Touch Display Based on a Heterogeneous Imaging System**

Y. Maeda, D. Miyazaki, S. Maekawa
Osaka City Univ., Japan
Parity Innovations, Japan

3D4 - 3 9:40 **A 2D-3D Display with a 120 Hz Hybrid Spatial-Temporal Color LCD**

*Y. Weng, Y. Zhang, X. Li
Southeast Univ., China*

3D4 - 4 10:00 **True Color Optical Simulation of Integral Imaging 3D Display**

*J. Chen, B. Fang, D. Fan, Q. Liao, Q. Wei, C. Yang,
C. Lee, C. Lo, A. Lien*
Shenzhen China Star Optoelect. Tech., China
TCL Corporate Res., China

----- Break -----

10:45 - 11:45

Room 301

3D5: 3D/Hyper-Realistic Displays (2)

Chair: J.-Y. Son, Konyang Univ., Korea

Co-Chair: M. Tsuchida, NTT, Japan

3D5 - 1
10:45**3D Image Qualities for the 4K2K TVs***J.-Y. Huang, H.-S. Chen, P.-L. Sun, R. Luo***Nat. Taiwan Univ. of S&T, Taiwan***Univ. of Leeds, UK***3D5 - 2**
11:05**Examination of Night Driving Support System by the Video Infrared Stereo Night Vision and 3D Television***S. Suidu, T. Endo, M. Yamamoto**Niigata Univ., Japan***3D5 - 3**
11:25**4-D Floating Image Display using Dual Off-Axis Parabolic Reflectors***K. Li**Wavien, USA*

----- Lunch -----

13:30 - 14:55

Room 301

3D6: Optical Devices for 3D System

Chair: S. Yano, Shimane Univ., Japan

Co-Chair: M. Tsuchida, NTT, Japan

3D6 - 1:
13:30***Invited* Expanding Depth Directional Stereoscopic Viewing Zone by Continuous Varying Optical Power Lens with Removing Structural Crosstalk in Auto-Stereoscopic 3D***K.-H. Lee**Korea Photonics Tech. Inst., Korea***3D6 - 2**
13:55**A Novel Autostereoscopic Display Designed by Use of Wave Optics Simulation***A. Yuuki, T. Fujino, T. Satake, Y. Niwano, S. Nagano**Mitsubishi Elec., Japan***3D6 - 3**
14:15**Analytical Solutions (Moiré Solver) of the Parameters of 3D Auto-Stereoscopic Multi-View Display.***F. Mukhtarov, S. D. Hwang**Samsung Elect., Korea*

**3D6 - 4
14:35 The Design of a Stereo Microscopic Eyepiece by Using a Biprism**

S.-W. Yang, T.-H. Lin^{}, C.-Y. Chen^{*}, K.-L. Huang^{**},
P.-J. Wu^{***}*

Nat. Central Univ., Taiwan

^{}Nat. Yunlin Univ. of S&T., Taiwan*

*^{**}Ming Dao Univ., Taiwan*

*^{***}Nat. Chiao Tung Univ., Taiwan*

----- Break -----

15:15 - 16:20

Room 301

3D7/VHF7: Visual Perception for 3D System

Chair: K.-H. Lee, Korea Photonics Tech. Inst., Korea

Co-Chair: Y. Hisatake, Japan Display, Japan

**3D7/
VHF7 - 1:
15:15 *Invited* Towards the ISO Guideline for Image Safety
in Stereoscopic Viewing**

T. Bando

AIST, Japan

**3D7/
VHF7 - 2
15:40 The Impact of Screen Size on 3D Flicker-Free
Luminance**

P.-L. Sun^{}, Y.-P. Hsieh^{*}, H.-S. Chen^{*}, M. R. Luo^{*,**}*

^{}Nat. Taiwan Univ. of S&T, Taiwan*

*^{**}Univ. of Leeds, UK*

**3D7/
VHF7 - 3
16:00 Measurement of Visual Fatigue Induced by
Stereoscopic Display Using an Oddball Based
Event-Related Potential Experiment**

*P. Ye, H. Liang, J. Wang, F. Chen, S. Yang, J. Chen,
X. Wu, D. Gao*

Nat. Sun Yat-Sen Univ., China

Author Interviews and Demonstrations

16:45 – 17:45

Supporting Organizations:

Technical Group on Three-Dimensional Image Technology, ITE
Holographic Display Artists and Engineers Club, The Japan Society of
Applied Physics

Workshop on Applied Vision and Human Factors

Thursday, December 4

9:00 - 10:10

Room 302 A

VHF1: Optical Measurements

Chair: J. Bergquist, Nokia Techs., Japan

Co-Chair: Y. Hisatake, Japan Display, Japan

VHF1 - 1: *Invited* General FPD Mura Index under the IEC Measurement Standard

9:00

S. Hasegawa, S. Tomioka, K. Nagamine**

Sony Visual Prods., Japan

**Sony, Japan*

VHF1 - 2 Novel Evaluation Method of Sparkle for LCDs with Different Anti-Glare Films

9:30

T.-W. Hsu, Y.-H. Chiang, C.-W. Chen

AU Optronics, Taiwan

VHF1 - 3 Spectral Imaging Analysis of OLED Display Light Emission Properties

9:50

P. M. Boher, T. Leroux, T. Bignon, V. Collomb-Patton

ELDIM, France

----- Break -----

10:45 - 11:55

Room 302 A

VHF2: Color and OLEDs

Chair: S. Hasegawa, Sony Visual Prods., Japan

Co-Chair: K. Masaoka, NHK, Japan

VHF2 - 1: *Invited* Visual Effects of Curved AMOLEDs

10:45

J. S. Kimmel

Nokia Techs., Finland

VHF2 - 2 A Monitor-Based System for Digital Quantification of Deuteranomalous Vision

11:15

*Y. Tsai, H. Chen, M. R. Luo**

Nat. Taiwan Univ. of S&T, Taiwan

**Univ. of Leeds, UK*

VHF2 - 3 Estimation of the Helmholtz-Kohrausch Effect in Natural Images Using Gaze Tracking Data

11:35

T. Shizume, G. Ohashi, H. Takamatsu, Y. Shimodaira*

Shizuoka Univ., Japan

**NEC Display Solutions, Japan*

13:30 - 16:30

Exhibition Hall B

Poster VHFp1: Applied Vision and Human Factors

- VHFp1 - 1** **Evaluating and Simulating on Luminance Discrepancy between Centre and Fringe of a Liquid Crystal Display**
J. Wang, C. Wu, H. Liu, S. Lo
Shenzhen China Star Optoelect. Tech., China
- VHFp1 - 2** **Object Images Quality Improvement for Transparent Display**
Y.-H. Tsai^{,**}, W.-D. Jeng^{*}, K.-L. Lo^{**}, T.-W. Huang^{*}, O.-Y. Mang^{*}*
^{*}*Nat. Chiao Tung Univ., Taiwan*
^{**}*ITRI, Taiwan*
- VHFp1 - 3** **Image Qualities of the Curved OLED Displays with Different Picture Setting Modes**
J.-Y. Huang, C.-W. Hsu, H.-S. Chen, P.-L. Sun, M. R. Luo^{}*
^{*}*Nat. Taiwan Univ. of S&T, Taiwan*
^{*}*Univ. of Leeds, UK*
- VHFp1 - 4** **Quantitative Visual Assessment of Moving Image Quality for 4K8K UHD TV Systems**
I. Kawahara, H. Sato, H. Tabata
Keisoku Giken, Japan
- VHFp1 - 5** **Equivalent Spatial Resolution of RxGxBx Subpixel Arrangements**
H.-C. Lin, C.-H. Wen, P.-L. Sun, S.-P. Wang^{}, K.-J. Hu^{*}, M.-C. Lo^{**}*
^{*}*Nat. Taiwan Univ. of S&T, Taiwan*
^{*}*ITRI, Taiwan*
^{**}*Shih Hsin Univ., Taiwan*
- VHFp1 - 6** **Comparison of Accommodation and Convergence among Real Object, 2D Display and 3D Display When a Target Moves along the Depth Direction**
S. Mochiduki, Y. Yokoyama, H. Takahira, M. Yamada
Tokai Univ., Japan
- VHFp1 - 7** **Analysis of Fundamental Characteristics of Movement of Eye and Head When Indexing the Target by the Finger**
K. Kikuchi, H. Takahira, R. Ishiro, Y. Tanaka, M. Endou, M. Yamada
Tokai Univ., Japan

- VHFp1 - 8 Analysis of Accommodation and Convergence while Viewing 4K Images**
H. Takahira, S. Mochiduki, Y. Yokoyama, M. Yamada
Tokai Univ., Japan
- VHFp1 - 9 Analysis of Convergence and Accommodation while Viewing 3D Movies**
Y. Shiratori, M. Kitade, H. Takahira, S. Mochiduki, Y. Yokoyama, M. Yamada
Tokai Univ., Japan
- VHFp1 - 10 Analysis of Accommodation and Convergence Eye Movement among Medium When a Target Moves along the Depth Direction**
Y. Yokoyama, S. Mochiduki, H. Takahira, M. Yamada
Tokai Univ., Japan

----- Break -----

17:00 - 18:00

Room 302 A

VHF3: Moving Image Quality

Chair: T. Kurita, NHK Media Tech., Japan

Co-Chair: Y. Nakamura, Mitsubishi Elec., Japan

- VHF3 - 1 Method of Verifying Accuracy of Pursuit Cameras**
17:00 *M. Rejhon, J. Bergquist*, E. F. Kelley**, P. A. Boynton****
Rejhon Techs., Canada
**Nokia Techs., Japan*
***KELTEK, USA*
****NIST, USA*

- VHF3 - 2 A Method of Image Quality Evaluation for Adaptive Temporal Aperture Control with Hold-Type Displays**
17:20 *T. Usui, H. Sato, Y. Takano, T. Yamamoto, K. Ishii*
NHK, Japan

- VHF3 - 3 Image Quality Metrics for Color Breakup Based on Perceived Image Simulation**
17:40 *K. Hirai, N. Torige, T. Horiuchi, S. Tominaga, T. Shibuya*, F. Hasegawa*, M. Nose**
Chiba Univ., Japan
**Ricoh, Japan*

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

9:00 - 10:00

Room 201

VHF4: Display Legibility

Chair: Y. Shimodaira, Shizuoka Univ., Japan
 Co-Chair: N. Hiruma, NHK, Japan

VHF4 - 1 **Model for Flicker Analysis in Reflective LCD in Low
 9:00** **Frequency Driving**

*Y. Kubota, R. Hatsumi, S. Fukai, D. Kubota, Y. Hirakata,
 S. Yamazaki, M. Hirose^{*}, M. Kasuga^{**} ^{***}*

Semiconductor Energy Lab., Japan

^{}Univ. of Tokyo, Japan*

*^{**}Sakushin Gakuin Univ., Japan*

*^{***}Utsunomiya Univ., Japan*

VHF4 - 2 **Effect of Font Types and Pixel Density of Electronic
 9:20** **Displays on the Legibility of Japanese Characters**

Y. Hisatake, T. Kawamorita^{}, Y. Kanno, S. Takahashi^{**},
 M. Ito^{**}, H. Takahashi^{**}*

Japan Display, Japan

^{}Kitasato Univ., Japan*

*^{**}DNP, Japan*

VHF4 - 3 **Psychological Derivation of Optimal Line Space for
 9:40** **Legible Japanese Documents Based on Scheffe's
 Method of Paired Comparison**

Y. Yonezu, T. Tokui, N. Ishikawa, T. Matsui

Gunma Univ., Japan

----- Break -----

10:45 - 12:15

Room 201

DES3/VHF5: System Design and Evaluation in Augmented Reality
Special Topics of Interest on Augmented Reality and Virtual Reality

Chair: K. Morita, Nat. Traffic Safety & Environment Lab., Japan
 Co-Chair: K. Sakamoto, Panasonic, Japan

DES3/ ***Invited* Simulation of Traffic Accident Scenarios with
 VHF5 - 1:** **an Augmented Reality Vehicle**
10:45

N. Uchida, T. Tagawa, K. Sato

Japan Automobile Res. Inst., Japan

DES3/ ***Invited* The Realistic 3D Image Display Using Direct
 VHF5 - 2:** **Light Scanning Method**
11:10

H. Horimai, K. Hattori^{}, T. Umezaki*

3Dragons LLC, Japan

^{}Chubu Univ., Japan*

**DES3/
VHF5 - 3
11:35** **Fast Calculation Algorithm Based on Point-Based Method for CGHs Using Polygon Model**
Y. Ogihara, Y. Sakamoto
Hokkaido Univ., Japan

**DES3/
VHF5 - 4
11:55** **The Superiority of Widespread Monocular Augmented Reality Presentation in a Manual Tracing Task**
A. Kitamura, H. Naito, T. Kimura^{}, K. Shinohara, T. Sasaki^{**}, H. Okumura^{**}*
Osaka Univ., Japan
^{}Kansai Univ. of Welfare Scis., Japan*
*^{**}Toshiba, Japan*

----- Lunch -----

13:30 - 14:30

Room 302 A

VHF6: Mobile Human Factors and 'Kansei' Evaluation

Chair: J. S. Kimmel, Nokia Techs., Finland
Co-Chair: T. Nakatsue, Sony, Japan

**VHF6 - 1
13:30** **Required Performances of Electronic Displays for Smartphones Revealed by the Survey Results**
Y. Hisatake, M. Takemoto^{}, S. Kubota^{**}*
Japan Display, Japan
^{}Seikei Univ., Japan*
*^{**}Ergo Design Lab., Japan*

**VHF6 - 2
13:50** **An Overall Image Quality Model for Mobile Displays under Different Lighting Conditions**
R. Gong^{}, H. Xu^{*}, M. R. Luo^{*,**}*
^{}Zhejiang Univ., China*
*^{**}Univ. of Leeds, UK*

**VHF6 - 3
14:10** **Emotion Prediction Model of Museum Lighting**
C.-J. Chou, H.-W. Luo, H.-S. Chen, M. R. Luo^{}*
Nat. Taiwan Univ. of S&T, Taiwan
^{}Univ. of Leeds, UK*

----- Break -----

15:15 - 16:20

Room 301

3D7/VHF7: Visual Perception for 3D System

Chair: K.-H. Lee, Korea Photonics Tech. Inst., Korea

Co-Chair: Y. Hisatake, Japan Display, Japan

**3D7/
VHF7 - 1: Invited Towards the ISO Guideline for Image Safety
in Stereoscopic Viewing**

15:15

*T. Bando**AIST, Japan***3D7/
VHF7 - 2: The Impact of Screen Size on 3D Flicker-Free
Luminance**

15:40

*P.-L. Sun**, *Y.-P. Hsieh**, *H.-S. Chen**, *M. R. Luo**,****Nat. Taiwan Univ. of S&T, Taiwan****Univ. of Leeds, UK***3D7/
VHF7 - 3: Measurement of Visual Fatigue Induced by
Stereoscopic Display Using an Oddball Based
Event-Related Potential Experiment**

16:00

*P. Ye, H. Liang, J. Wang, F. Chen, S. Yang, J. Chen,
X. Wu, D. Gao**Nat. Sun Yat-Sen Univ., China***Author Interviews and Demonstrations**

16:45 – 17:45

Supporting Organizations:Technical Committee on Electronic Information Displays, Electronics
Society, IEICE

Technical Group on Information Display, ITE

RECEPTION

Wednesday, December 3, 2014

19:00 – 21:00

Room "Continental" (4F)

Hotel Okura Niigata

See page 12 for details

Workshop on Projection and Large-Area Displays and Their Components

Wednesday, December 3

14:00 - 14:05

Room 201

Opening

Opening Remarks

14:00

S. Ouchi, Hitachi, Japan

14:05 - 15:30

Room 201

PRJ1: Solid-State Light Source Technologies for Projector

Chair: P. Hickl, Barco Control Rooms, Germany

Co-Chair: H. Nakano, Barco, Japan

PRJ1 - 1: *Invited* SiC Light Emitting Diode and Its Polarization Control Using a Dressed Photon

14:05

T. Kawazoe, K. Nishioka, M. Ohtsu

Univ. of Tokyo, Japan

PRJ1 - 2: High Power AlGaInP Red Laser Diode for Display Applications

14:30

K. Kuramoto, T. Nishida, S. Abe, M. Miyashita, K. Mori, T. Yanagisawa, T. Yagi

Mitsubishi Elec., Japan

PRJ1 - 3: A New Technology for Stabilization of Chromaticity in Laser Projectors

14:50

Y. Ogi, Y. Seo, S. Ouchi

Hitachi, Japan

PRJ1 - 4: Lighting Technology for Automotive Headlamps

15:10

T. Masuda, H. Tanaka, Y. Shibata, M. Hayakawa, S. Yamamura

Koito Manufacturing, Japan

----- Break -----

15:45 - 17:15

Room 201

PRJ2: Vehicle Display

Chair: J. Thompson, Texas Instrs., USA

Co-Chair: K. Ohara, Texas Instrs., Japan

PRJ2 - 1: Invited Projection Technology Will Take Automotive Head-Up Display to the Next Level

15:45

*C. Kusaka, J. Kimura**Techno Syss. Res., Japan***PRJ2 - 2: Invited DLP Technology: Enabling the Next Generation of Automotive Head-Up Display Systems**

16:10

*G. Pettitt, J. Thompson, J. Ferri, M. McCormick**Texas Instrs., USA***PRJ2 - 3: Intelligent Head-Up-Display for Driver Assistance**

16:35

*S.-W. Cheng, J.-T. Hsu**Automotive Res. & Testing Ctr., Taiwan***PRJ2 - 4: Development of Car Display System with Free-Form Screen**

16:55

*S. Okagaki, J. Kondo, H. Sakamoto, S. Nakahara,**M. Kuwata, A. Heishi, H. Yoshii, K. Nakamura, K. Kojima,**M. Uno**Mitsubishi Elec., Japan***Author Interviews and Demonstrations**

17:15 – 18:15

Thursday, December 4

9:00 - 10:05

Room 301

PRJ3: Projection Technologies

Chair: D. Cuypers, imec, Belgium

Co-Chair: H. Kikuchi, NHK, Japan

PRJ3 - 1: Invited Speckle Reduction by Current-Induced Magneto-Optical Effect Using P-type ZnO Device

9:00

*N. Tate, T. Kawazoe, M. Ohtsu**Univ. of Tokyo, Japan***PRJ3 - 2: Speckle Measurement of Laser Display by Means of Simulating to Human Eye Perception**

9:25

*T. Fukui, K. Suzuki, S. Kubota**Oxide, Japan*

PRJ3 - 3 **Speckle Reduction by Optimizing Pulse Width of Drive Current for Red Laser Diodes**
9:45

T. Nishida^{,**}, T. Yagi^{*}, H. Murata^{**}, Y. Fujiwara^{**},
M. Takemi^{*}*

^{}Mitsubishi Elec., Japan*

*^{**}Osaka Univ., Japan*

----- Break -----

10:45 - 11:50

Room 301

PRJ4: Wearable Display

Special Topics of Interest on Augmented Reality and Virtual Reality

Chair: S. Shikama, Setsunan Univ., Japan

Co-Chair: S. Ouchi, Hitachi, Japan

PRJ4 - 1: *Invited* Laser Light Field Display Based on a Retinal Scanning Array
10:45

M. Ide, K. Yoda, S. Kato

Citizen Holdings, Japan

PRJ4 - 2 **Compact Optical Engine for Smart Glass**
11:10

H. Baba, T. Totani, T. Hashizume

Seiko Epson, Japan

PRJ4 - 3 **Light-Guide Optical Element Utilizing Notch Filters for See-Through Glasses**
11:30

X. Xiao, X. Lin, X. Tan

Beijing Inst. of Tech., China

----- Lunch -----

13:30 - 14:30

Room 302 B

PRJ5: Projection Applications

Chair: F. Shevlin, DYOPTYKA, Ireland

Co-Chair: Y. Asakura, Nittoh Kogaku, Japan

PRJ5 - 1 **Ultra-Short-Throw 4K Projector with Solid-State Light Source**
13:30

T. Mochizuki, Y. Sato, J. Nishikawa, R. Miyao, H. Kikuchi

Sony, Japan

PRJ5 - 2 **Stable Optical Projection Screen for Near Seamless Display Walls**
13:50

P. Hickl

Barco Control Rooms, Germany

PRJ5 - 3 Inorganic Alignment Layers for Liquid Crystal Grating Devices

14:10

D. Cuypers^{}, H. D. Smet^{*,**}*

^{}imec, Belgium*

*^{**}Ghent Univ., Belgium*

14:30 - 14:42

Room 302 B

Short Presentation PRJp: Projection

All authors of poster papers for the PRJp1 session will give a brief, 3-minute oral presentation with no discussion time in advance

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

9:00 - 12:00

Exhibition Hall B

Poster PRJp1: Projection

PRJp1 - 1 A Wide Laser Head-Up Display with the Complex Refractive Elements

S.-W. Yang, J.-H. Wu^{}, I.-K. Hsu, P.-J. Wu^{**}, C.-Y. Chen^{*}*

Nat. Central Univ., Taiwan

^{}Nat. Yunlin Univ. of Sci. & Tech., Taiwan*

*^{**}Nat. Chiao Tung Univ., Taiwan*

PRJp1 - 2 A Study of Optical Design of Laser Projector

W.-T. Li, K.-D. Huang

Nat. Kaohsiung First Univ. of S&T, Taiwan

PRJp1 - 3 Development of Column-Parallel LED Screen with Flexible Shape

K. Sato^{}, A. Tsuji^{*}, S. Suyama^{*}, H. Yamamoto^{*,**,*}*

^{}Univ. of Tokushima, Japan*

*^{**}JST-CREST, Japan*

*^{***}Utsunomiya Univ., Japan*

PRJp1 - 4 Image Dispersion Compensation Based on Spatial-Multiplexed Holographic Optical Elements

H.-T. Lin, H.-S. Syu, W.-C. Su

Nat. Changhua Univ. of Education, Taiwan

Supporting Organizations:

Laser Display Technology Research Group, Optical Society of Japan
Technical Group on Information Display, ITE

Workshop on Electronic Paper

Wednesday, December 3

14:00 - 14:50

Room 302 A

EP1: Electrophoretic Displays

Chair: G. Zhou, South China Normal Univ., China

Co-Chair: M. Tsuchiya, Innova Dynamics, Japan

EP1 - 1: *Invited* Three Particle Microencapsulated 14:00 Electrophoretic Display

*M. Wang, C. Lin, P. Laxton, H. Du, H. Zang, M. McCreary**
E-Ink California, USA
**E-Ink, USA*

EP1 - 2: *Invited* Biprimary Dual-Particle Electrokinetic 14:25 Displays with 70% Reflectance and Greatly Improved Color Saturation

S. Mukherjee, J. Heikenfeld, N. Smith, M. Goulding*,*
C. Topping, S. Norman*, L. Kramer**, Q. Liu***
Univ. of Cincinnati, USA
**Merck Chems., UK*
***Hewlett Packard Res. Lab., USA*

----- Break -----

15:45 - 17:00

Room 302 A

EP2: Various Technologies for e-Paper

Chair: M. Omodani, Tokai Univ., Japan

Co-Chair: N.-S. Roh, Samsung Display, Korea

EP2 - 1: *Invited* Review of Paper-Like Display Technologies 15:45

G. Zhou
South China Normal Univ., China

EP2 - 2: *Invited* The Progress of Electrowetting Display and 16:10 Its Applications

L.-C. Chen, W.-Y. Cheng, K.-L. Lo, R.-L. Chang
ITRI, Taiwan

EP2 - 3: *Invited* Frontlighting Technologies for Reflective 16:35 Displays: e-Papers, MEMS, MEOMS, LCDs

K. Kälantär
Global Optical Solutions, Japan

Author Interviews and Demonstrations

17:15 - 18:15

Thursday, December 4

9:00 - 10:05

Marine Hall

EP3: Chromic Displays

Chair: N. Kobayashi, Chiba Univ., Japan

Co-Chair: M. Higuchi, NIMS, Japan

EP3 - 1: Invited Thermo-Switchable Imaging Media with Dual Emissive and Reflective Modes

9:00

*K. Nakamura, K. Ogasawara, Y. Kobayashi,**K. Kanazawa, N. Kobayashi**Chiba Univ., Japan***EP3 - 2: Improvement of Coloration Properties of Electrochromic Cell by Immobilizing Organic Electrochromic Molecules on the Electrode**

9:25

*N. Ura, K. Nakamura, N. Kobayashi**Chiba Univ., Japan***EP3 - 3: Design and Preparation of Metallo-Supramolecular Polymers with Improved Electrochromic Properties**

9:45

M. Higuchi^{}***^{*}*NIMS, Japan*^{**}*JST-CREST, Japan*

10:05 - 10:11

Marine Hall

Short Presentation EPp: Electronic Paper

All authors of poster papers for the EPp session will give a brief, 3-minute oral presentation of with no discussion time in advance.

----- Lunch -----

Author Interviews and Demonstrations

18:30 – 19:30

13:30 - 16:30

Exhibition Hall B

Poster EPp1: Electronic Paper**EPp1 - 1: Improvement of Response of an Electrophoretic Display by Controlling Liquid Flow**

13:30

*K. Sato, M. Omodani**Tokai Univ., Japan***EPp1 - 2: Development of Twisting Balls for e-Paper by a Microchannel Device**

EPp1 - 2

*H. Akita, Y. Awatsu, Y. Takizawa**Soken Chem. & Eng., Japan*

Workshop on MEMS and Emerging Technologies for Future Displays and Devices

Thursday, December 4

9:00 - 9:10

Room 201

Opening

Opening Remarks: 10th Anniversary Opening Remarks

9:00

M. Nakamoto, Shizuoka Univ., Japan

9:10 - 10:30

Room 201

MEET1: Emerging Quantum Dots and Nanotechnologies

Chair: W. Milne, Univ. of Cambridge, UK

Co-Chair: Y. Bonnasieux, Ecole Polytechnique, France

MEET1 - 1: *Invited* Images and Cathodoluminescent Spectra of Red and Green Quantum Dots

9:10

J. Silver, G. R. Fern, T. G. Ireland, S. Coe-Sullivan, J. S. Steckel**

Brunel Univ., UK

**QD Vision, USA*

MEET1 - 2: *Invited* Progress in Quantum Dots for Liquid Crystal Displays

9:30

S. Coe-Sullivan

QD Vision, USA

MEET1 - 3: *Invited* Red Quantum Rods under the Electron Microscope

9:50

*G. R. Fern, S. Jack, F. Schröder-Oeynhausen, T. Jochum**

Brunel Univ., UK

**CAN, Germany*

MEET1 - 4: *Invited* Advancements in On-Chip Quantum Dots for LED Backlights in Wide Color Gamut LCD Displays

10:10

J. Osinski, J. Kurtin, N. Puetz, B. Theobald, S. Nathan, B. Mangum

Pacific Light Techs., USA

----- Break -----

10:45 - 12:45

Room 201

MEET2: Fundamental Components and Process Technologies

Chair: D. Pribat, Sungkyukwan Univ., Korea
 Co-Chair: F. Templier, CEA-LETI, France

MEET2 - 1: Invited CNTs and Graphene for X-ray Systems and Other Applications

10:45

W. I. Milne^{,**}, R. J. Parmee^{*,**}, J. Cameron^{**}, C. Li^{***},
 W. Lei^{***}, B. Wang^{***}, M. T. Cole^{*,**}*

**Univ. of Cambridge, UK*

***Cambridge X-ray Syss., UK*

****Southeast Univ., China*

MEET2 - 2: Invited Fabrication of Lighting Lamp with Carbon Nanotube Emitters Beam (C-beam)

11:05

K. C. Park

Kyung Hee Univ., Korea

MEET2 - 3 Sub-Micron Transparent Metal Mesh Conductor for Touch Screen Displays

11:25

*B. Kobrin, I. McMackin, J. Geddes, O. Seitz, M. Aryal,
 J. Wassei*

Rolith, USA

MEET2 - 4: Invited Gaussian Density-of-States Model for Organic Devices

11:45

Y. Bonnassieux, S. Jung, C. H. Kim, G. Horowitz

Ecole Polytechnique, France

MEET2 - 5 Crystallization Technique with Carbon Nanotube Electron Beam (C-beam) Exposure Technique

12:05

*H. T. Park, J. S. Kang, J. H. Hong, H. Lee, W. J. Kim,
 K. C. Park*

Kyung Hee Univ., Korea

MEET2 - 6 Cathodoluminescence Properties of Silicon Thin Films with Carbon Nanotube Electron Beam (C-beam) Exposure Technique

12:25

*W. J. Kim, J. S. Kang, H. R. Lee, J. H. Hong, H. T. Park,
 K. C. Park*

Kyung Hee Univ., Korea

----- Lunch -----

13:30 - 14:50

Room 201

MEET3: EL Quantum Dots Technologies

Chair: S. Coe-Sullivan, QD Vision, USA

Co-Chair: J. Silver, Brunel Univ., UK

MEET3 - 1: Invited All Solution Processed QLED

13:30

*J. Jang, J. E. Lee**Kyung Hee Univ., Korea***MEET3 - 2: Invited Efficient Quantum Dot Light-Emitting Diodes by Improving Charge Carrier Balance**

13:50

M. Park, H. Jung, J. Lim, W. Bae**, J. Kwak***, K. Char, S. Lee, C. Lee**Seoul Nat. Univ., Korea***Los Alamos Nat. Lab., USA****KIST, Korea*****Dong-A Univ., Korea***MEET3 - 3: Invited Quantum Dot Light-Emitting Diodes for Efficient, Solution-Processed Flat Panel Displays**

14:10

J. R. Manders, Y. Zheng*, L. Qian*, Y. Yang*, A. Titov*, J. Hyvonen*, J. Tokarz-Scott*, W. Cao**, J. Xue**, C. Morton*, P. H. Holloway******NanoPhotonica, USA****Univ. of Florida, USA***MEET3 - 4 Enhanced Efficiency of Quantum Dot Light-Emitting Diodes by Modifying Sol-Gel Based Metal-Doped ZnO Electron Transport Layer**

14:30

H. Jung, M. Thambidurai, J. Lim, K. Char, S. Lee, C. Lee
Seoul Nat. Univ., Korea

----- Break -----

15:15 - 16:55

Room 201

MEET4: Novel Materials and Components

Chair: K. C. Park, Kyung Hee Univ., Korea

Co-Chair: G. R. Fern, Brunel Univ., UK

MEET4 - 1: Invited Graphene-Silicon Composites for Improved Solar Cells

15:15

*E. Moyer, J. Jo, D. Pribat**Sungkyunkwan Univ., Korea***MEET4 - 2 Conducting Graphene Thin Film on Glass with Electron Beam Irradiation**

15:35

*G. C. Lim, J. S. Kang, J. S. Ahn, K. C. Park**Kyung Hee Univ., Korea*

MEET4 - 3: Invited High Target Utilization Sputtering of Thin Film Metal Oxides for Large-Area Electronics

15:55

*A. J. Flewitt**Univ. of Cambridge, UK***MEET4 - 4 Super Smart Window—Its Energy Design and Some Early Research**

16:15

*H. Morita, H. Yoshida**Tokyo Univ. of Sci., Yamaguchi, Japan***MEET4 - 5 Resonator-Type Infrared Detector Released by Plasmaless Sacrificial Si Etching**

16:35

J.-H. Jeong, S. Kumagai, S. Tajima, T. Hayashi*, K. Yamakawa**, M. Sasaki**Toyota Tech. Inst., Japan***Nagoya Univ., Japan****Katagiri Eng., Japan*

----- Break -----

17:00 - 18:40

Room 201

MEET5: Nanotechnology Display and Imaging

Chair: J. Jang, Kyung Hee Univ., Korea

Co-Chair: A. J. Flewitt, Univ. of Cambridge, UK

MEET5 - 1: Invited High-Brightness GaN LED Arrays Hybridized on Silicon Interconnect at a Pixel-Pitch of 10 μm .

17:00

*F. Templier, H. Bono, J.-M. Bethoux, F. Marion, I.-C. Robin, M.-A. di Forte-Poisson***CEA-LETI, France***3-5 Lab, France***MEET5 - 2: Invited Mechanical Strengthening of Silicon Torsion Bar of Scanning Micro Mirror by Hydrogen Anneal**

17:20

*S. Yoshida, S. Tanaka, M. Esashi**Tohoku Univ., Japan***MEET5 - 3: Invited Formation of Conductive AlN by a New Spontaneous Via Holes Technique and Development of Vertical Deep Ultra-Violet Light Emitting Device (RefV-LED)**

17:40

*N. Kurose, Y. Aoyagi**Ritsumeikan Univ., Japan*

**MEET5 - 4: *Invited* High Brightness Microdisplays by Monolithic
18:00 Integration of III-V LEDs and Thin Film Silicon
Transistors**

V. W. Lee

Lumiode, USA

**MEET5 - 5: *Invited* Quantum Photonic Imager (QPI): A New
18:20 Display Technology and Its Applications**

H. S. El-Ghoroury, Z. Y. Alpaslan

Ostendo Techs., USA

Author Interviews and Demonstrations

18:30 – 19:30

EXHIBITION

12:40 – 18:00 Wednesday, Dec. 3, 2014

10:00 – 18:00 Thursday, Dec. 4, 2014

10:00 – 14:00 Friday, Dec. 5, 2014

Exhibition Hall B

TOKI MESSE Niigata Convention Center

Free admission with your registration name tag

IDW '14 Tutorial in Japanese

Organized by SID Japan Chapter

Tuesday, December 2, 2014

Room 301, 3F

TOKI MESSE Niigata Convention Center

Detailed information is available on

<http://www.sid-japan.org>

Final Program

The final program of IDW '14 will be available on
the website (<http://www.idw.or.jp/>)
from the middle of November.

Workshop on Display Electronic Systems

Thursday, December 4

9:00 - 10:35

Room 302 B

DES1: Display Technologies in Augmented Reality *Special Topics of Interest on Augmented Reality and Virtual Reality*

Chair: K. Kiyokawa, Osaka Univ., Japan

Co-Chair: K. Makita, AIST, Japan

**DES1 - 1: *Invited* Diminished Reality Based on Image
9:00 Inpainting for Visually Removing Real Objects in
Real Time**

N. Kawai

Nara Inst. of S&T, Japan

DES1 - 2: *Invited* HMD Technologies for AR

9:25

K. Kiyokawa

Osaka Univ., Japan

**DES1 - 3: *Invited* Fog Display as a Co-creative Expression
9:50 Media**

Y. Miwa, S. Itai, Y. Terada

Waseda Univ., Japan

DES1 - 4 *Security Doors*

10:15

H.-F. Wang, C.-C. Lan, J.-Y. Huang, T.-H. Lin, H.-S. Chen

Nat. Taiwan Univ. of S&T, Taiwan

----- Break -----

10:45 - 11:55

Room 302 B

DES2: Image Processing

Chair: A. Ninan, Dolby Labs., USA

Co-Chair: A. Sakaigawa, Japan Display, Japan

**DES2 - 1: *Invited* Evolution of Displays through Advances in
10:45 Next Generation Video**

A. Ninan

Dolby Labs., USA

**DES2 - 2: *Invited* Pursuit of Visually Lossless Compression
11:10 and Practical Tradeoffs in Display Systems**

D. F. Stoltzka

Samsung Display, USA

DES2 - 3 Study of Low Color Shift Design with a WRGB LCD Panel

11:35

*L.-X. Chen, C.-T. Kang**Shenzhen China Star Optoelect. Tech., China*

----- Lunch -----

Author Interviews and Demonstrations

18:30 – 19:30

13:30 - 16:30

Exhibition Hall B

Poster DESp1: Display Electronic Systems**DESp1 - 1 Design of Human Face Recognition Application on Wide Viewing Angle Near-Eye See-Through Display***Z. Song, Z. Hu, L. Wang, Y. Tang**Southeast Univ., China***DESp1 - 2 A Study of Optical Design of Automotive Head-Up Display***Y.-C. Fang, B.-R. Hsueh*, Y.-H. Chang**Nat. Kaohsiung First Univ. of S&T, Taiwan***Kao Yuan Univ. of S&T, Taiwan***DESp1 - 3 Amorphous Silicon Integrated Gate Driver Circuits for High Resolution and Narrow Bezel Panel Application***G.-T. Zheng, P.-T. Liu*, C.-H. Chang*, S.-H. Hung*,
W.-C. Wang**, Y.-H. Chang**, W.-C. Wang**, W.-L. Sung****Nat. Tsing Hua Univ., Taiwan***Nat. Chiao Tung Univ., Taiwan****Chunghwa Picture Tubes, Taiwan***DESp1 - 4 Proposal of a Negative Level Shifter for a Negative High Voltage Generator***M. Fukuhara, A. Ueda, M. Urakami, S. Hayakawa,
M. Yoshida**Tokai Univ., Japan***DESp1 - 5 A Novel Charge Sharing Method for Liquid Crystal Displays with Lower Power Consumption***Y. Mu**, X. Guo*, X. Tang*****Shanghai Jiao Tong Univ., China****Infovision Optoelect., China*

- DESp1 - 6 Introduction of a Liquid Crystal Driving Circuit**
X. Xu, Z. Song, J. Chang, C. Gang, A. Jian, R. Lung, X. Chen, B. Liao
Shenzhen China Star Optoelect. Tech., China
- DESp1 - 7 Reducing Influence of Bias Stress on AMOLED Displays by Driving in Linear Regime: a Sensitivity Perspective**
F. D. Roose^{,**}, K. Myny^{**}, J. Genoe^{*,**}, P. Heremans^{*,**}, W. Dehaene^{*}*
^{*}*KULeuven, Belgium*
^{**}*imec, Belgium*
- DESp1 - 8 External TFT Compensating System for AMOLED Displays**
W.-C. Chiou, C.-C. Tsou, P.-S. Chen, C.-L. Lin
Nat. Cheng Kung Univ., Taiwan
- DESp1 - 9 A Differential Signal Impedance Matching Solution**
Y. Mu^{,**}, X. Guo^{*}, X. Tang^{*,**}*
^{*}*Shanghai Jiao Tong Univ., China*
^{**}*Infovision Optoelect., China*
- DESp1 - 10 Super-Resolution Based on Edge Detection and Sub-Regional Interpolation**
H.-L. Hu, H. Li, L.-W. Chu, C. Li, C.-C. Lo
Shenzhen China Star Optoelect. Tech., China

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5**10:45 - 12:15****Room 201**

DES3/VHF5: System Design and Evaluation in Augmented Reality
Special Topics of Interest on Augmented Reality and Virtual Reality

Chair: K. Morita, Nat. Traffic Safety & Environment Lab., Japan
 Co-Chair: K. Sakamoto, Panasonic, Japan

DES3/VHF5 - 1: Invited Simulation of Traffic Accident Scenarios with an Augmented Reality Vehicle
10:45
N. Uchida, T. Tagawa, K. Sato
Japan Automobile Res. Inst., Japan

DES3/VHF5 - 2: Invited The Realistic 3D Image Display Using Direct Light Scanning Method
11:10
H. Horimai, K. Hattori^{}, T. Umezaki*
^{*}*3Dragons, Japan*
^{*}*Chubu Univ., Japan*

DES3/
VHF5 - 3
11:35

Fast Calculation Algorithm Based on Point-Based Method for CGHs Using Polygon Model

*Y. Ogihara, Y. Sakamoto
Hokkaido Univ., Japan*

DES3/
VHF5 - 4
11:55

The Superiority of Widespread Monocular Augmented Reality Presentation in a Manual Tracing Task

A. Kitamura, H. Naito, T. Kimura, K. Shinohara,
T. Sasaki**, H. Okumura**
Osaka Univ., Japan
*Kansai Univ. of Welfare Scis., Japan
**Toshiba, Japan*

----- Lunch -----

13:30 - 14:30

Room 201

DES4: Display Driving Technologies

Chair: A. Sakaigawa, Japan Display, Japan
Co-Chair: T. Yamamoto, NHK, Japan

DES4 - 1
13:30

Low Power Liquid Crystal Driving Technique Based on Capacitors for 1-Pixel Display

H. Manabe, M. Date, H. Takada*, H. Inamura
NTT DoCoMo, Japan
NTT, Japan

DES4 - 2
13:50

Ultra Low Power LCD TV Using RGBW System

*C. Jung, Y. Chu, Z. Lai, W. Li, Y. Han, K. Kim, L. Zhang,
J. Jun
BOE Tech. Group, China*

DES4 - 3
14:10

Pixel Circuit with Fast Charging Capability Using Charge-Sharing Method for Blue-Phase Liquid Crystal Displays

*P.-C. Lai, M.-H. Cheng, P.-C. Lai, C.-L. Lin
Nat. Cheng Kung Univ., Taiwan*

----- Break -----

Final Program

The final program of IDW '14 will be available on the website (<http://www.idw.or.jp/>) from the middle of November.

15:15 - 16:15

Room 201

DES5: Display Interface and Driving Technologies

Chair: H. Okumura, Toshiba, Japan

Co-Chair: T. Yamamoto, NHK, Japan

**DES5 - 1
15:15 An Automatic DC Self-Adjusting Encoder of 5Gbps/
Lane Intra-Panel Interface for High Speed
Transmission***L.-W. Chang, Y.-C. Wu, Y.-C. Kang, W.-T. Chen, C.-P. Ho,
C.-H. Yang**AU Optronics, Taiwan***DES5 - 2
15:35 A Novel Method to Reduce the Loss of the Data in
High Resolution LCD***S.-Y. Wu, Y.-L. Ho, Y.-C. Chen, H.-H. Chen, H.-M. Su,
W.-Z. Zeng**Chunghwa Picture Tubes, Taiwan***DES5 - 3
15:55 A P-Type LTPS TFT Compensation Pixel Circuit for
Self-Emission Displays with GOA***Y.-T. Lin, H.-Y. Hsieh, C.-H. Chen, Y.-C. Lai, M.-Y. Lu,
C.-C. Kuo, C.-T. Chuang, Y.-S. Huang, C.-N. Yeh,
N. Sugiura**AU Optronics, Taiwan***Author Interviews and Demonstrations**

16:45 – 17:45

Supporting Organizations:

Shin-etsu Section, IEEE

Special Interest Group on Mixed Reality, The Virtual Reality Society
of JapanTechnical Committee on Electronic, Information Displays, Electronics
Society IEICE

Technical Group on Information Display, ITE

Technical Group on Information Sensing Technologies, ITE

Technical Committee on Image Engineering, Systems Society, IEICE

IDW '14 Tutorial in Japanese

Organized by SID Japan Chapter

Tuesday, December 2, 2014

Room 301, 3F

TOKI MESSE Niigata Convention Center

Detailed information is available on

<http://www.sid-japan.org>

Workshop on Flexible Electronics

Wednesday, December 3

14:00 - 14:05

Snow Hall A

Opening

Opening Remarks

14:00

T. Sekitani, Osaka Univ., Japan

14:05 - 15:40

Snow Hall A

FLX1: Flexible Backplane

Chair: T. Kamata, AIST, Japan

Co-Chair: T. Sekitani, Osaka Univ., Japan

FLX1 - 1: *Invited* Oxide Thin Film Transistors for Flexible Display

14:05

Y. Uraoka, M. Fujii, M. Horita, Y. Ishikawa

Nara Inst. of S&T, Japan

FLX1 - 2: *Invited* Improvement in the Field-Effect Mobility of Metal Oxide TFTs by Advanced Stack Channel Structure and Defect Control for the Next-Generation High-End Active-Matrix Displays

14:30

J. K. Jeong, A. Y. Hwang, K. Ji, J. H. Song, C. K. Lee, H. Y. Jung

Inha Univ., Korea

FLX1 - 3: *Invited* Vertical Organic Field-Effect Transistors for Truly Flexible AMOLED Backplanes

14:55

G. Schwartz, H. Kleemann, J. Blochwitz-Nimoth

Novald, Germany

FLX1 - 4: Flexibility Improvement of LTPS-TFT for Foldable AMOLED

15:20

J.-Y. Yan, W.-W. Tsai, B.-Y. Su, C.-W. Su, H.-C. Yao, T.-J. Wang, W.-C. Kao, Y.-C. Lin, C.-Y. Hung, W.-H. Chen, M.-J. Yang, C.-Y. Chiang, K.-L. Chuang, W.-T. Wang, C.-C. Lee

ITRI, Taiwan

----- Break -----

15:45 - 16:25

Snow Hall A

FLX2: Flexible Displays and Devices

Chair: K. Uemura, Nippon Steel & Sumitomo Metal, Japan
 Co-Chair: H. Maeda, DNP, Japan

FLX2 - 1 **Bezel-Less PMOLED Modules with Flexible**
15:45 **Substrates for Scalable Display System**

*H. Iijima, M. Izuchi, H. Makino, T. Wakabayashi, K. Sasai,
 Y. Okumoto, A. Miyamoto, K. Morita*
Panasonic, Japan

FLX2 - 2 **A Flexible Display Panel, a Flexible Battery, and a**
16:05 **Flexible Printed Circuit for Wearable Display**

*T. Miwa, R. Tajima, Y. Goto, Y. Saito, T. Oguni, H. Miyake,
 A. Hitotsuyanagi, J. Goto, H. Katagiri, S. Okano,
 M. Kaneyasu, M. Hiroki, M. Takahashi, S. Yamazaki*
Semiconductor Energy Lab., Japan

Author Interviews and Demonstrations

17:15 – 18:15

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster FLXp1: Flexible Electronics

FLXp1 - 1 **A 4.6-in. Flexible AMOLED Encapsulated by**
Sputtered Thin Film and Laminated High Barrier
Film

L. Lin, C. Zhao, P. Dang, X. Liu, X. Huang, X. Gao
Visionox R&D Ctr., China

FLXp1 - 2 **Ultra-High Gas Barrier Film Deposition Using a**
Novel Precursor, TG-4E, by PECVD for OLED
Devices

H. Chiba, M. Shimizu, D. Hara, K. Tokuhisa
TOSOH, Japan

FLXp1 - 3 **Flexible Dye Sensitized Solar Cells for Device Power**
Applications

*J. Silver, T. G. Ireland, G. R. Fern, M. Spratt**
Brunel Univ., UK
**G24 Power, UK*

- FLXp1 - 4** **Enhanced Charge Injection of Organic Field-Effect Transistor with 6, 13-Bis(triisopropylsilylethynyl) Pentacene Using a Metal Oxide Buffer Layer**
E.-Y. Shin, C.-H. Shin, M.-H. Kim, J.-H. Lee, Y. Choi
Hanbat Nat. Univ., Korea
- FLXp1 - 5** **The Study on Electrical Characteristics Variation of Flexible Pentacene Based Thin Film Transistors on PET Substrate with/without Surface Treatments**
Y. W. Wang, W. L. Liu, J. S. Jiang, T. M. Jian
Nat. Changhua Univ. of Education, Taiwan
- FLXp1 - 6** **Structure Design of IGZO TFTs with Stress Analysis for Flexible Applications Using Finite Element Method**
M. H. Lee, S.-M. Hsu, C. Liu, J.-D. Shen*
Nat. Taiwan Normal Univ., Taiwan
**Nat. Taiwan Univ., Taiwan*
- FLXp1 - 7** **Flexible Polymer Dispersed LC Materials for Holographic Recording**
K.-T. Kuo, W.-C. Su
Nat. Changhua Univ. of Education, Taiwan
- FLXp1 - 8** **Study of Polymer Stabilized Blue Phase LC on Flexible Substrate**
N. Endo, T. Matsumoto, H. Kikuchi, M. Kimura*
Nagaoka Univ. of Tech., Japan
**Kyushu Univ., Japan*
- FLXp1 - 9** **Fabrication of Conductive Electrode on Flexible Substrate Using Ag Nanoparticle Ink by Transfer Printing Method**
J.-C. Choi, J.-S. Park, G. T. Park, J.-H. Kim, M.-K. Park, I. Mahmud, J.-H. Bae, H.-R. Kim
Kyungpook Nat. Univ., Korea
- FLXp1 - 10** **Pretilt Angle and Surface Anchoring Energy of LCD Fabricated by Slit Coater**
T. Yamamoto, M. Kimura
Nagaoka Univ. of Tech., Japan
- FLXp1 - 11** **A Non-Contact Resistance Measurement of Flexible Substrates for Repeating Bending Test by Using a Terahertz Time Domain Spectroscopy**
B.-J. Wen, T.-A. Liu, S.-W. Hsu
ITRI, Taiwan

- FLXp1 - 12 The Enhanced Thin Glass with an Ultra-High Bending Strength by a Laser Peeling Technology**
C.-H. Li, C.-J. Huang, K.-T. Chen, M.-C. Lin
ITRI, Taiwan

----- Lunch -----

13:30 - 14:45

Snow Hall B

FLX3: Advanced Printing Technologies
Special Topics of Interest on Printed Electronics

Chair: M. Ito, Toppan Printing, Japan

Co-Chair: H. Hirata, Toray Eng., Japan

- FLX3 - 1: Invited Novel Roll-to-Roll Screen Printing Machine for Flexible Devices**
13:30

D. Kobayashi, N. Naoi^{}, T. Suzuki^{*}, T. Sasaki^{*},
 T. Furukawa^{**}*

Tokai Shoji, Japan

^{}Tokai Seiki, Japan*

*^{**}Yamagata Univ., Japan*

- FLX3 - 2: Invited Technologies for Fully Integrated Printed Displays**
13:55

*N. Fruehauf, M. Strecker, D. Benzel, S. Hoehla,
 J. Remmele*

Univ. of Stuttgart, Germany

- FLX3 - 3: Invited Flexible Transparent Conductive Films Based on Metal Mesh Technology**
14:20

Z. Cui

Chinese Ac. of Sci., China

----- Break -----

15:15 - 16:25

Snow Hall B

FLX4: Printed TFT Technologies
Special Topics of Interest on Printed Electronics

Chair: Y. Uraoka, Nara Inst. of S&T, Japan

Co-Chair: T. Furukawa, Yamagata Univ., Japan

- FLX4 - 1: Invited Fully Printed Flexible TFT Array for Electronic Paper**
15:15

*M. Ito, H. Chujo, K. Murata, M. Nishizawa, N. Ikeda,
 K. Hatta, M. Yokoo, R. Matsubara, O. Kina, S. Akao,
 T. Yamamoto, M. Takei, M. Kumagai, M. Ishizaki,
 K. Morosawa, M. Matsumura*

Toppan Printing, Japan

FLX4 - 2: Invited Fully-Printed Organic TFTs and Circuits on Ultra-Flexible Substrates

15:40

K. Fukuda, Y. Takeda, S. Tokito
Yamagata Univ., Japan

FLX4 - 3 Flexible Electronics on Backmolded Plastic Foils

16:05

P. Guacci, N. Fruehauf, A. Ilchmann, B. Polzinger*,*
W. Eberhardt, H. Kueck**
Univ. of Stuttgart, Germany
**HSG-IMAT, Germany*

Author Interviews and Demonstrations

18:30 – 19:30

Friday, December 5

10:45 - 11:50

Snow Hall A

FLX5: Flexible Substrates

Chair: T. Shiro, Teijin, Japan
 Co-Chair: T. Eguchi, Sumitomo Bakelite, Japan

FLX5 - 1: Invited Flexible Paper Electronics Based on Cellulose Nanofiber Paper

10:45

H. Koga, M. Nogi, K. Suganuma
Osaka Univ., Japan

FLX5 - 2 Resent Approach to High Throughput Barrier Coating on Plastic Substrate

11:10

T. Okimoto, T. Segawa, H. Tamagaki
Kobe Steel, Japan

FLX5 - 3 Development of Transparent Cellulose Nano Fiber Film for Flexible Displays

11:30

G. Banzashi, H. Fushimi, S. Iwai, M. Tsunoda, E. Mikami
Oji Holdings, Japan

----- Lunch -----

IMID 2014

August 26 – 29, 2014

EXCO

Daegu, Korea

13:30 - 14:35

Snow Hall A

FLX6/FMC6: Flexible Materials and Devices

Chair: Y. Mishima, FUJIFILM, Japan
 Co-Chair: T. Tomono, Toppan Printing, Japan

**FLX6/
FMC6 - 1:** ***Invited* Flexible Substrates and Alternative
Electrodes of ITO for OLED Lighting**
13:30 *M. Kodan, H. Kobayashi, T. Moriya, N. Kawamura,
T. Furukawa, H. Nakada
Yamagata Univ., Japan*

**FLX6/
FMC6 - 2** **An Analysis Method of Shock Test for Flexible
Displays by Using an Image Luminance
Measurement Device**
13:55 *J.-M. Hsu, S.-W. Hsu, B.-J. Wen, T.-Y. Chung
ITRI, Taiwan*

**FLX6/
FMC6 - 3** **Plastic Substrate Technology for Flexible LCD**
14:15 *Z.-H. Chen, T.-H. Huang, J.-K. Lu, N. Sugiura
AU Optronics, Taiwan*

Author Interviews and Demonstrations

16:45 – 17:45

Supporting Organizations:

Technical Committee on Electronic Information Displays, Electronics
 Society, IEICE
 Technical Group on Information Display, ITE

IDW '15

The 22nd International Display Workshops

December 8 – 11, 2015

Otsu Prince Hotel
 Otsu, Japan

<http://www.idw.or.jp>

Workshop on Touch Panels and Input Technologies

Wednesday, December 3

14:00 - 14:05

Room 302 B

Opening

Opening Remarks

14:00

N. Hashimoto, Citizen Holdings, Japan

14:05 - 15:30

Room 302 B

INP1: Touch Panel (1)

Chair: H.-S. Koo, Minghsin Univ. of S&T, Taiwan

Co-Chair: K. Nakatani, Touchpanel Labs., Japan

INP1 - 1: *Invited* Technological Development of Touch Panel Industry in Taiwan

14:05

H.-S. Koo, M. Chen

Minghsin Univ. of S&T, Taiwan

INP1 - 2: New AI-Based Metal Mesh Electrode for a Touch Screen Panel

14:30

*M. Ochi, Y. Shida, H. Goto, T. Kugimiya, K. Moriyoshi**

Kobe Steel, Japan

**Kobelco Res. Inst., Japan*

INP1 - 3: Low Reflectance Metal Layers for New Touch Panel Solutions

14:50

J. L. Grillmayer, H. C. Ko, M. Bender, K. Witting**

Appl. Materials, Taiwan

**Appl. Materials, Germany*

INP1 - 4: A Novel Metal Mesh Single Layer Touch Sensor Design to Achieve Preeminent Touch and Visual Performance

15:10

R. Fu, J. Qiu, J. Zhang, C. Ye, Y. Lin, C. Lee, C. Luo, A. Lien

Shenzhen China Star Optoelect. Tech., China

----- Break -----

15:45 - 17:15

Room 302 B

INP2: Touch Panel (2) and Haptics

Chair: T. Hoshi, Nagoya Inst. of Tech., Japan
 Co-Chair: H. Haga, NLT Techs., Japan

INP2 - 1: 15:45 *Invited* Electrostatic Tactile Display for Stimulus Localization

*H. Haga, K. Yoshinaga, J. Yanase, D. Sugimoto,
 K. Takatori, H. Asada
 NLT Techs., Japan*

INP2 - 2: 16:10 *Invited* Noncontact Tactile Display Using Airborne Ultrasound

*T. Hoshi
 Nagoya Inst. of Tech., Japan*

INP2 - 3 16:35 Touchless Architecture for Small and Medium Size Panel Application

*D.-C. Yu, J.-S. Liao, H.-H. Chen, H.-M. Su, W.-T. Tseng
 Chunghwa Picture Tubes, Taiwan*

INP2 - 4 16:55 A Novel Embedded Touch Display with Integrated Chip Solution

*Y.-C. Li, C.-C. Chang, W.-J. Yang, C.-Y. Hsu, H.-H. Chen,
 H.-M. Su, W.-T. Tseng
 Chunghwa Picture Tubes, Taiwan*

Author Interviews and Demonstrations

17:15 – 18:15

Thursday, December 4

9:00 - 12:00

Exhibition Hall B

Poster INPp1: Touch Panel**INPp1 - 1 Transparent Conductive Metal Structure Electrodes with Electrospun Nanofiber Templates**

*H. Yoo, W. Hwang, H. Chae
 Sungkyunkwan Univ., Korea*

INPp1 - 2 Invisible Patterned Method for Silver Nano-Wires Conductive Film

*Y.-P. Chang, M.-H. Yang, W.-T. Chen, C.-Y. Chiu,
 Y.-Z. Lee
 ITRI, Taiwan*

INPp1 - 3 Reduced Non-Uniformity Moiré in Metal Mesh Touch Display Using View Angle Compensation*C. Y. Chen, J. L. Chen, S. Y. Huang**General Interface Solution, Taiwan***INPp1 - 4 Capacitive Touch Sensing Circuit on Flexible Substrate Using Back-Channel-Etch a-IGZO TFTs***Y. Chen, D. Geng, J. Jang**Kyung Hee Univ., Korea*

----- Lunch -----

13:30 - 14:20**Room 301****INP3: AR Interactive Systems*****Special Topics of Interest on Augmented Reality and Virtual Reality***

Chair: N. Hashimoto, Citizen Holdings, Japan

Co-Chair: N. Balram, Ricoh Innovations, USA

**INP3 - 1: *Invited* System Design Considerations for Personal
13:30 Light Field Displays for the Mobile Information
Gateway***N. Balram, W. Wu, I. Tomic, K. Berkner**Ricoh Innovations, USA***INP3 - 2: *Invited* Further Analysis of the R-V Dynamics
13:55 Illusion on Sense of Weight***S. Hashiguchi, Y. Kataoka, F. Shibata, A. Kimura**Ritsumeikan Univ., Japan*

----- Break -----

15:15 - 16:30**Room 302 A****INP4: Sensor and Applications**

Chair: M. Kimura, Ryukoku Univ., Japan

Co-Chair: J. Ohta, NAIST, Japan

**INP4 - 1: *Invited* Sensor Applications Using Thin-Film Devices
15:15 Derived from Display Technologies - Flatpanel
Imager, Artificial Retina, Temperature Sensor,
Magnetic-Field Sensor, etc. -***M. Kimura, T. Matsuda, S. Noguchi, T. Sakamoto*,
T. Ozawa**, K. Aoki**, C.-C. Kuo****Ryukoku Univ., Japan***AIST, Japan****AU Optronics, Japan*

INP4 - 2: 15:40 *Invited* CMOS Image Sensor Technologies in Biomedical Applications

J. Ohta

Nara Inst. of S&T, Japan

INP4 - 3: 16:05 *Invited* Next Generation Natural User Interface, Tobii Eye Tracking -Eye Experience-

K. Hachisu

Tobii Tech., Japan

Author Interviews and Demonstrations

18:30 – 19:30

Supporting Organizations:

Human Interface Society

The Forum for Advancement of Stereoscopic Three Dimensional Image Technology and Arts

Holographic Display Artists and Engineers Club, The Japan Society of Applied Physics

Technical Group on Information Sensing Technologies, ITE

“Innovative Demonstration Session” by Oral and Poster Presenters

Live demonstrations of emerging information display technologies

Thursday, December 4, 2014

Friday, December 5, 2014

In the afternoon

Exhibition Hall B

The 50th Anniversary Speech of PDPs “Summing Up of the PDP History and a Peek at Plasma Technologies Beyond Displays” (FED4 – 1)

Friday, December 5, 2014

15:15 - 15:55

Room 302B

See page 65 for detail

IDW '14 COMMITTEES

ORGANIZING COMMITTEE

General Chair:	K. Azuma	Shimadzu
General Vice-Chair:	K. Betsui	Hitachi
Representative (ITE):	N. Shimidzu	NHK
	H. Fujikake	Tohoku Univ.
Representative (SID):	K. Kondo	Sharp
	M. Omodani	Tokai Univ.
Standing (Executive Chair):	S. Komura	Japan Display
Standing (Program Chair):	A. Mikami	Kanazawa Inst.of Tech.
Standing:	Y. Iimura	Tokyo Univ. of A&T
	R. Hattori	Kyushu Univ.
	K. Ishikawa	Tokyo Inst. of Tech.
	M. Kimura	Ryukoku Univ.
	H. Okumura	Toshiba
	Y. Shimodaira	Shizuoka Univ.
	T. Tsujimura	KONICA MINOLTA
	Y. Yamamoto	Semiconductor Energy Lab.
Auditor:	H. Sakurai	Asahi Glass

OVERSEAS ADVISORS

Overseas Advisor:	B. H. Berkeley	Samsung Display, USA
	J. Chen	ITRI, Taiwan
	N. Fruehauf	Univ. of Stuttgart, Germany
	A. Ghosh	eMagin, USA
	M.-K. Han	Seoul Nat. Univ., Korea
	J. Jang	Kyung Hee Univ., Korea
	H.-S. Kwok	Hong Kong Univ. of S&T, Hong Kong
	J.-N. Perbet	Thales Avionics, France
	K.-R. Sarma	Honeywell Int., USA
	H.-P. D. Shieh	Nat. Chiao Tung Univ., Taiwan
	D. Theis	Tech. Univ. Munich, Germany
	B. Wang	Southeast Univ., China
	L. F. Weber	Consult., USA

EXECUTIVE COMMITTEE

Executive Chair:	S. Komura	Japan Display
Executive Vice-Chair:	H. Okumura	Toshiba
	H. Sakurai	Asahi Glass
	K. Takatori	NLT Techs.
	T. Shiga	Univ. of Electro-Commun.
Program Chair:	A. Mikami	Kanazawa Inst.of Tech.
Program Vice-Chair:	Y. Gotoh	Kyoto Univ.
	M. Kimura	Ryukoku Univ.
	Y. Nakai	Toshiba
Program Secretary:	O. Akimoto	Sony
	M. Date	NTT
	M. Higuchi	NIMS
	H. Hirata	Toray Eng.
	Y. Hisatake	Japan Display
	K. Ishikawa	Tokyo Inst. of Tech.
	H. Kato	Sharp
	Y. Kijima	Sony
	H. Kominami	Shizuoka Univ.
	K. Makita	AIST
	M. Shinohara	Omron

Publication Chair:	K. Ishii	NHK
Publication Vice-Chair:	H. Kumomi	Tokyo Inst. of Tech.
Publication:	H. Kawamura	NTT
	T. Tsuzuki	NHK
Local Arrangement Chair:	T. Katoh	ZEON
Local Arrangement Vice-Chair:	K. Kato	Niigata Univ.
Local Arrangement:	K. Toda	Niigata Univ.
Exhibition Chair:	S. Komura	Japan Display
Financial Supporting Chair:	S. Komura	Japan Display
Treasurer:	T. Numao	Sharp
General Secretary:	K. Betsui	Hitachi
Senior Member:	Y. Iimura	Tokyo Univ. of A&T
Members:	I. Fujieda	Ritsumeikan Univ.
	N. Hashimoto	Citizen Holdings
	M. Inoue	Huawei Technologies Japan
	M. Inoue	Apple
	S. Kaneko	NLT Techs.
	S. Kobayashi	Tokyo Univ. of Sci. Yamaguchi
	T. Komaki	Panasonic
	H. Kuma	Idemitsu Kosan
	S. Maeda	Tokai Univ.
	T. Miyashita	Tohoku Inst. of Tech.
	Y. Sakamoto	Hokkaido Univ.
	A. Sasaki	Kyoto Univ.
	K. Suzuki	Toshiba Res. Consulting
	M. Suzuki	Merck
	Y. Toko	Stanley Elec.
	T. Uchida	Sendai Nat. College of Tech.
	H. Uchiike	Saga Univ.
	Y. Yanagi	Lumiotec
	H. Yokoyama	Kent State Univ.
	M. Yuki	Asahi Glass
	D. P. Gosain	AKT
	S. Naemura	Univ. of Southampton

WORKSHOP CHAIR

LCT	T. Ishinabe	Tohoku Univ.
AMD	Y. Fujisaki	NHK
FMC	T. Miyashita	Tohoku Inst. of Tech.
PH	Y. Nakanishi	Shizuoka Univ.
FED	H. Mimura	Shizuoka Univ.
OLED	T. Wakimoto	Merck
3D	S. Yano	Shimane Univ.
VHF	T. Kurita	NHK Media Tech.
PRJ	S. Ouchi	Hitachi
EP	H. Arisawa	Fuji Xerox
MEET	M. Nakamoto	Shizuoka Univ.
DES	H. Okumura	Toshiba
FLX	H. Fujikake	Tohoku Univ.
INP	N. Hashimoto	Citizen Holdings

PROGRAM COMMITTEE

Program Chair:	A. Mikami	Kanazawa Inst. of Tech.
Program Vice-Chair:	Y. Gotoh	Kyoto Univ.
	M. Kimura	Ryukoku Univ.
	Y. Nakai	Toshiba
Program Secretary:	O. Akimoto	Sony
	M. Date	NTT

M. Higuchi	NIMS
H. Hirata	Toray Eng.
Y. Hisatake	Japan Display
K. Ishikawa	Tokyo Inst. of Tech.
H. Kato	Sharp
Y. Kijima	Sony
H. Kominami	Shizuoka Univ.
K. Makita	AIST
M. Shinohara	Omron

Committee:

LCT	S. Ishihara	Osaka Inst. of Tech.
AMD	H. Kumomi	Tokyo Inst. of Tech.
FMC	T. Tomono	Toppa Printing
PH	N. Miura	Meiji Univ.
FED	H. Shimawaki	Hachinohe Inst. of Tech.
OLED	K. Monzen	Nissan Chem. Inds.
3D	M. Tsuchida	NTT
VHF	K. Masaoka	NHK
PRJ	K. Ohara	Texas Instr. Japan
EP	T. Fujisawa	DIC
MEET	Y. Nakai	Toshiba
DES	K. Makita	AIST
FLX	T. Sekitani	Osaka Univ.
INP	T. Nakamura	Japan Display

Workshop on LC Science and Technologies

Workshop Chair:	T. Ishinabe	Tohoku Univ.
Program Chair:	S. Ishihara	Osaka Inst. of Tech.
Program Vice-Chair:	S. Oka	Japan Display
	S. Shibahara	Sony
General Secretary:	H. Wakemoto	Japan Display
Program Committee:	F. Araoka	RIKEN
	M. Funahashi	Kagawa Univ.
	I. Hirose	JASRI
	M. Inoue	Apple
	K. Ishikawa	Tokyo Inst. of Tech.
	A. Kubono	Shizuoka Univ.
	K. Miyachi	Sharp
	H. Nakata	DIC
	M. Nishikawa	JSR
	T. Nose	Akita Pref. Univ.
	H. Okada	Univ. of Toyama
	M. Ozaki	Osaka Univ.
	M. Suzuki	Merck
	T. Takahashi	Kogakuin Univ.
	S. Takanori	JNC Petrochem.

Workshop on Active Matrix Displays

Workshop Chair:	Y. Fujisaki	NHK
Program Chair:	H. Kumomi	Tokyo Inst. of Tech.
Program Vice-Chair:	M. Inoue	Huawei Techs. Japan
General Secretary:	H. Minemawari	AIST
Program Committee:	A. C. Arias	Univ. of California, Berkeley
	K. Azuma	Shimadzu
	E. Fortunato	New Univ. of Lisbon
	H. Hamada	Kinki Univ.
	M. Hiramatsu	Japan Display
	S. Horita	JAIST

H. J. Kim	Yonsei Univ.
M. Kimura	Ryukoku Univ.
N. Morosawa	Sony
T. Noguchi	Univ. of the Ryukyus
T. Ozawa	AU Optronics
M. Shibazaki	Innolux
K. Suga	Sharp
K. Takatori	NLT Techs.
Y.-H. Yeh	ITRI

Workshop on FPD Manufacturing, Materials and Components

Workshop Chair:	T. Miyashita	Tohoku Inst. of Tech.
Program Chair:	T. Tomono	Toppan Printing
General Secretary:	R. Yamaguchi	Akita Univ.
Program Vice-Chair:	M. Shinohara	Omron
Program Committee:	I. Amimori	A51 Tech
	T. Arikado	Tokyo Electron
	K. Dantani	ATMI Japan
	A. Fujita	JNC
	Y. Iimura	Tokyo Univ. of A&T
	Y. Inoue	Corning Holding Japan
	K. Käläntär	Global Optical Solutions
	T. Katoh	ZEON
	C. C. Lee	ITRI
	D. Matsuura	Dai Nippon Printing
	T. Mori	Nitto Denko
	Y. Murata	ULVAC
	S. Namekawa	Nippon Steel & Sumikin Chemical
	T. Nonaka	AZ Elec. Materials
	Y. Saitoh	FUJIFILM
H. Sakurai	Asahi Glass	
S. Takahashi	Sumitomo Bakelite	
T. Takeda	Nagase ChemteX	
Y. Ukai	UDDI	
T. Unate	UNATE	
Y. Yang	Japan Display	

Workshop on EL Displays and Phosphors

Workshop Chair:	Y. Nakanishi	Shizuoka Univ.
Program Chair:	N. Miura	Meiji Univ.
General Secretary:	N. Matsuda	Toshiba Materials
Program Committee:	K. Hara	Shizuoka Univ.
	T. Hisamune	Mitsubishi Chem.
	S. Itoh	Futaba
	D. Jeon	KAIST
	H. Kobayashi	Tottori Univ.
	T. Kunimoto	Tokushima Bunri Univ.
	T. Kusunoki	Dexerials
	T. Miyata	Kanazawa Inst. of Tech.
	T. Mukai	Nichia Chem.
	K. Ohmi	Tottori Univ.
	D. Poelman	Gent Univ.
	M. Shiiki	Hitachi Chem.
	K. Wani	TAZMO
	R. Xie	NIMS

Workshop on Field Emission Displays, CRTs and Plasma Displays

Workshop Chair:	H. Mimura	Shizuoka Univ.
-----------------	-----------	----------------

Program Chair:	H. Shimawaki	Hachinohe Inst.of Tech.
General Secretary:	M. Nanba	NHK
Program Committee:	Y. Gotoh	Kyoto Univ.
	J. Ishikawa	Chubu Univ.
	H. Kajiyama	Tokushima Bunri Univ.
	S. Mikoshihira	Univ. of Electro-Commun.
	M. Nagao	AIST
	M. Nakamoto	Shizuoka Univ.
	S. Okuda	Okuda
	T. Shiga	Univ. of Electro-Commun.
	M. Takai	Osaka Univ.
	F. Wakaya	Osaka Univ.

Workshop on OLED Displays and Related Technologies

Workshop Chair:	T. Wakimoto	Merck
Program Chair:	K. Monzen	Nissan Chem. Inds.
Program Vice-Chair:	T. Ikuta	JNC Petrochem.
General Secretary:	T. Uchida	Tokyo Polytechnic Univ.
Program Committee:	C. Adachi	Kyushu Univ.
	S. Aratani	Hitachi
	S. Enomoto	Toshiba Lighting & Tech.
	T. Fukuda	Saitama Univ.
	R. Hattori	Kyushu Univ.
	T. Inoue	TDK Corporation
	Y. Kijima	Sony
	T. Komatsu	Panasonic
	H. Kuma	Idemitsu Kosan
	A. Mikami	Kanazawa Inst.of Tech.
	H. Murata	JAIST
	S. Naka	Univ. of Toyama
	K. Nakayama	Yamagata Univ.
	Y. Sakai	MCRC
	T. Shimizu	NHK
	S. Tokito	Yamagata Univ.
	T. Tsuji	Pioneer

Workshop on 3D/Hyper-Realistic Displays and Systems

Workshop Chair:	S. Yano	Shimane Univ.
Program Chair:	M. Tsuchida	NTT
General Secretary:	K. Yamamoto	NICT
Program Committee:	T. Fujii	Nagoya Univ.
	T. Koike	Hosei Univ.
	T. Mishina	NHK
	J.-Y. Son	Konyang Univ.
	C.-H. Tsai	ITRI
	M. Tsuboi	NTT DoCoMo
	H. Yamamoto	Univ. of Utsunomiya

Workshop on Applied Vision and Human Factors

Workshop Chair:	T. Kurita	NHK Media Tech.
Program Chair:	K. Masaoka	NHK
General Secretary:	A. Yoshida	Sharp
Program Committee:	J. Bergquist	Nokia Corp.
	S. Clippingdale	NHK
	N. Hiruma	NHK
	Y. Hisatake	Japan Display
	M. Idesawa	Univ. of Electro-Commun.
	H. Isono	Tokyo Denki Univ.
	A. Morishita	Toshiba

Y. Nakamura	Mitsubishi Elec.
T. Nakatsue	Sony
G. Ohashi	Shizuoka Univ.
K. Sakamoto	Panasonic
Y. Shimodaira	Shizuoka Univ.
J. Someya	Mitsubishi Elec.
T. Tamura	Tokyo Polytech. Univ.
R. Yoshitake	Shibaura Inst. of Tech.

Workshop on Projection and Large-Area Displays and Their Components

Workshop Chair:	S. Ouchi	Hitachi
Program Chair:	K. Ohara	Texas Instr. Japan
Vice-Secretary:	O. Akimoto	Sony
Program Vice-Chair:	S. Shikama	Setsunan Univ.
General Secretary:	T. Suzuki	JVC KENWOOD
Program Committee:	Y. Asakura	Nittoh Kogaku
	K. Goto	Ushio
	H. Kikuchi	NHK
	H. Nakano	Barco
	H. Sugiura	Mitsubishi Elec.
	M. Takaso	Telepathy Japan
	C. Kusaka	Techno Sys. Res
	T. Hashizume	Seiko Epson
	S. Koike	

Workshop on Electronic Paper

Workshop Chair:	H. Arisawa	Fuji Xerox
Program Chair:	T. Fujisawa	DIC
Program Vice-Chair:	N. Kobayashi	Chiba Univ.
General Secretary:	Y. Toko	Stanley Elec.
Program Committee:	M. Higuchi	NIMS
	Y. Hotta	Ricoh
	S. Maeda	Tokai Univ.
	M. Omodani	Tokai Univ.
	N.-S. Roh	Samsung Display
	A. Suzuki	Chiba Univ.
	M. Tsuchiya	Innova Dynamics
	G. Zhou	South China Normal Univ.

Workshop on MEMS and Emerging Technologies for Future Displays and Devices

Workshop Chair:	M. Nakamoto	Shizuoka Univ.
Program Chair:	Y. Nakai	Toshiba
General Secretary:	T. Komoda	Panasonic
Program Committee:	T. Akinwande	MIT
	G. Barbastathis	MIT
	M. Esashi	Tohoku Univ.
	H. Fujita	Univ. of Tokyo
	J. Jang	Kyung Hee Univ.
	H. Kikuchi	NHK
	J. Kim	Univ. of Oxford
	K. Matsumoto	Olympus
	W. Milne	Univ. of Cambridge
	S. Sugiyama	Ritsumeikan Univ.
	H. Tuller	MIT
	S. Uchikoga	Toshiba
	J.-B. Yoon	KAIST
	Y. Yoshida	Mitsubishi Elec.

Workshop on Display Electronic Systems

Workshop Chair:	H. Okumura	Toshiba
Workshop Vice-Chair:	T. Yamamoto	NHK
Program Chair:	K. Makita	AIST
General Secretary:	S. Takamura	NTT
Program Committee:	R. Hattori	Kyushu Univ.
	T. Fujine	Sharp
	K. Kagawa	Shizuoka Univ.
	K. Käläntär	Global Optical Solutions
	L. Kerofsky	Sharp Labs. of America
	H.-S. Koo	Minghsin Univ. of S&T
	H. Nam	Kyung Hee Univ.
	O.-K. Kwon	Hanyang Univ.
	T. Mitasaki	NTT
	K. Morita	Nat. Traffic Safety & Environment Lab.
	A. Nagase	Mitsubishi Elec.
	H. Nitta	Japan Display
	S. Ono	Panasonic
	A. Sakaigawa	Japan Display
	K. Sekiya	Kanagawa Inst. of Tech.

Workshop on Flexible Electronics

Workshop Chair:	H. Fujikake	Tohoku Univ.
Program Chair:	T. Sekitani	Osaka Univ.
General Secretary:	H. Maeda	DNP
Program Committee:	K. Akamatsu	Sony
	T. Eguchi	Sumitomo Bakelite
	H. Endo	NEC HV
	M. Funahashi	Kagawa Univ.
	T. Furukawa	Yamagata Univ.
	H. Hirata	Toray Eng.
	M. Ito	Toppan Printing
	T. Kamata	AIST
	M. Kimura	Nagaoka Univ. of Tech.
	Y. Mishima	FUJIFILM
	A. Miyamoto	Panasonic
	M. Nakata	NHK
	T. Shiro	Teijin
	K. Takimiya	RIKEN
	T. Tomono	Toppan Printing
	K. Uemura	Nippon Steel & Sumitomo Metal
	Y. Uraoka	Nara Inst. of S&T

Workshop on Touch Panels and Input Technologies

Workshop Chair:	N. Hashimoto	Citizen Holdings
Program Chair:	T. Nakamura	Japan Display
General Secretary:	H. Haga	NLT Techs.
Program Committee:	I. Fujieda	Ritsumeikan Univ.
	K. Imoto	Toshiba
	M. Inoue	Huawei Technologies Japan
	K. Kagawa	Shizuoka Univ.
	H. Kato	Sharp
	F. Koo	Minghsin Univ. of S&T
	I. Mihara	Toshiba
	K. Nakatani	Touchpanel Labs.
	H. Noma	Ritsumeikan Univ.
	H. Okumura	Toshiba
	Y. Sasaki	Mitsubishi Elec.

K. Yamazaki Corning Holding Japan
J. Watanabe NTT

Special Topics of Interest on Oxide-Semiconductor TFT

Facilitator: M. Kimura Ryukoku Univ.

Program Committee:

AMD H. Kumomi Tokyo Inst. of Tech.
FMC R. Yamaguchi Akita Univ.
FLX M. Nakata NHK

Special Topics of Interest on Augmented Reality and Virtual Reality

Facilitator K. Makita AIST

Program Committee:

FMC M. Shinohara Omron
3D M. Tsuchida NTT
PRJ O. Akimoto Sony
DES K. Makita AIST
INP N. Hashimoto Citizen Holdings
VHF A. Yoshida Sharp
DES H. Okumura Toshiba

Special Topics of Interest on Lighting Technologies

Facilitator: Y. Kijima Sony

Program Committee

FMC M. Shinohara Omron
PH K. Hara Shizuoka Univ.
OLED T. Ikuta JNC Petrochem.

Special Topics of Interest on Printed Electronics

Facilitator: H. Hirata Toray Eng.

Program Committee:

LCT K. Ishikawa Tokyo Inst. of Tech.
AMD H. Minemawari AIST
FMC T. Tomono Toppan Printing
OLED K. Monzen Nissan Chem. Inds.
DES R. Hattori Kyushu Univ.
FLX H. Hirata Toray Eng.

FINANCIAL SUPPORTING ORGANIZATIONS (as of August 6, 2014)

ADEKA CORPORATION

Japan Display Inc.

JSR Corporation

Nichia Corporation

Semiconductor Energy Laboratory Co., Ltd.

TOKYO ELECTRON LIMITED

ZEON CORPORATION

SUPPORTING MEMBERS (as of August 6, 2014)

EIZO Corporation

JAPAN BROADCASTING CORPORATION

JNC Corporation

Merck Ltd. Japan

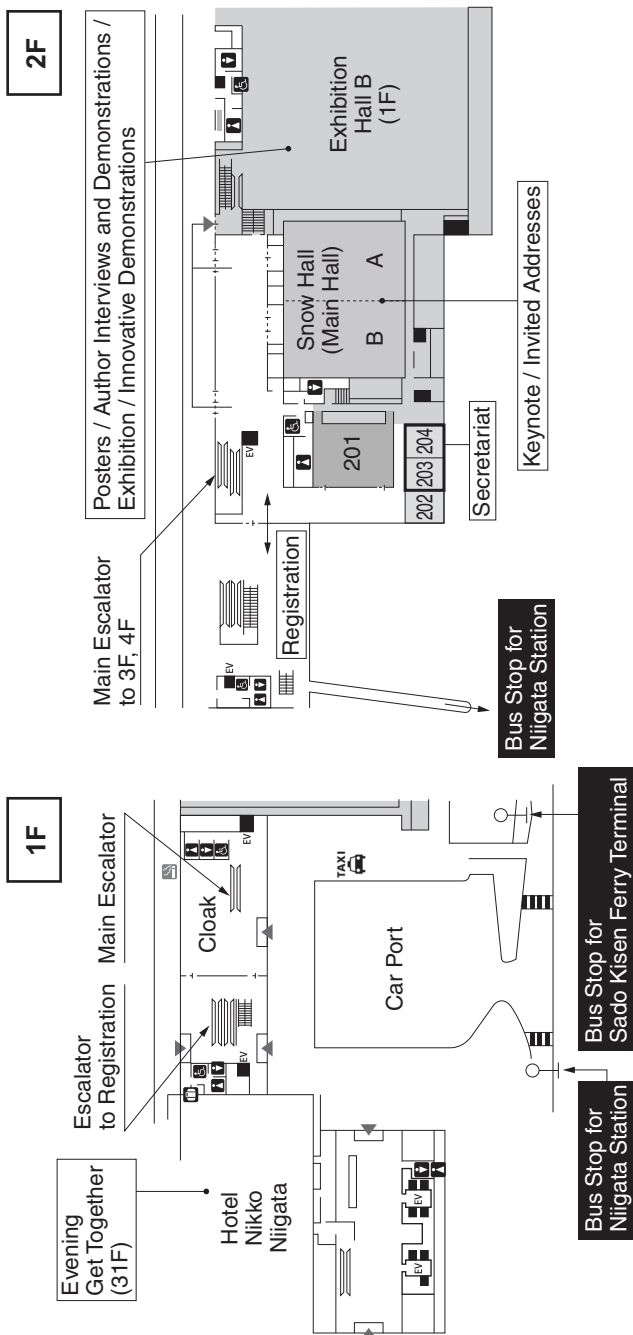
NLT Technologies, Ltd.

Panasonic Corporation

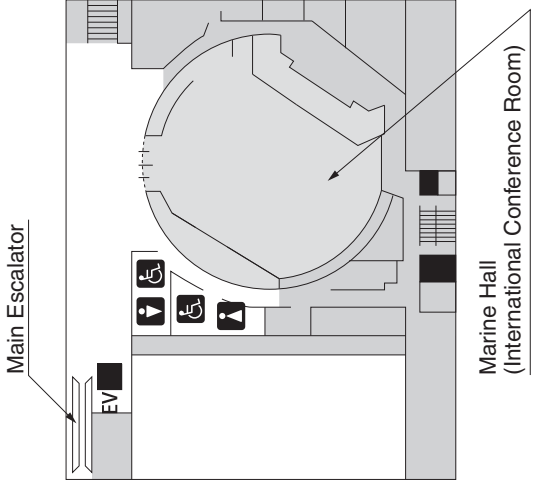
Toshiba Corporation

ULVAC, Inc.

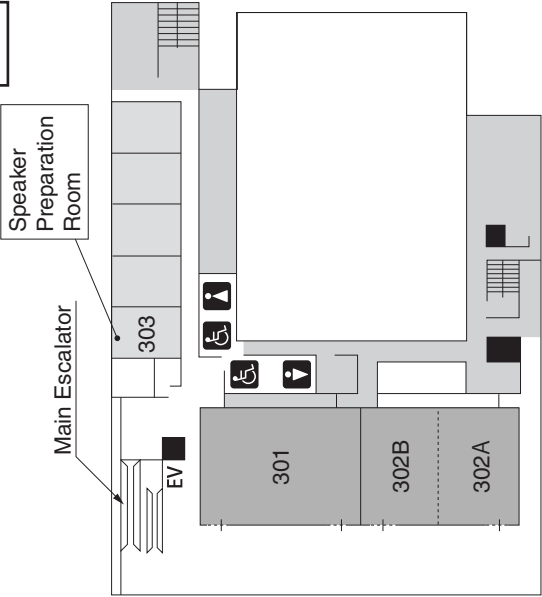
FLOOR MAP



4F



3F



MEMO

MEMO

MEMO

IDW '14 Workshop Timetable

Date	2F Lobby	Snow Hall A	Snow Hall B	Marine Hall	Room 301	Room 302 A	Room 302 B	Room 201	Exhibition Hall B			
Tue., Dec. 2	Registration 17:00 - 20:00	Evening Get-Together at Observation Deck (31F) in Hotel Nikko Niigata 18:00 - 20:00										
Wednesday, December 3	Registration 8:00 - 18:00	Opening, Keynote & Invited Addresses 9:30 - 12:30		Lunch				AMDp 14:00 - 17:00	Exhibition 12:40 - 18:00			
		FLX1 (p.102) 14:00 - 15:40	OLED1 (p.67) 14:00 - 15:20	FMC1 (p.51) 14:00 - 15:20	LCT1 (p.38) 14:00 - 15:05	EP1 (p.90) 14:00 - 14:50	INP1 (p.108) 14:00 - 15:30			PRJ1 (p.86) 14:00 - 15:30		
		Break										
		FLX2 (p.103) 15:45 - 16:25	OLED2 (p.67) 15:45 - 16:45	FMC2 (p.51) 15:45 - 16:45	LCT2 (p.38) 15:45 - 17:10	EP2 (p.90) 15:45 - 17:00	INP2 (p.109) 15:45 - 17:15	PRJ2 (p.87) 15:45 - 17:15				
		Author Interviews & Demonstrations 17:15 - 18:15										
Reception at the Room "Continental" (4F) in Hotel Okura Niigata 19:00 - 21:00												
Thursday, December 4	Registration 8:00 - 18:00	AMD1 (p.47) 9:00 - 10:15	OLED3 (p.68) 9:00 - 10:10	EP3 [†] (p.91) 9:00 - 10:11	PRJ3 (p.87) 9:00 - 10:05	VHF1 (p.80) 9:00 - 10:10	DES1 (p.97) 9:00 - 10:35	MEET1 (p.92) 9:00 - 10:30	FMCp, PHp, 3Dp, FLXp, INPp 9:00 - 12:00	Exhibition 10:00 - 18:00		
		Break										
		AMD2 (p.47) 10:45 - 12:20	OLED4 (p.69) 10:45 - 11:55	LCT3 (p.39) 10:45 - 11:55	PRJ4 (p.88) 10:45 - 11:50	VHF2 (p.80) 10:45 - 11:55	DES2 (p.97) 10:45 - 11:55	MEET2 (p.93) 10:45 - 12:45				
		Lunch				OLEDp, VHFp, EPp, DESp 13:30 - 16:30						
		AMD3 (p.48) 13:30 - 14:55	FLX3 (p.105) 13:30 - 14:45	LCT4 (p.40) 13:30 - 14:35	INP3 (p.110) 13:30 - 14:20	3D1 (p.75) 13:30 - 15:00	PRJ5 [†] (p.88) 13:30 - 14:42	MEET3 (p.94) 13:30 - 14:50				
		Break										
		AMD4 (p.49) 15:15 - 16:20	FLX4 (p.105) 15:15 - 16:25	LCT5 (p.40) 15:15 - 16:20	3D2 (p.76) 15:15 - 16:30	INP4 (p.110) 15:15 - 16:30	PH1 (p.60) 15:15 - 16:25	MEET4 (p.94) 15:15 - 16:55				
		Break										
		AMD5 (p.49) 17:00 - 18:10	FMC3 (p.56) 17:00 - 18:00			3D3 (p.76) 17:00 - 18:40	VHF3 (p.82) 17:00 - 18:00	PH2 (p.61) 17:00 - 18:05	MEET5 (p.95) 17:00 - 18:40		Innovative Demonstration Session 16:45 - 19:30	
		Author Interviews & Demonstrations 18:30 - 19:30										
Friday, December 5	Registration 8:00 - 13:00	OLED5 (p.73) 9:00 - 10:25	FMC4 (p.56) 9:00 - 10:00			3D4 (p.77) 9:00 - 10:20	PH3 (p.61) 9:00 - 10:25	FED1 (p.63) 9:00 - 10:35	VHF4 (p.83) 9:00 - 10:00	LCTp, PRJp 9:00 - 12:00	Exhibition 10:00 - 14:00	
		Break										
		FLX5 (p.106) 10:45 - 11:50	FMC5 (p.57) 10:45 - 12:05			3D5 (p.78) 10:45 - 11:45	FED2 (p.64) 10:45 - 12:05		DES3/VHF5 (p.83/p.99) 10:45 - 12:15			
		Lunch				Innovative Demonstration Session 12:30 - 15:15						
		FLX6/FMC6 (p.57/p.107) 13:30 - 14:35			3D6 (p.78) 13:30 - 14:55	VHF6 (p.84) 13:30 - 14:30	FED3 (p.65) 13:30 - 14:50	DES4 (p.100) 13:30 - 14:30				
		Break										
				3D7/VHF7 (p.79/p.85) 15:15 - 16:20	FED4 (p.65) 15:15 - 16:35	DES5 (p.101) 15:15 - 16:15						
Author Interviews & Demonstrations 16:45 - 17:45												

[†]Including Short Presentations

Fri., Dec. 5	Thu., Dec. 4	Wed., Dec. 3
AM	PM	AM
	AMDC: High Resolution Displays Using LTP-Si Oxide TFTs (p.29)	AMDC: High Resolution Displays Using LTP-Si Oxide TFTs (p.29)
	AMDC: Physics of Semiconductors 10:45 - 12:20 (p.25)	AMDC: Physics of Semiconductors 10:45 - 12:20 (p.25)
	AMDC: Stability of Oxide TFTs (p.28)	AMDC: Stability of Oxide TFTs (p.28)
	AMDC: Higher Performance Oxide 15:15 - 16:20 (p.28)	AMDC: Higher Performance Oxide 15:15 - 16:20 (p.28)
		FMCp4: Poster 9:00 - 12:00 (p.24)
		AMDp1: Poster 14:00 - 17:00 (p.22)
	Augmented Reality & Virtual Reality 9:00 - 10:30 (p.30)	
		Augmented Reality and Virtual Reality
		Room 301
		Room 302 B
		Room 201
		Snow Hall B
		Lighting Technologies
		Room 302 A
		Exhibition Hall B
		Snow Hall A
		Snow Hall B
		Printed Electronics
		Exhibition Hall B
		AMDC: Printed Electronics 17:00 - 18:10 (p.37)
		OLEDp3: Poster 9:00 - 12:00 (p.32)
		FMCp3: PHp2: 9:00 - 12:00 (p.32)
		OLEDp3: PHp2: 9:00 - 12:00 (p.32)
		OLEDp4: OLED Materials (1) 10:45 - 11:55 (p.39)
		OLEDp3: OLED Process Technologies 9:00 - 11:10 (p.35)
		FLXp4: Printed TFT Technologies 15:15 - 16:25 (p.37)
		FLXp3: Advanced Printing Technologies 13:30 - 14:45 (p.39)
		OLEDp2: Poster 13:30 - 16:30 (p.36)

IDW '14 Session Navigator

	Wednesday, December 3			Thursday, December 4				Friday, December 5						
	PM	17:15-18:15		AM	PM	18:30-19:30	AM	PM	16:45-17:45					
Active-Matrix Displays	Exhibition Hall B			Snow Hall A				Exhibition Hall B						
	Posters			High Resolution Displays Using LTPS & Oxide TFTs	Physics of Oxide Semiconductors	Stability of Oxide TFT	Higher Performance Oxide TFT	Printed Electronics	A.I.					
Display Electronic Systems				Room 302 B		Exhibition Hall B		Exhibition Hall B		Room 201		Exhibition Hall B		
				Display Technologies in Augmented Reality	Image Processing	Posters		A.I.		System Design & Evaluation in Augmented Reality*	Display Driving Technologies	Display Interface & Driving Technologies	A.I.	
Emissive Technologies	Room 201			Exhibition Hall B		Room 302 B		Exhibition Hall B		Room 302 B		Exhibition Hall B		
	Solid-State Light Source Technologies for Projector			Posters		Phosphor for General	Phosphor Applications	A.I.		Novel Devices & Applications	Fabrication Processes & New Materials	FE Mechanisms & PDP Protective Layers	Summing Up of PDP History	A.I.
										Room 302 A	Snow Hall B			
e-Paper	Room 302 A		Exhibition Hall B	Marine Hall		Exhibition Hall B		Exhibition Hall B						
	Electrophoretic Displays	Various Technologies for e-Paper	A.I.	Chromic Displays	Posters		A.I.							
Flexible Electronics	Snow Hall A		Exhibition Hall B	Exhibition Hall B		Snow Hall B		Exhibition Hall B		Snow Hall A		Exhibition Hall B		
	Flexible Backplane	Flexible Displays & Devices	A.I.	Posters		Advanced Printing Technologies	Printed TFT Technologies	A.I.		Flexible Substrates	Flexible Materials & Devices*	A.I.		
Image Quality Evaluation & Human Factor				Room 302 A		Exhibition Hall B		Room 302 A	Exhibition Hall B		Room 201	Room 302 A	Room 301	Exhibition Hall B
				Optical Measurements	Color & OLEDs	Posters		Moving Image Quality	A.I.		Display Legibility	System Design & Evaluation in Augmented Reality*	Mobile Human Factors & 'Kansei' Evaluation	Visual Perception for 3D System*
Liquid-Crystal Technologies	Room 301		Exhibition Hall B	Marine Hall		Exhibition Hall B		Exhibition Hall B						
	Fast Switching LCD	Novel Optics for LCD	A.I.	Photo Alignment	LC Materials	LC Evaluation	A.I.		Posters					
Manufacturing, Process & Equipment	Marine Hall		Exhibition Hall B	Exhibition Hall B		Exhibition Hall B		Exhibition Hall B						
	Manufacturing Technologies		A.I.	Posters		Exhibition Hall B		Exhibition Hall B						
Materials & Components	Marine Hall		Exhibition Hall B	Exhibition Hall B		Snow Hall B		Exhibition Hall B		Snow Hall B		Snow Hall A	Exhibition Hall B	
	Materials & Components		A.I.	Posters		Optical Films		A.I.		Augmented Reality & Virtual Reality	Lighting Technologies	Flexible Materials & Devices*	A.I.	
MEMS & Nanotechnologies				Room 201				Exhibition Hall B						
				Emerging Quantum Dots & Nanotechnologies	Fundamental Components & Process Technologies	EL Quantum Dots Technologies	Novel Materials & Components	Nanotechnology Display & Imaging	A.I.					
Organic Light-Emitting Displays & Organic Devices	Snow Hall B		Exhibition Hall B	Snow Hall B		Exhibition Hall B		Exhibition Hall B		Snow Hall A	Exhibition Hall B			
	Advanced OLED Technologies (1)	Advanced OLED Technologies (2)	A.I.	OLED Process Technologies	OLED Materials (1)	Posters		A.I.		OLED Materials (2)	A.I.			
Projection & Large Area Displays	Room 201		Exhibition Hall B	Room 301		Room 302 B	Exhibition Hall B		Exhibition Hall B					
	Solid-State Light Source Technologies for Projector	Vehicle Display	A.I.	Projection Technologies	Wearable Display	Projection Applications	A.I.		Posters					
Touch & Interactive Technologies	Room 302 B		Exhibition Hall B	Exhibition Hall B		Room 301	Room 302 A	Exhibition Hall B						
	Touch Panel (1)	Touch Panel (2) & Haptics	A.I.	Posters		AR Interactive Systems	Sensor & Applications	A.I.						
3D/Hyper-Realistic Displays				Exhibition Hall B		Room 302 A	Room 301		Exhibition Hall B		Room 301		Exhibition Hall B	
				Posters		Holography	Interactive 3D Display Technology	Omnidirectional Hyper-Realistic System	A.I.		3D/Hyper-Realistic Displays (1)	3D/Hyper-Realistic Displays (2)	Optical Devices for 3D System	Visual Perception for 3D System*

A.I. Author Interviews & Demonstrations
* Joint Session

IDW '14 The 21st International Display Workshops

December 3-5, 2014 TOKI MESSE Niigata Convention Center, Niigata, Japan

Registration

(1) Registration Fees

The registration fee includes admission to the conference and a CD-ROM of the proceedings. In addition, a printed Final Program including abstracts of each paper will be provided at the conference site. No refunds will be made on and after November 1, 2014.

	ITE/SID/ ASO*1 Member*2	Non- Member*3	Student*4	Life Member of ITE/SID
Until October 31	¥35,000	¥45,000	¥ 8,000	¥ 8,000
On and After November 1	¥45,000	¥55,000	¥10,000	¥10,000

*1 ASO: Academic Supporting Organizations. See p.14 as well as "Supporting Organizations and Sponsors" at the end of each workshop section in the Advance Program.

*2 Individual member

*3 If you intend to join either ITE or SID, the one year membership fee will be subsidized by the IDW '14 Committee.

*4 Photocopy of your student ID is required.

(2) Reception Fee

Until October 31 ¥8,000
On and After November 1 ¥10,000

One free ticket will be provided to each invited speaker.

(3) Additional Proceedings (CD-ROM)

At the Conference Site ¥8,000
Airmail after the Conference ¥12,000
Domestic Mail after the Conference ¥10,000

Registration

(1) e-Registration (Deadline: November 21, 2014)

Access <http://www.idw.or.jp/regist.html>

(2) Mail or Fax (Deadline: November 21, 2014)

Registration Form is available via <http://www.idw.or.jp/regist.html>

(3) On-site

Early-Bird Fee: until Oct. 31
Deadline of Advance Registration: Nov. 21

Accommodations

JTB Kanto Corp. will handle arrangements for your hotel reservations. Room rates include breakfast, service charge, and 8% consumption tax.

Reservation

Access <http://www.idw.or.jp/accommodation.html>

Area	No. in map (p.18)	Hotel Name	Phone	Rates (per person/ per night)		Internet Access	
				Single	Twin	Charge	Wired or Wireless LAN
Bandai Area	1	Hotel Nikko Niigata	+81-25-240-1888	¥9,500	¥9,000	Free	Wireless
	2	ANA Crowne Plaza Niigata	+81-25-245-3333	¥12,500	¥8,700	Free	Both
	3	Bandai Silver Hotel	+81-25-243-3711	¥8,000	¥7,500	Free	Both
Furumachi Area	4	Hotel Okura Niigata	+81-25-224-6111	¥8,500	¥8,000	Free	Wireless
	5	Niigata Grand Hotel	+81-25-228-6111	¥8,000	¥7,500	Free	Both
Niigata Eki Mae Area	6	Niigata Tokyu Inn	+81-25-243-0109	¥7,500	¥6,500	Free	Both
	7	Hotel Sunroute Niigata	+81-25-246-6161	¥7,500	¥6,500	Free	Both
	8	Niigata Toei Hotel	+81-25-244-7101	¥6,500	¥6,000	Free	Both
	9	Court Hotel Niigata	+81-25-247-0505	¥6,000		Free	Both
	10	Comfort Hotel Niigata	+81-25-242-0611	¥6,000		Free	Both

Cancellation Policy

8 days or more days prior to the first night of stay No charge
2 to 7 days before the first night of stay 20% of daily room rate
1 day before the first night of stay 40% of daily room rate
Before 14:00 of the first night of stay 50% of daily room rate
After 14:00 of the first night of stay or no notice given 100% of daily room rate

Deadline of Hotel Reservation:
Nov. 14

IDW '14 Secretariat:
c/o Bilingual Group Ltd.
3-3-6 Kudan Minami, Chiyoda-ku,
Tokyo 102-0074, Japan
Phone : +81-3-3263-1345
FAX : +81-3-3263-1264
E-mail : idw@idw.or.jp



JSR Corporation



NLT Technologies



Panasonic



TOSHIBA
Leading Innovation >>>



TOKYO ELECTRON

ULVAC

ZEON

IDW '14
ADVANCE PROGRAM
<http://www.idw.or.jp/>